RTMP'S copy

REPLACEMENT SHEETS SG
☐ Description : paged ..... to paged .....
☐ Claim(s) : paged ..... to paged .....
☐ Drawing(s) : paged ..... to paged .....
☐ Abstract : paged ..... to paged .....
DATE OF RECEIPT 18 DEC 1996

THIS SHEET HAS BEEN REPLACED

DIELECTRIC CERAMIC COMPOSITION AND MONOLITHIC CERAMIC CAPACITOR USING SAME

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to a dielectric ceramic composition and monolithic ceramic capacitor using the same.

2. Description of the Related Art

The conventional ceramic capacitor is usually produced by the following process.

First, a sheet of a dielectric material coated with an electrode material to serve as inner electrodes on its surface is prepared. A material essentially composed of $BaTiO_3$ is used for the dielectric material. Then, the sheet of the dielectric material coated with this electrode material is laminated with heat-pressing to a monolithic body followed by firing at 1250 to 1350 °C in an atmospheric environment to obtain a ceramic monolithic body having inner electrodes. A monolithic ceramic capacitor is obtained by glazing outer electrodes electrically connected to inner electrodes.

Noble metals such as platinum, gold, palladium or silver have been conventionally used for the material of the inner electrode of this monolithic ceramic capacitor.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

However, these electrode materials are expensive while having excellent characteristics, rendering the production cost to be increased. Therefore, a monolithic capacitor using base metals such as Ni in the inner electrode is currently proposed to reduce the production cost, its application in the market being steadily increasing.

SUMMARY OF THE INVENTION

In the trend to make electronic appliances compact, high performance and low price, the monolithic capacitor is strongly required to be low price, to be improved in insulation durability, insulating property and reliability, and to have a large capacitance. Although it is advantageous for reducing the price of the electronic appliances to use an inexpensive monolithic ceramic capacitor in which nickel is used for the inner electrode, a problem that the insulation resistance, insulation durability and reliability are extremely deteriorated when the electronic appliances are used under a high electric field strength because conventional dielectric ceramic materials are designed on the premise that they are used under a low electric field strength. In other words, there has been no monolithic ceramic capacitor being able to use under a high electric field strength along with using nickel

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

for the inner electrode.

For example, while the dielectric materials disclosed in Japanese Examined Patent Publication No. 57-42588 and Japanese Unexamined Patent Publication No. 61-101459 can display a large dielectric constant, the grain size of the dielectric ceramic is large, thereby exhibiting deficiencies such that the insulation durability of the monolithic ceramic capacitor becomes low when it is used under a high electric field strength or the mean life span under the high temperature load test becomes short.

In the dielectric material disclosed in Japanese Examined Patent Publication No. 61-14611, there was a deficiency that the dielectric constant, or the electrostatic capacitance, is extremely lowered when the capacitor is used under a high electric field strength, although its dielectric constant obtained under a low electric field strength is as high as 2000 to 2800. It was also a deficiency that the insulation resistance is low.

The object of the present invention is to provide a dielectric ceramic composition capable of forming, for example, dielectric ceramic layers of a monolithic ceramic capacitor, wherein the insulation resistance represented by a product with the electrostatic capacitance (a product CR) is as high as 4900 to 5000 Ω·F or more and 200 Ω·F or more

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

at room temperature and 150 °C, respectively, when the capacitor is used under a high electric field strength of, for example, as high as about 10 kV/mm, along with having a small voltage dependence of the insulation resistance, being excellent in stability of the electrostatic capacitance against DC vias voltage, being high in the insulation durability besides the temperature characteristics of the electrostatic capacitance satisfying both of B-level characteristic standard stipulated in the JIS Standard and X7R-level characteristic standard stipulated in the EIA standard and being excellent in weather resistance performance shown by a high temperature load test and high humidity load test. Another object of the present invention is to provide a monolithic ceramic capacitor whose inner electrode is constructed of Ni or Ni alloys along with using such dielectric ceramic composition as a dielectric ceramic layer.

In a first aspect, the present invention provides a dielectric ceramic composition comprising barium titanate containing 0.02% by weight or less of alkali metal oxides, at least one of either scandium oxide or yttrium oxide, at least one kind of compound selected from europium oxide, gadolinium oxide, terbium oxide and dysprosium oxide, and barium zirconate and manganese oxide, and containing an

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

essential component represented by the following composition formula;

$$(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$$

(wherein M_2O_3 represents at least one of either Sc_2O_3 or Y_2O_3 and R_2O_3 represents at least one of the compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, α, β, γ and g representing mole ratio in the range of $0.001 \leq \alpha \leq 0.05$, $0.001 \leq \beta \leq 0.05$, $0.005 \leq \gamma \leq 0.06$, $0.001 < g \leq 0.13$ and $\alpha + \beta \leq 0.06$ with $1.000 < m \leq 1.035$),

along with containing 0.2 to 3.0 parts by weight of either the first or second side component relative to 100 parts by weight of the essential component, wherein the first side component is an oxide represented by Li_2O - $(Si, Ti)O_2$ - MO (wherein MO is at least one of Al_2O_3 or ZrO_2) and the second side component is an oxide represented by SiO_2 - TiO_2 - XO (wherein XO is at least one of the compound selected from BaO, CaO, SrO, MgO, ZnO and MnO).

In the dielectric ceramic composition described above, the essential component may further contain h mole ratio of magnesium oxide, where $0.001 < g \leq 0.12$, $0.001 < h \leq 0.12$ and $g + h \leq 0.13$

In the dielectric ceramic composition according to another aspect of the present invention, the essential component may be represented by the following composition

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

formula;

$$(BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MnO$$

(wherein M_2O_3 represents at least one of either Sc_2O_3 or Y_2O_3, where α, β and γ representing mole ratio in the range of $0.001 \leq \alpha \leq 0.06$, $0.005 \leq \beta \leq 0.06$ and $0.001 < \gamma \leq 0.13$ with $1.000 < m \leq 1.035$).

The essential component may further contain g mole ratio of magnesium oxide, where $0.001 < \gamma \leq 0.12$, $0.001 < g \leq 0.12$ and $\gamma + g \leq 0.13$

According to a different aspect of the present invention, the essential component may be represented by the following composition formula;

$$(BaO)_mTiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MnO$$

(wherein R_2O_3 represents at least one kind of compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, where α, β and γ representing mole ratio in the range of $0.001 \leq \alpha \leq 0.06$, $0.005 \leq \beta \leq 0.06$ and $0.001 < \gamma \leq 0.13$ with $1.000 < m \leq 1.025$).

The essential component may further contain g mole ratio of magnesium oxide, where $0.001 \leq \beta \leq 0.06$, $0.001 < \gamma \leq 0.12$, $0.001 < g \leq 0.12$ and $\gamma + g \leq 0.13$.

In the dielectric ceramic composition described above, it is preferable that the first side component, when its composition is represented by $xLi_2O-y(Si_wTi_{1-w})O_2-zMO$ (wherein

This Sheet Has Been Replaced

x, y and z represent mol% and w is in the range of $0.30 \leq w \leq 1.00$), falls within or on the boundary lines of the area surrounded by straight lines connecting each point indicated by A (x = 20, y = 80, z = 0), B (x = 10, y = 80, z = 10), C (x = 10, y = 70, z = 20), D (x = 35, y = 45, z = 20), E (x = 45, y = 45, z = 10) and F (x = 45, y = 55, z = 0)
(when the composition falls on the straight line of A - F, w is within the area of $0.3 \leq w < 1.0$) in the three component diagram defined by the apexes corresponding to each component.

In the dielectric ceramic composition described above, it is preferable that the second side component, when its composition is represented by $xSiO2-yTiO_2-zXO$ (wherein x, y and z represent mol%), falls within or on the boundary lines of the area surrounded by straight lines connecting each point indicated by A (x = 85, y = 1, z = 14), B (x = 35, y = 51, z = 14), C (x = 30, y = 20, z = 50) and D (x = 39, y = 1, z = 60)
in the three component diagram defined by the apexes corresponding to each component.

The second side component contains in total of 15 parts by weight of at least one of Al_2O_3 and ZrO_2 (the content of ZrO_2 is 5 parts by weight or less) relative to 100 parts by weight of the oxide represented by SiO_2-TiO_2-

THIS SHEET HAS BEEN
REPLACED

XO.

The present invention according to a different aspect provides a monolithic ceramic capacitor provided with a plurality of dielectric ceramic layers, inner electrodes formed between the ceramic layers and outer electrodes being electrically connected to the inner electrodes, wherein the dielectric ceramic layers are constructed by the dielectric ceramic composition described above and the inner electrodes are composed of nickel or a nickel alloy.

The outer electrode may be provided with a sintered layer of an electroconductive metal powder or an electroconductive metal powder supplemented with glass frits.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a cross sectional view showing the monolithic ceramic capacitor according to one embodiment of the present invention.

FIG. 2 is a plane view showing the dielectric ceramic layer portion having inner electrodes of the monolithic ceramic capacitor shown in FIG. 1.

FIG. 3 is a disassembled perspective view showing the ceramic monolithic portion of the monolithic ceramic capacitor shown in FIG. 1.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

FIG. 4 is a three component phase diagram of Li_2O-(Si_w, Ti_{1-w})O_2-MO oxides.

FIG. 5 is a three component phase diagram of SiO_2-~~Ti_2-~~ TiO_2 XO oxides.

DESCRIPTION OF THE PREFERRED EMBODIMENT

The basic construction of the monolithic ceramic capacitor according to the first embodiment of the present invention will be described hereinafter referring to the drawings. FIG. 1 is a cross section showing one example of the monolithic ceramic capacitor, FIG. 2 is a plane view showing the dielectric ceramic portion having inner electrodes of the monolithic ceramic capacitor in FIG. 1, and FIG. 3 is a disassembled perspective view showing the dielectric ceramic portion having inner electrodes of the monolithic ceramic capacitor in FIG. 1.

As shown in FIG. 1, the monolithic ceramic capacitor 1 according to the present embodiment is provided with a rectangular shaped monolithic ceramic body 3 obtained by laminating a plurality of dielectric ceramic layers 2a and 2b via the inner electrodes 4. An outer electrode 5 is formed on the both side faces of the monolithic ceramic body 3 so that the outer electrodes are electrically connected to each of the specified inner electrodes 4, on which a first

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

plating layer **6** comprising nickel or copper is plated, a second plating layer **7** comprising a solder or tin being further formed on the first plating layer.

The method for producing the monolithic ceramic capacitor **1** will be next described in the order of production steps.

At first, a raw material powder of barium titanate prepared by weighing and mixing in a given composition ratio is prepared as an essential component of the dielectric ceramic layers **2a** and **2b**.

Then, a slurry is prepared by adding an organic binder in this raw material powder and, after forming this slurry into a sheet, a green sheet for use in the dielectric ceramic layers **2a** and **2b** is obtained.

Next, an inner electrode **4** comprising nickel or a nickel alloy is formed on one principal face of the green sheet to serve as the dielectric ceramic layers **2b**. Nickel or nickel alloys as base metals may be used for the material of the inner electrode **4** when the dielectric ceramic layers **2a** and **2b** are formed using the dielectric ceramic composition as described above. The inner electrode **4** may be formed by a screen printing method, a deposition method or a plating method.

After laminating a required number of the green sheets

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

for use in the dielectric ceramic layers **2b** having the inner electrodes **4**, the green sheets are inserted between the green sheets for use in the dielectric ceramic layer **2a** having no inner electrode, thus obtaining a raw monolithic body by press-adhering these green sheets.

Then, this raw monolithic body is fired at a given temperature to obtain a ceramic monolithic body **3**.

The outer electrodes **5** are formed at the both side faces of the ceramic monolithic body **3** so as to be electrically connected to the inner electrodes **4**. The same material as used in the inner electrodes **4** can be used for the outer electrodes **5**. While silver, palladium, a silver-palladium alloy, copper and a copper alloy is available besides a composition prepared by adding a glass frit such as a B_2O_3-SiO_2-BaO glass or Li_2O-SiO_2-BaO glass into these metal powders, an appropriate material should be selected by taking the application object and application site of the monolithic capacitor into consideration. While the outer electrodes **5** is formed by coating the ceramic monolithic body **3** obtained by firing with a metal powder paste as a raw material followed by heat-adhering, it may be formed by heat-adhering the metal powder paste simultaneously with the ceramic monolithic body **3**.

The first plating layer **6** is then formed by applying a

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

plating with nickel or copper on the outer electrode **5**. Finally, the second plating layer **7** comprising a solder or tin is formed on the first plating layer **6**, thereby completing the monolithic capacitor **1**. Such process for further forming a conductive layer on the outer electrode **5** may be omitted depending on the application field of the monolithic ceramic capacitor.

By using the dielectric ceramic composition as described previously for constructing the dielectric ceramic layers **2a** and **2b**, the characteristic of the dielectric ceramic layers is not deteriorated even when it is fired in a reducing atmosphere. In other words, such characteristics are obtained in which the product between the insulation resistance and the electrostatic capacitance (a product CR) is as high as 4900 to 5000 Ω·F or more and 200 Ω·F or more at room temperature and 150 °C, respectively, when the capacitor is used under an electric field strength as high as about 10 kV/mm, along with having a small voltage dependence of the insulation resistance, the absolute value of the capacitance decreasing ratio at an impressed DC voltage of 5 kV/mm being as small as 40% to 45%, the insulation durability being as high as 12 kV/mm or more under an AC voltage and 14 kV/mm under a DC voltage, besides its temperature characteristics of the electrostatic

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

capacitance satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C and being excellent in weather resistance performance shown by a high temperature load test at 150 °C and at DC 25 kV/mm and high humidity load test.

It has been confirmed that, among alkali earth metal oxides such as SrO and CaO existing in barium titanate as impurities, alkali metal oxides such as Na_2O and K_2O and other oxides such as Al_2O_3 and SiO_2, especially the content of the alkali metal oxides largely influences on the electric characteristics. While the specific dielectric constant is decreased when the amounts of addition of rare earth element oxides such as Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, and Sc_2O_3 and Y_2O_3 are increased, the specific dielectric constant can be kept to a practically acceptable range of 900 to 1600 by keeping the content of the alkali metal oxides contained in barium titanate as impurities to 0.02% by weight or less.

Adding an oxide represented by Li_2O-(Si, Ti)O_2-MO (wherein MO is at least one of Al_2O_3 and ZrO_2) in the dielectric ceramic composition allows the composition to be sintered at a relatively low temperature of 1300 °C or less,

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

further improving the high temperature load characteristic.

Adding an oxide represented by Si_2O-TiO_2-XO (wherein XO is at least one kind of compound selected from BaO, CaO, SrO, MgO, ZnO and MnO) in the dielectric ceramic composition allows the composition to be improved in sintering property as well as in high temperature load characteristic and humidity resistance load characteristic. A higher insulation resistance can be obtained by adding Al_2O_3 and/or ZrO_2 in the oxide represented by Si_2O-TiO_2-XO.

(Examples)

The present invention will now be described in more detail by way of examples. However, the embodiment within the scope of the present invention is not limited to these examples.

(Example 1)

After preparing and weighing $TiCl_4$ and $Ba(NO_3)_2$ having a variety of purity as starting materials, the compounds were precipitated as titanyl barium oxalate ($BaTiO(C_2O_4)\cdot 4H_2O$) by adding oxalic acid. This precipitate was decomposed by heating at a temperature of 1000 °C or more to synthesize four kinds of barium titanate listed in TABLE 1.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

TABLE 1

Oxides, carbonates or hydroxides as each component of the first side component were weighed so as to be a composition ratio (mole ratio) of $0.25Li_2O$-$0.65(0.30TiO_2 \cdot 0.70SiO_2)$-$0.10Al_2O_3$ to obtain a powder by crushing and mixing.

Likewise, oxides, carbonates or hydroxides as each component of the second side component were weighed so as to be a composition ratio (mole ratio) of $0.66SiO_2$-$0.17TiO_2$-$0.15BaO$-$0.02MnO$ to obtain a powder by crushing and mixing.

Oxide powders of the first and second side components were placed in separate platinum crucibles, respectively, and heated at 1500 °C. After quenching and crushing the mixture, each oxide powder with a mean particle size of 1 μm or less was obtained.

In the next step, $BaCO_3$ for adjusting the mole ratio Ba/Ti (m) in barium titanate, Sc_2O_3, Y_2O_3, Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, and $BaZrO_3$, MgO and MnO, each having a purity of 99% or more, were prepared. These raw material powders and the oxides described above to be either one of the side components were weighted so as to form compositions shown in TABLE 2 and TABLE 3. The amounts of addition of the first

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

and second side components are indicated by parts by weight relative to 100 parts by weight of the essential component $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + \cancel{gMnO} + hMnO$. gMgO

TABLE 2

TABLE 3

Organic solvents such as polyvinyl butyral binder and ethanol were added to the weighed compounds and the mixture was mixed in a ball mill in an wet state to prepare a ceramic slurry. This ceramic slurry was formed into a sheet by a doctor blade method to obtain a rectangular shaped green sheet with a thickness of 35 μm, followed by printing an electroconductive paste mainly composed of Ni on the ceramic green sheet to form an electroconductive paste layer for forming inner electrodes.

Then, a plurality of the ceramic green sheets on which the electroconductive layer is formed were laminated so that the sides where the electroconductive paste is projected out are alternately placed with each other, thus obtaining a monolithic body. This monolithic body was heated at 350 °C in a N_2 atmosphere and, after allowing the binder to decompose, the monolithic body was fired at the temperatures

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

shown in TABLE 4 and TABLE 5 in a reducing atmosphere comprising H_2-N_2-H_2O gases under an oxygen partial pressure of 10^{-9} to 10^{-12} MPa, thereby obtaining a ceramic sintered body.

The both side faces of the ceramic sintered body were coated with a silver paste containing B_2O_3-Li_2O-SiO_2-BaO glass frits and fired at a temperature of 600 °C in a N_2 atmosphere, thereby obtaining outer electrodes electrically connected to the inner electrodes.

The overall dimensions of the monolithic ceramic capacitor thus obtained were 5.0 mm in width, 5.7 mm in length and 2.4 mm in thickness while the thickness of the dielectric ceramic layer was 30 μm. Total number of the effective dielectric ceramic layers were 57, the area of the confronting electrode per one layer being $8.2 \times 10^{-6} m^2$.

Electric characteristics of these monolithic ceramic capacitors were measured. The electrostatic capacitance (C) and dielectric loss (tan δ) were measured using an automatic bridge type measuring instrument at 1 kHz, 1 Vrms and 25 °C and the dielectric constant (ε) was calculated from the electrostatic capacitance. Next, the insulation resistance was measured using an insulation resistance tester at 25 °C and 150 °C by impressing direct current voltages of 315 V (or 10 kV/mm) and 945 V (or 30 kV/mm) for 2 minutes,

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

obtaining a product of the electrostatic capacitance and insulation resistance, or a product CR.

The rate of change of the electrostatic capacitance against temperature changes was also measured. The rate of change at -25 °C and 85 °C by taking the electrostatic capacitance at 20 °C as a standard ($\Delta C/C20$), the rate of change at -55 °C and 125 °C by taking the electrostatic capacitance at 25 °C as a standard ($\Delta C/C25$) and the maximum value of the rate of change ($|\Delta C|max$) as an absolute value were measured as the electrostatic capacitances against temperature changes.

The DC vias characteristic was also evaluated. First, the electrostatic capacitance when an AC voltage of 1 kHz and 1 Vrms was impressed was measured. Then, the electrostatic capacitance when a DC voltage of 150 V and an AC voltage of 1 kHz and 1 Vrms were simultaneously impressed was measured, thereby the rate of reduction of the electrostatic capacitance ($\Delta C/C$) due to loading the DC voltage was calculated.

In the high temperature load test, a direct current voltage of 750 V (or 25 kV/mm) was impressed at 150 °C on 36 pieces of each sample to measure the time dependent changes of the insulation resistance. The time when the insulation resistance of each sample was reduced below $10^6\Omega$ was defined

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

to be a life span time and mean life span time was evaluated.

In the humidity resistance test, the number of the test pieces having an insulation resistance of $10^6\Omega$ or less among the 72 test pieces were counted after impressing a DC voltage of 315 V under an atmospheric pressure of 2 atm (relative humidity 100%) at 120 °C for 250 hours.

Insulation breakdown voltages under AC and DC voltages were measured by impressing AC and DC voltages at a voltage increase rate of 100 V/sec.

The results described above are listed in TABLE 4 and TABLE 5.

TABLE 4

TABLE 5

It is evident from Table 1 to TABLE 5 that the monolithic ceramic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of less than 1.0 %, wherein the rate of change of the electrostatic capacitance against temperature changes satisfies both the B-level characteristic standard

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + \overset{gMgO}{\cancel{gMnO}} + hMnO$ (wherein $\overset{M_2O_3}{\cancel{M_2O_3}}$ represents at least one of either Sc_2O_3 or Y_2O_3 and R_2O_3 represents at least one of the compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, α, β, γ, g and h representing mole ratio, respectively), the $\overset{M_2O_3}{\cancel{Mn_2O_3}}$ content α of less than 0.001 as shown in the sample No. 1 is not preferable because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

On the other hand, the ~~Mn_2O_3~~ M_2O_3 content α of more than 0.05 as shown in the sample No. 2 is also not preferable because the specific dielectric constant is reduced to less than 1000. Accordingly, the preferable range of the Mn_2O_3 content α is $0.001 \leq \alpha \leq 0.05$.

It is not preferable that the R_2O_3 content β is less than 0.001 as in the sample No. 3 since the insulation resistance is so low that the product CR becomes small. It is also not preferable that the R_2O_3 content β is more than 0.05 as in the sample No. 4 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, reducing the reliability. Accordingly, the preferable range of the R_2O_3 content β is $0.001 \leq \beta \leq 0.05$.

When the combined amount of M_2O_3 and R_2O_3 $(\alpha + \beta)$ is more than 0.06, the dielectric loss is increased up to 2.0% while the mean life span is shortened, being not preferable since the number of rejects in the humidity resistance load test is increased. Accordingly, the combined amount of M_2O_3 and R_2O_3 $(\alpha + \beta)$ is preferably in the range of $\alpha + \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 6, the $BaZrO_3$ content γ is zero since the insulation resistance becomes low while having a larger voltage dependency of the insulation resistance than in the system

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

containing $BaZrO_3$. On the other hand, when the $BaZrO_3$ content γ exceeds 0.06 as in the sample No. 7, the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, being not preferable since the mean life span is shortened. Accordingly, the preferable range of the $BaZrO_3$ content γ is $0.005 \leq \gamma \leq 0.06$.

It is not preferable that, as seen in the sample No. 8, the MgO content g is 0.001 since the insulation resistance becomes low besides the temperature characteristics noes not satisfy the B-level characteristic / X7R characteristic. On the other hand, when the MGO content g exceeds 0.12 as seen in the sample No. 9, the sintering temperature becomes high and the dielectric loss exceeds 2.0%, which is not preferable because rejections in the humidity resistance test are extremely increased while shortening the mean life span. Accordingly, the preferable range of the MgO content g is $0.001 \leq g \leq 0.12$.

It is not preferable that, ~~as seen in the sample No. 12~~, the MnO content h is 0.001 as seen in the sample No. 10 since the sample becomes not measurable due to semiconductor formation. It is not preferable that the MnO content h exceeds 0.12, on the other hand, because the temperature characteristic X7R is not satisfied along with the insulation resistance becomes low and the mean life span

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

becomes short. Accordingly, the preferable MnO content h is in the range of $0.001 < h \leq 0.12$.

It is not preferable that, as seen in the sample No. 12, the combined content of MgO and MnO (g + h) exceeds 0.13 because the dielectric loss is increased to 2.0%, the mean life span is shortened and the number of rejects in the humidity resistance load test is increased. Accordingly, the combined content of MgO and MnO (g + h) is preferably in the range of $g + h \leq 0.13$.

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 13 because measurements are impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 14, that the BaO/TiO_2 ratio m is 1.000 since the insulation resistance as well as the AC and DC breakdown voltage becomes low along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 since measurements becomes impossible due to insufficient sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 17 and 19 because measurements are impossible due to insufficient sintering. When the amount of addition of the

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

first or second side component exceeds 3.0 parts by weight as seen in the samples No. 18 and 20, the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span, which are not preferable. Accordingly, the preferable content of either the first or the second components is 0.2 to 3.0 parts by weight.

The contents of the alkali ~~earth~~ metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, when the contents of the alkali earth metal oxides exceeds o.02% by weight, the dielectric constant is decreased.

(Example 2)

A starting material $BaO_{1.010} \cdot TiO_2$ + $0.010Y_2O_3$ + $0.02Gd_2O_3$ + $0.01BaZrO_3$ + 0.05MgO + 0.01MnO (mole ratio) was prepared using barium titanate "A" in TABLE 1~~A~~ as a dielectric powder, in which Li_2O-(Si, Ti)O_2-MO oxide with a mean particle size of 1 μm or less shown in TABLE 6 prepared by heating at 1200 to 1500 °C was added as a first side component. A monolithic ceramic capacitor was prepared by the same method as in Example 1, except that the starting material as described above was used. The overall dimensions of the monolithic ceramic capacitor produced are the same as in Example 1.

This Sheet Has Been Replaced

TABLE 6

Then, the electric characteristics were measured by the same method as described in ~~Table 7~~ Example 1. The results are shown in TABLE 7.

TABLE 7

As is evident from TABLE 6 and TABLE 7, preferable results are obtained in the samples No. 101 to 112, 118 and 120, in which oxides with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 20, y = 80, z = 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (X = 45, y = 45, z = 10) and F (X = 45, y = 55, z = 0) in the three component phase diagram of the oxides represented by Li_2O-(Si_w, Ti_{1-w})O_2-MO shown in FIG. 4 are added, wherein the samples have a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard

in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

The insulation resistance represented by the product CR at 25 °C and 150 °C shows as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the capacitor used under a electric field strength of 10 kV/mm. The insulation breakdown voltages are as high as 12 kV/mm or more under AC voltage and 14 kV/mm or more under a DC voltage. The mean life span is as long as 800 hours or more in the acceleration test at 150 °C and DC 25 kV/mm while enabling a relatively low firing temperature of 1300 °C or less.

On the contrary, when the Li_2O-(Si_w, Ti_{1-w})O_2-MO oxides is outside of the composition range described above, the sintering becomes insufficient or many samples are rejected in the humidity resistance load test even after sintering in the samples No. 113 to 117 and 119. The samples with the composition falling on the line A-F and w = 1.0 as in the samples No. 119 and 121, the sintering temperature becomes high along with causing many rejects in the humidity resistance load test. When the value of w is less than 0.30 as shown in the sample No. 122, the sintering temperature becomes high along with causing many rejects in the humidity

This Sheet Has Been Replaced

resistance load test.

(Example 3)

A starting material $BaO_{1.010} \cdot TiO_2$ + $0.01Y_2O_3$ + $0.01Eu_2O_3$ + $0.01Gd_2O_3$ + $0.01BaZrO_3$ + 0.05MgO + 0.01MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder, in which oxides represented by SiO_2-TiO_2-XO with a mean particle size of 1 μm or less shown in TABLE 8 prepared by heating at 1200 to 1500 °C was added as a second side component. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that the starting material as described above was used. The amounts of addition of Al_2O_3 and ZrO_2 correspond to the amounts of addition relative to 100 parts by weight of the second side component ($xSiO_2$-$yTiO_2$-zXO). The overall dimensions of the monolithic capacitor produced is the same as in Example 1.

TABLE 8

Then, the electric characteristics were measured as in Example 1. The results are shown in TABLE 9.

TABLE 9

THIS SHEET HAS BEEN REPLACED

As is evident from TABLE 8 and TABLE 9, preferable results are obtained in the samples No. 201 to 212, in which oxides with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60), wherein x, y and z represent mole %, in the three component phase diagram of the SiO_2-TiO_2-XO oxides shown in FIG. 5 are added, wherein the samples have a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

When the capacitor is used under a high electric field strength of 10 kV/mm, the insulation resistance represented by the product CR at 25 °C and 150 °C show a high value of 5000 Ω·F or more and 200 Ω·F or more, respectively. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. The mean life span in the

This Sheet Has Been Replaced

acceleration test at 150 °C and DC 25 kV/mm is as long as 800 hours along with being free from rejects in the humidity resistance load test and being possible to sinter at a relatively low sintering temperature of 1300 °C.

In the SiO_2-TiO_2-XO oxide, on the other hand, sintering becomes insufficient as in samples No. 213 to 219 or rejects occur in the humidity resistance load test even after sintering.

Although a monolithic capacitor having 5400 Ω·F or more and 300 Ω·F or more of the insulation resistances at 25 °C and 150 °C, respectively, under the electric field strength of 10 kV/mm, the sintering property is extremely deteriorated when the amounts of addition of Al_2O_3 and ZrO_2 exceed 15 parts by weight and 5 parts by weight, respectively.

(Example 4)

Four kinds of barium titanate ($BaTiO_3$) in TABLE 1, an oxide powder as a first side component and an oxide powder as a second side component were obtained by the same method as in Example 1.

Next, $BaCO_3$ for adjusting the Ba/Ti mole ratio m of barium titanate, and Sc_2O_3, ~~Y_2O_3~~ Y_2O_3, Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, and $BaZrO_3$ and MnO, each having a purity of 99% or more,

THIS SHEET HAS BEEN REPLACED

were prepared. These raw material powders and the foregoing oxide powder as one of the side component of either the first or the second component were weighed to be the compositions shown in TABLE 10 and TABLE 11. The amounts of addition of the first and second side components correspond to the amount of addition relative to 100 parts by weight of the essential component $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$). A monolithic ceramic capacitor was produced using this weighed materials by the same method as in Example 1. Overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1.

TABLE 10

TABLE 11

The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 12 and TABLE 13.

TABLE 12

TABLE 13

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

As is evident from TABLE 10 to TABLE 13, the monolithic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, when the capacitor is used under a high electric field strength of 10 kV/mm, the insulation resistance represented by the product CR at 25°C and 150°C shows a high value of 4900 Ω·F or more and 200 Ω·F or more, respectively. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm under the DC voltage. The mean life span in the acceleration test at 150°C and DC 25 kV/mm is as long as 800 hours along with being possible to sinter at a relatively low sintering temperature of 1300°C.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$ (wherein M_2O_3 represents at least one of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

either Sc_2O_3 or Y_2O_3 and R_2O_3 represents at least one of the compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, α, β, γ and g representing mole ratio, respectively), the ~~Mn_2O_3~~ M_2O_3 content α of less than 0.001 as shown in the sample No. 301 is not preferable because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic. On the other hand, the ~~Mn_2O_3~~ M_2O_3 content α of more than 0.05 as shown in the sample No. 302 is also not preferable because the specific dielectric constant is reduced to less than 900. Accordingly, the preferable range of the ~~Mn_2O_3~~ M_2O_3 content α is $0.001 \leq \alpha \leq 0.05$.

It is not preferable that the R_2O_3 content β of less than 0.001 as in the sample No. 303 since the insulation resistance is so low that the product CR becomes small. It is also not preferable that the R_2O_3 content β is more than 0.05 as in the sample No. 304 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, reducing the reliability. Accordingly, the preferable range of the R_2O_3 content β is $0.001 \leq \beta \leq 0.05$.

When the combined amount of M_2O_3 and R_2O_3 (α + β) is more than 0.06 as in the sample No. 305, the dielectric loss is increased up to 2.0% while the mean life span is shortened, being not preferable since the number of rejects

This Sheet Has Been Replaced

in the humidity resistance load test is increased. Accordingly, the combined amount of M_2O_3 and R_2O_3 ($\alpha + \beta$) is preferably in the range of $\alpha + \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 306, the $BaZrO_3$ content γ is zero since the insulation resistance becomes low while having a larger voltage dependency of the insulation resistance than in the system containing $BaZrO_3$. On the other hand, when the $BaZrO_3$ content γ exceeds 0.06 as in the sample No. 307, the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, being not preferable since the mean life span is shortened. Accordingly, the preferable range of the $BaZrO_3$ content γ is $0.005 \leq \gamma \leq 0.06$.

It is not preferable that, as seen in the sample No. 308, the ~~MgO~~ MnO content g is 0.001 since measurements are impossible due to semiconductor formation. On the other hand, it is not preferable that the ~~MgO~~ MnO content g exceeds 0.13 as seen in the sample No. 309 because the temperature characteristic X7R is not satisfied besides the insulating resistance is low and the mean life span becomes short. Accordingly, the preferable range of the ~~MgO~~ MnO content g is $0.001 \leq g \leq 0.13$.

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 310 because measurements are

THIS SHEET HAS BEEN
REPLACED

impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 311, the BaO/TiO_2 ratio m is 1.000 since the insulation resistance as well as the AC and DC breakdown voltage becomes low along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 as in the samples No. 312 and 313 since measurements becomes impossible due to insufficient sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 314 and 316 because measurements are impossible due to insufficient sintering. It is not preferable that the amount of addition of the first or second side component exceeds 3.0 parts by weight as seen in the samples No. 315 and 317, the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span. Accordingly, the preferable content of either the first or the second components is 0.2 to 3.0 parts by weight.

The contents of the alkali earth metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, when the contents of the

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

alkali earth metal oxides exceeds 0.02% by weight as in the sample No. 318, the dielectric constant is decreased.

(Example 5)

A starting material of the composition of $BaO_{1.010}\cdot TiO_2$ + $0.01Y_2O_3$ + $0.02Dy_2O_3$ + $0.01BaZrO_3$ + 0.06MnO (mole ration) was prepared using barium titanate in TABLE 1A as a dielectric powder, in which oxides represented by LI_2O-(Si, Ti)O_2-MO with a mean particle size of 1 μm or less shown in TABLE 6 prepared by heating at 1200 to 1500 °C was added as a first side component. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that the starting material as described above was used. The overall dimensions of the monolithic capacitor is the same as in Example 1. The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 14. The samples No. 401 to 422 in TABLE 14 correspond to the samples No. 101 to 122 in TABLE 6, respectively, wherein, for example, the side component in the sample No. 101 in TABLE 6 is added to the sample No. 401 in TABLE 14.

TABLE 14

As is evident from TABLE 14, preferable results are obtained in the samples No. 401 to 412, 418 and 420, in

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

which oxides in the samples No. 101 to 112, 118 and 120 in TABLE 6 with compositions within or on the boundary line of the area surrounded by the straight lines connecting each spot indicated by A (X = 20, y = 80, z = 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (X = 45, y = 45, z = 10) and F (X = 45, y = 55, z = 0), wherein x, y and z represent mole % and w is mole ratio, in the three component phase diagram of the Li_2O-$(Si_w, Ti_{1-w})O_2$-MO oxides shown in FIG. 4 are added, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

When the capacitor is used under a high electric field strength of 10 kV/mm, the insulation resistance represented by the product CR at 25 °C and 150 °C show a high value of 4900 Ω·F or more and 200 Ω·F or more, respectively. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm under the DC

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

voltage. The mean life span in the acceleration test at 150 °C and DC 25 kV/mm is as long as 800 hours along with being possible to sinter at a relatively low sintering temperature of 1300 °C.

On the contrary, when the oxides represented by Li_2O-$(Si_w, Ti_{1-w})O_2$-MO is outside of the composition range described above as in the samples No. 113 to 117 and 119 in TABLE 6, the sintering becomes insufficient or many samples are rejected in the humidity resistance load test even after sintering as seen in the samples No. 413 to 417 and 419. The samples with the composition falling on the line A-F and W = 1.0 have high sintering temperature along with causing many rejects in the humidity resistance load test as seen in the samples No. 119 and 121 in TABLE 14. When the value of w is less than 0.30 as shown in the sample No. 122 in TABLE 6, the sintering temperature becomes high along with causing many rejects in the humidity resistance load test as seen in the sample NO. 433 in TABLE 14.

(Example 6)

A starting material with a composition of $BaO_{1.010}TiO_2$ + $0.01Y_2O_3$ + $0.01Eu_2O_3$ + $0.01Tb_2O_3$ + $0.015BaZrO_3$ + 0.06MnO (mole ration) was prepared using barium titanate in TABLE 1A as a dielectric powder, in which the oxide represented by SiO_2-

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

TiO_2-XO with a mean particle size of 1 μm or less as shown in TABLE 8 prepared by heating at 1200 to 1500 °C was added as a second side component. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that the starting material as described above was used. The overall dimensions of the monolithic capacitor produced is the same as in Example 1. The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 15. The samples No. 501 to 519 in TABLE 15 correspond to the samples No. 201 to 219 in TABLE 8, respectively, wherein, for example, the sample No. 501 in TABLE 15 was obtained by adding the side component in the sample No. 201 in TABLE 8.

TABLE 15

As is evident from the samples No. 501 to 512 in TABLE 15, preferable results are obtained in the samples in which the oxides of the samples No. 201 to 212 in TABLE 8 with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60), wherein x, y and z represent mole %, in the three

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

component phase diagram of the oxides represented by SiO_2-TiO_2-XO shown in FIG. 5 are added, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

When the capacitor is used under a high electric field strength of 10 kV/mm, the insulation resistance represented by the product CR at 25 °C and 150 °C show a high value of 4900 Ω·F or more and 200 Ω·F or more, respectively. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm under the DC voltage. The mean life span in the acceleration test at 150 °C and DC 25 kV/mm is as long as 800 hours along with being free from rejections in the humidity resistance load test and being possible to sinter at a relatively low sintering temperature of 1300 °C.

On the contrary, when the SiO_2-TiO_2-XO oxides is outside of the composition range described above as in the samples No. 213 to 219 in TABLE 8, the sintering becomes

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

insufficient or many samples are rejected in the humidity resistance load test even after sintering as seen in the samples No. 513 to 519 in TABLE 15.

When Al_2O_3 and/or ZrO2 is allowed to contain in the oxides represented by SiO_2-TiO_2-XO as in the samples No. 211 and 212 in TABLE 8, a monolithic capacitor having the insulation resistances of 5300 Ω·F or more and 300 Ω·F or more at 25 °C and 150 °C, respectively, under an electric field strength of 10 kV/mm as the samples No. 511 and 512 in TABLE 15 can be obtained. However, when the amounts of addition of Al_2O_3 and ZrO_2 exceed 15 parts by weight and 5 parts by weight, respectively, as in the samples No. 217 and 218 in TABLE 8, the sintering property is extremely deteriorated as in the samples No. 217 and 218 in TABLE 8.

(Example 7)

After preparing and weighing $TiCl_4$ and $Ba(NO_3)_2$ having a variety of purity as starting materials, the compounds were precipitated as titanyl barium oxalate ($BaTiO(C_2O_4)\cdot 4H_2O$) by adding oxalic acid. This precipitate was decomposed by heating at a temperature of 1000 °C or more to synthesize four kinds of barium titanate listed in TABLE 1.

Oxides, carbonates or hydroxides as each component of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

the first side component were weighed so as to be a composition ratio (mole ratio) of $0.25Li_2O$-$0.65(0.30TiO_2 \cdot 0.70SiO_2)$-$0.10Al_2O_3$ to obtain a powder by crushing and mixing.

Likewise, oxides, carbonates or hydroxides as each component of the second side component were weighed so as to be a composition ratio (mole ratio) of $0.66SiO_2$-$0.17TiO_2$-$0.15BaO$-$0.02MnO$ to obtain a powder by crushing and mixing.

Oxide powders of the first and second side components were placed in separate platinum crucibles, respectively, and heated at 1500 °C. After quenching and crushing the mixture, each oxide powder with a mean particle size of 1 μm or less was obtained.

In the next step, $BaCO_3$ for adjusting the mole ratio Ba/Ti (m) in barium titanate, Sc_2O_3, Y_2O_3, $BaZrO_3$, MgO and MnO, each having a purity of 99% or more, were prepared. These raw material powders and the oxides described above to be either the first or second side component were weighted so as to form the compositions shown in TABLE 1002 and TABLE 1003. The amounts of addition of the first and second side components are indicated by parts by weight relative to 100 parts by weight of the essential component represented by $((BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO)$.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

TABLE 1002

TABLE 1003

Organic solvents such as polyvinyl butyral binder and ethanol were added to the weighed compounds and the mixture was mixed in a ball mill in an wet state to prepare a ceramic slurry. This ceramic slurry was formed into a sheet by a doctor blade method to obtain a rectangular shaped green sheet with a thickness of 35 μm, followed by printing an electroconductive paste mainly composed of Ni on the ceramic green sheet to form an electroconductive paste layer for forming inner electrodes.

Then, a plurality of the ceramic green sheets on which the electroconductive layer is formed were laminated so that the sides where the electroconductive paste is projected out are alternately placed with each other, thus obtaining a monolithic body. This monolithic body was heated at 350 °C in a N_2 atmosphere and, after allowing the binder to decompose, the monolithic body was fired at the temperatures shown in TABLE 1004 and TABLE 1005 in a reducing atmosphere comprising H_2-N_2-H_2O gases under an oxygen partial pressure of 10^{-9} to 10^{-12} MPa for two hours, thereby obtaining a ceramic sintered body.

This Sheet Has Been Replaced

The both side faces of the ceramic sintered body were coated with a silver paste containing B_2O_3-Li_2O-SiO_2-BaO glass frits and fired at a temperature of 600 °C in a N_2 atmosphere, thereby obtaining outer electrodes electrically connected to the inner electrodes.

The overall dimensions of the monolithic ceramic capacitor thus obtained were 5.0 mm in width, 5.7 mm in length and 2.4 mm in thickness while the thickness of the dielectric ceramic layer was 30 μm. Total number of the effective dielectric ceramic layers were 57, the area of the confronting electrode per one layer being $8.2 \times 10^{-6} m^2$.

Electric characteristics of these monolithic ceramic capacitors were measured. The electrostatic capacitance (C) and dielectric loss (tan δ) were measured using an automatic bridge type measuring instrument at 1 kHz, 1 Vrms and 25 °C and the dielectric constant (ε) was calculated from the electrostatic capacitance. Next, the insulation resistance was measured using an insulation resistance tester at 25 °C and 150 °C by impressing direct current voltages of 315 V (or 10 kV/mm) and 945 V (or 30 kV/mm) for 2 minutes, obtaining a product of the electrostatic capacitance and insulation resistance, or a product CR.

The rate of change of the electrostatic capacitance against temperature changes was also measured. The rate of

THIS SHEET HAS BEEN
REPLACED

change at -25 °C and 85 °C by taking the electrostatic capacitance at 20 °C as a standard ($\Delta C/C20$), the rate of change at -55 °C and 125 °C by taking the electrostatic capacitance at 20 °C as a standard ($\Delta C/C25$) and the maximum value of the rate of change ($|\Delta C|max$) as an absolute value were measured as the electrostatic capacitances against temperature changes.

The DC vias characteristic was also evaluated. First, the electrostatic capacitance when an AC voltage of 1 kHz and 1 Vrms was impressed was measured. Then, the electrostatic capacitance when a DC voltage of 150 V and an AC voltage of 1 kHz and 1 Vrms were simultaneously impressed was measured, thereby the rate of reduction of the electrostatic capacitance ($\Delta C/C$) due to loading the DC voltage was calculated.

In the high temperature load test, a direct current voltage of 750 V (or 25 kV/mm) was impressed at 150 °C on 36 pieces of each sample to measure the time dependent changes of the insulation resistance. The time when the insulation resistance of each sample was reduced below $10^6\Omega$ was defined to be a life span time and mean life span time was evaluated.

In the humidity resistance test, the number of the test pieces having an insulation resistance of $10^6\Omega$ or less

This Sheet Has Been Replaced

among the 72 test pieces were counted after impressing a DC voltage of 315 V under an atmospheric pressure of 2 atm (relative humidity 100%) at 120 °C for 250 hours.

Insulation breakdown voltages under AC and DC voltages were measured by impressing AC and DC voltages at a voltage increase rate of 100 V/sec.

The results described above are listed in TABLE 1004 and TABLE 1005.

TABLE 1004

TABLE 1005

It is evident from Table 1002 to TABLE 1005 that the monolithic ceramic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of less than 1.0 %, wherein the rate of change against temperature changes satisfies both the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150

THIS SHEET HAS BEEN
REPLACED

°C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO$ (wherein M_2O_3 represents at least one of either Sc_2O_3 or Y_2O_3, α, β, γ, and g representing mole ratio, respectively), the ~~Mn_2O_3~~ M_2O_3 content α of less than 0.001 as shown in the sample No. 1001 is not preferable because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic. On the other hand, the ~~Mn_2O_3~~ M_2O_3 content α of more than 0.06 as shown in the sample No. 1002 is also not preferable because the specific dielectric constant is reduced to less than 1000. Accordingly, the preferable range of the ~~Mn_2O_3~~ M_2O_3 content α is $0.001 \leq \alpha \leq 0.06$.

It is not preferable that the $BaZrO_3$ content β of zero as in the sample No. 1003 is not preferable since the

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

insulation resistance is low and the voltage dependency of the insulating resistance is larger than that of the composition system containing $BaZrO_3$. It is also not preferable that the $BaZrO_3$ content β is more than 0.06 as in the sample No. 1004 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, along with shortening the mean life span. Accordingly, the preferable range of the $BaZrO_3$ content β is $0.005 \leq \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 1005, the MgO content γ is 0.001 since the insulation resistance becomes low and the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic. It is not preferable, on the other hand, that the MgO content γ exceeds 0.12 as in the sample No. 1006, because the sintering temperature becomes high, the dielectric loss exceeds 2.0%, the number of rejections in the humidity resistance load test is extremely increased along with shortening the mean life span. Accordingly, the preferable range of the MgO content γ is in the range of $0.001 < \gamma \leq 0.12$.

It is not preferable that, as seen in the sample No. 1007, the MnO content g is 0.001 since measurement becomes impossible due to formation of semiconductors. It is not

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

preferable, on the other hand, that the MnO content g exceeds 0.12 as seen in the sample No. 1008 because the temperature characteristic X7R is not satisfied and the insulation resistance is lowered besides the mean life span becomes short. Accordingly, the preferable range of the MnO content g is in the range of $0.001 < g \leq 0.12$.

It is not preferable that, as in the sample No. 1009, the combined amount of $\gamma + g$ of the MgO content γ and MnO content g exceeds 0.13 because the dielectric loss is increased to 2.0% and the mean life span is shortened besides the rejection number in the humidity resistance load test increases. Accordingly, the combined amount of $\gamma + g$ of the MgO content γ and MnO content g is preferably in the range of $\gamma + g \leq 0.13$.

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 1010 because measurements are impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 1011, the BaO/TiO_2 ratio m is 1.000 since the insulation resistance as well as the AC and DC breakdown voltage are lowered along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 as in the samples No. 1012 and 1013 since measurements becomes impossible due to insufficient

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 1014 and 1016 because measurements are impossible due to insufficient sintering. It is not preferable that the amount of addition of the first or second side component exceeds 3.0 parts by weight as seen in the samples No. 1015 and 1017, because the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span. Accordingly, the preferable content of either the first or the second components is 0.2 to 3.0 parts by weight.

The contents of the alkali earth metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, when the contents of the alkali earth metal oxides exceeds 0.02% by weight as in the sample No. 1018, the dielectric constant is decreased.

(Example 8)

A material with a composition of $BaO_{1.010} \cdot TiO_2 + 0.03Y_2O_3 + 0.02BaZrO_3 + 0.05MgO + 0.01\ MnO$ (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

as in Example 1, except that an oxide represented by Li_2O-(Si, Ti)O_2-MO shown in Table ~~1005~~ 1006, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the first side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1.

TABLE 1006

The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 1007.

TABLE 1007

As is evident from TABLE 1006 and TABLE 1007, preferable results are obtained in the samples No. 1101 to 1112, 1118 and 1120, in which oxides with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 20, y = 80, z = 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (X = 45, y = 45, z = 10) and F (x = 45, y = 55, z = 0), (wherein x, y and z represent mole % and w represents mole ratio, which is in

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

the range of $0.3 \leq w < 1.0$ in the composition on the line A - F) of the three component phase diagram of the oxides represented by Li_2O-(Si_w, Ti_{1-w})O_2-MO shown in FIG. 4 are added, wherein the samples have a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

On the contrary, when the Li_2O-(Si_w, Ti_{1-w})O_2-MO oxides is outside of the composition range described above as shown

This Sheet Has Been Replaced

in the samples No. 1113 to 1117, and 1119, the sintering becomes insufficient or many samples are rejected in the humidity resistance load test even after sintering. The samples with the composition falling on the line A-F and W = 1.0 as in the samples No. 1119 and 1121 have high sintering temperature along with causing many rejects in the humidity resistance load test. When the value of w is less than 0.30 as shown in the sample No. 1122, the sintering temperature becomes high along with causing many rejects in the humidity resistance load test.

(Example 9)

A material with a composition of $BaO_{1.010} \cdot TiO_2$ + $0.03Sc_2O_3$ + $0.015BaZrO_3$ + 0.05MgO + 0.01 MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide Li_2O-TiO_2-XO shown in Table 1008, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the second side component. The amounts of addition of Al_2O_3 and ZrO_2 correspond to parts by wight relative to 100 parts by weight of ($xSiO_2$ ~~w~~ $yTiO_2$ ~~w~~ zXO). The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1.

THIS SHEET HAS BEEN REPLACED

TABLE 1008

The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 1009.

TABLE 1009

As is evident from TABLE 1008 and TABLE 1009, preferable results are obtained in the samples No. 1201 to 1212 in which oxides with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60), (wherein x, y and z represent mole %) of the three component phase diagram of the oxides represented by SiO_2-TiO_2-XO shown in FIG. 5 are added, wherein the samples have a capacitance decreasing ratio of as small as -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

When the composition of the oxide represented by SiO_2-TiO_2-XO is out of the composition range described above, on the other hands, sintering becomes insufficient as seen in the samples No. 1213 to 1219 or many rejects occur in the humidity resistance load test even after the sintering.

When Al_2O_3 and/or ZrO2 is allowed to contain in the oxides represented by SiO_2-TiO_2-XO as in the samples No. 1211 and 1212, a monolithic capacitor having the insulation resistances of 5400 Ω·F or more and 300 Ω·F or more at 25 °C and 150 °C, respectively, under an electric field strength of 10 kV/mm can be obtained. However, when the amounts of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

addition of Al_2O_3 and ZrO_2 exceed 15 parts by weight and 5 parts by weight, respectively, the sintering property is extremely deteriorated as in the samples No. 1217 and 1218.

(Example 10)

Four kinds of barium titanate ($BaTiO_3$) in TABLE 1, an oxide powder as a first side component and an oxide powder as a second side component were obtained by the same method as in Example 1.

Then, $BaCO_3$ for adjusting the Ba/Ti mole ratio m in barium titanate, and Sc_2O_3, Y_2O_3, $BaZrO_3$ and MnO with purity of 99% or more were prepared. These raw material powder and oxide powder to be either the first or second side component were weighed so as to be the composition shown in TABLE 1010 and TABLE 1011. The amount of addition of the first or second side component corresponds to the amount relative to 100 parts of the essential component of $((BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MnO)$. A monolithic ceramic capacitor was produced using this weighed compounds by the same method as in Example 1. The overall dimensions of the monolithic ceramic capacitor produced are the same as in Example 1.

TABLE 1010

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

TABLE 1011

The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 1012 and TABLE 1013.

TABLE 1012

TABLE 1013

As evident from TABLE 1012 and TABLE 1013, the ceramic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -40% at an impressed DC voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 4900 Ω·F or more and 190 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MnO$ (wherein M_2O_3 represents at least one of either Sc_2O_3 and Y_2O_3, α, β, and γ representing mole ratio, respectively), the M_2O_3 ~~Mn_2O_3~~ content α of less than 0.001 as shown in the sample No. 1301 is not preferable because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic. On the other hand, the M_2O_3 ~~Mn_2O_3~~ content α of more than 0.06 as shown in the sample No. 1302 is also not preferable because the specific dielectric constant is reduced to less than 900. Accordingly, the preferable range of the M_2O_3 ~~Mn_2O_3~~ content α is $0.001 \leq \alpha \leq 0.06$.

It is not preferable that the $BaZrO_3$ content β of zero as in the sample No. 1303 is not preferable since the insulation resistance is low and the voltage dependency of the insulating resistance is larger than that of the composition system containing $BaZrO_3$. It is also not

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

preferable that the $BaZrO_3$ content β is more than 0.06 as in the sample No. 1304 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, along with shortening the mean life span. Accordingly, the preferable range of the $BaZrO_3$ content β is $0.005 \leq \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 1305, the MgO content γ is 0.001 since measurements becomes impossible due to semiconductor formation. It is not preferable that the MgO content γ exceeds 0.13 as in the sample No. 1306, because the temperature characteristic does not satisfy the X7R characteristic besides the insulation resistance is low and mean life span is shortened. Accordingly, the preferable range of the MgO content γ is in the range of $0.001 < \gamma \leq 0.13$.

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 1307 because measurements are impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 1308, the BaO/TiO_2 ratio m is 1.000 since the insulation resistance as well as the AC and DC breakdown voltage becomes low along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 as in the samples No. 1309 and 1310 since

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

measurements becomes impossible due to insufficient sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 1311 and 1313 because measurements are impossible due to insufficient sintering. It is not preferable that the amount of addition of the first or second side component exceeds 3.0 parts by weight as seen in the samples No. 1312 and 1314, on the other hand, because the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span. Accordingly, the preferable content of either the first or the second components is in the range of 0.2 to 3.0 parts by weight.

The contents of the alkali earth metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, as in the sample No. 1315, when the contents of the alkali earth metal oxides exceeds 0.02% by weight, the dielectric constant is decreased.

(Example 11)

A material with a composition of $BaO_{1.010} \cdot TiO_2 + 0.02Y_2O_3 + 0.01BaZrO_3 + 0.04\ MnO$ (mole ratio) was prepared using

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide represented by Li_2O-$(Si,Ti)O_2$-MO as shown in Table 1006, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the first side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1. The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 1014. The sample No. 1401 to 1422 in TABLE 1014 correspond to the samples NO. 1101 to 1122 in TABLE 1006, respectively. For example, the sample No. 1401 in TABLE ~~1401~~ 1014 was obtained by adding the side component of the sample No. 1101 in TABLE 1006.

TABLE 1014

As is evident from the samples NO. 1401 to 1412, 1418 and 1420 in TABLE 1014, preferable results are obtained in the samples in which oxides of the samples No. 1101 to 1112, 1118 and 1120 in TABLE 1006 with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 20, y = 80, z

This Sheet Has Been Replaced

= 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (x = 45, y = 45, z = 10) and F (x = 45, y = 55, z = 0) (wherein x, y and z represent mole %, w represent mole ratio and w is in the range of 0.3 ≤ w < 1.0 in the composition on the line A - F) inside of the three component phase diagram of the oxides represented by Li_2O-(Si_w, Ti_{1-w})O_2-MO shown in FIG. 4 are added as side components, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 4900 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life

THIS SHEET HAS BEEN REPLACED

span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

On the contrary, when the oxides represented by Li_2O-$(Si_w, Ti_{1-w})O_2$-MO is outside of the composition range described above as shown in the samples No. 1113 to 1117, and 1119 in TABLE 1006, the sintering becomes insufficient or many samples are rejected in the humidity resistance load test even after sintering as seen in the samples NO. 1413 to 1417 and 1419 in TABLE 1014. The samples with the composition falling on the line A-F and W = 1.0 as in the samples No. 1119 and 1121 in TABLE 1006 have high sintering temperature along with causing many rejects in the humidity resistance load test as seen in the samples No. 1419 and 1421 in TABLE 1014. When the value of w is less than 0.30 as shown in the samples No. 1122 in TABLE 1006 ~~1122~~, the sintering temperature becomes high along with causing many rejects in the humidity resistance load test as seen in the sample No. 1422 in TABLE 1014.

(Example 12)

A material with a composition of $BaO_{1.010}\cdot TiO_2$ + $0.02Sc_2O_3$ + $0.01BaZrO_3$ + 0.04 MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

as in Example 1, except that an oxide represented by SiO_2-TiO_2-XO shown in Table 1008, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the second side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1. The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 1015. In TABLE 1015, the samples NO. 1501 to 1519 corresponds to the samples NO. 1201 to 1219 in TABLE 1008. For example, the sample No. 1501 in TABLE 1015 was obtained by adding the side component of the sample No. 1201 in TABLE 1008.

TABLE 1015

As is evident from Samples NO. 1501 to 1512 in TABLE 1015, preferable results are obtained in the samples, in which oxides of the samples NO. 1201 to 1212 in TABLE 1008 with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60), (wherein x, y and z represent mole %), of the three

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

component phase diagram of the oxides represented by SiO_2-TiO_2-XO shown in FIG. 5 are added as a side component, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 4900 Ω·F or more and 190 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more and no rejections were found in the humidity resistance load test besides enabling a relatively low firing temperature of 1300 °C or less.

When the oxide SiO_2-TiO_2-XO has a composition outside of the composition described above as in the samples No.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

1213 to 1219 in TABLE 1008, on the contrary, sintering becomes insufficient or many rejection appear in the humidity resistance load test even after sintering as seen in the samples No. 1513 to 1519 in TABLE 1015.

While a monolithic capacitor having an insulation resistance of 5290 Ω·F or more and 310 Ω·F or more at 25 °C and 150 °C, respectively, under a strong electric field of 10 kV/mm can be obtained as shown in the samples No. 1511 and 1512 in TABLE 1015 by allowing Al_2O_3 and/or ZrO_2 to contain in the SiO_2-TiO_2-XO oxides as in the sample No. 1211 and 1212 in Table 1008, sintering property is extremely decreased when Al_2O_3 and ZrO_2 are added in an amounts of 15 parts by weight or more and 5 parts by weight or more, respectively, as in the samples No. 1217 and 1218 in TABLE 1008.

(Example 13)

After preparing and weighing $TiCl_4$ and $Ba(NO_3)_2$ having a variety of purity as starting materials, the compounds were precipitated as titanyl barium oxalate ($BaTiO(C_2O_4)\cdot 4H_2O$) by adding oxalic acid. This precipitate was decomposed by heating at a temperature of 1000 °C or more to synthesize four kinds of barium titanate listed in TABLE 1.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

Oxides, carbonates or hydroxides as each component of the first side component were weighed so as to be a composition ratio (mole ratio) of $0.25Li_2O$-$0.65(0.30TiO_2 \cdot 0.70SiO_2)$-$0.10Al_2O_3$ to obtain a powder by crushing and mixing.

Likewise, oxides, carbonates or hydroxides as each component of the second side component were weighed so as to be a composition ratio (mole ratio) of $0.66SiO_2$-$0.17TiO_2$-$0.15BaO$-$0.02MnO$ (mole ratio) to obtain a powder by crushing and mixing.

Oxide powders of the first and second side components were placed in separate platinum crucibles and heated at 1500 °C. After quenching and crushing the mixture, each oxide powder with a mean particle size of 1 μm or less was obtained.

In the next step, $BaCO_3$ for adjusting the mole ratio Ba/Ti (m) in barium titanate, Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, and $BaZrO_3$, MgO and MnO, each having a purity of 99% or more, were prepared. These raw material powders and the oxides described above to be either one of the first or second side component were weighted so as to form compositions shown in TABLE 2002 and TABLE 2003. The amounts of addition of the first and second side components are indicated by parts by weight relative to 100 parts by

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

weight of the essential component $(BaO)_mTiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO$.

TABLE 2002

TABLE 2003

Organic solvents such as polyvinyl butyral binder and ethanol were added to the weighed compounds, which were mixed in a ball mill in an wet state to prepare a ceramic slurry. This ceramic slurry was formed into a sheet by a doctor blade method to obtain a rectangular shaped green sheet with a thickness of 35 μm, followed by printing an electroconductive paste mainly composed of Ni on the ceramic green sheet to form an electroconductive paste layer for forming inner electrodes.

Then, a plurality of the ceramic green sheets on which the electroconductive layer is formed were laminated so that the sides where the electroconductive paste is projected out are alternately placed with each other, thus obtaining a monolithic body. This monolithic body was heated at 350 °C in a N_2 atmosphere and, after allowing the binder to decompose, the monolithic body was fired at the temperatures shown in TABLE 2004 and TABLE 2005 in a reducing atmosphere

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

comprising H_2-N_2-H_2O gases under an oxygen partial pressure of 10^{-9} to 10^{-12} MPa for two hours, thereby obtaining a ceramic sintered body.

The both side faces of the ceramic sintered body were coated with a silver paste containing B_2O_3-Li_2O-SiO_2-BaO glass frits and fired at a temperature of 600 °C in a N_2 atmosphere, thereby obtaining outer electrodes electrically connected to the inner electrodes.

The overall dimensions of the monolithic ceramic capacitor thus obtained were 5.0 mm in width, 5.7 mm in length and 2.4 mm in thickness while the thickness of the dielectric ceramic layer was 30 μm. Total number of the effective dielectric ceramic layers were 57, the area of the confronting electrode per one layer being $8.2 \times 10^{-6} m^2$.

Electric characteristics of these monolithic ceramic capacitors were measured. The electrostatic capacitance (C) and dielectric loss (tan δ) were measured using an automatic bridge type measuring instrument at 1 kHz, 1 Vrms and 25 °C and the dielectric constant (ε) was calculated from the electrostatic capacitance. Next, the insulation resistance was measured using an insulation resistance tester at 25 °C and 150 °C by impressing direct current voltages of 315 V (or 10 kV/mm) and 945 V (or 30 kV/mm) for 2 minutes, obtaining a product of the electrostatic capacitance and

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

insulation resistance, or a product CR.

The rate of change of the electrostatic capacitance against temperature changes was also measured. The rate of change at -25 °C and 85 °C by taking the electrostatic capacitance at 20 °C as a standard ($\Delta C/C20$), the rate of change at -55 °C and 125 °C by taking the electrostatic capacitance at 20 °C as a standard ($\Delta C/C25$) and the maximum value of the rate of change ($|\Delta C|max$) as an absolute value in the temperature range of -55 °C to 125 °C were measured as the electrostatic capacitances against temperature changes.

The DC vias characteristic was also evaluated. First, the electrostatic capacitance when an AC voltage of 1 kHz and 1 Vrms was impressed was measured. Then, the electrostatic capacitance when a DC voltage of 150 V and an AC voltage of 1 kHz and 1 Vrms were simultaneously impressed was measured, thereby the rate of reduction of the electrostatic capacitance ($\Delta C/C$) due to loading the DC voltage was calculated.

In the high temperature load test, a direct current voltage of 750 V (or 25 kV/mm) was impressed at 150 °C on 36 pieces of each sample to measure the time dependent changes of the insulation resistance. The time when the insulation resistance of each sample was reduced below $10^6\Omega$ was defined

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

to be a life span time and mean life span time was evaluated.

In the humidity resistance test, the number of the test pieces having an insulation resistance of $10^6\Omega$ or less among the 72 test pieces were counted after impressing a DC voltage of 315 V under an atmospheric pressure of 2 atm (relative humidity 100%) at 120 °C for 250 hours.

Insulation breakdown voltages under AC and DC voltages were measured by impressing AC and DC voltages at a voltage increase rate of 100 V/sec.

The results described above are listed in TABLE 2004 and TABLE 2005.

TABLE 2004

TABLE 2005

It is evident from Table 2002 to TABLE 2005 that the monolithic ceramic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of less than 1.0 %, wherein the rate of change against temperature changes satisfies both the B-level characteristic standard stipulated in the JIS Standard

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO$ (wherein R_2O_3 represents at least one compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, α, β, γ, and g representing mole ratio, respectively), the ~~Mn_2O_3~~ R_2O_3 content α of less than 0.001 as shown in the sample No. 2001 is not preferable because the insulation resistance is low and the product CR becomes small. On the other hand, the ~~Mn_2O_3~~ R_2O_3 content α of more than 0.06 as shown in the sample No. 2002 is also not preferable because the

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, being poor in reliability. Accordingly, the preferable range of the ~~Mn_2O_3~~ R_2O_3 content α is $0.001 \leq \alpha \leq 0.06$.

The $BaZrO_3$ content β of zero as in the sample No. 2003 is not preferable since the insulation resistance is low and the voltage dependency of the insulating resistance is larger than that of the composition system containing $BaZrO_3$. It is also not preferable that the $BaZrO_3$ content β is more than 0.06 as in the sample No. 2004 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, along with shortening the mean life span. Accordingly, the preferable range of the $BaZrO_3$ content β is $0.005 \leq \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 2005, the MgO content γ is 0.001 since the insulation resistance becomes low and the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic. On the other hand, it is not preferable that the MgO content γ exceeds 0.12 as in the sample No. 2006, because the sintering temperature becomes high, the dielectric loss exceeds 2.0%, the number of rejections in the humidity resistance load test is extremely increased along with the mean life span being short. Accordingly, the

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

preferable range of the MgO content γ is in the range of $0.001 < \gamma \leq 0.12$.

It is not preferable that, as seen in the sample No. 2007, the MnO content g is 0.001 since measurement becomes impossible due to formation of semiconductors. It is not preferable, on the other hand, that the MnO content g exceeds 0.12 as seen in the sample No. 2008 because the temperature characteristic X7R is not satisfied and the insulation resistance is lowered besides the mean life span becomes short. Accordingly, the preferable range of the MnO content g is in the range of $0.001 < g \leq 0.12$.

It is not preferable that, as in the sample No. 2009, the combined amount of $\gamma + g$ of the MgO content and MnO content exceeds 0.13 because the dielectric loss is increased to 2.0% and the mean life span is shortened besides the rejection number in the humidity resistance load test increases. Accordingly, the combined amount of $\gamma + g$ of the MgO content and MnO content is preferably in the range of $\gamma + g \leq 0.13$.

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 2010 because measurements are impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 2011, the BaO/TiO_2 ratio m is 1.000 since the insulation

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

resistance as well as the AC and DC breakdown voltage becomes low along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 as in the samples No. 2012 and 2013 since measurements becomes impossible due to insufficient sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 2014 and 2016 because measurements are impossible due to insufficient sintering. It is not preferable that the amount of addition of the first or second side component exceeds 3.0 parts by weight as seen in the samples No. 2015 and 2017, on the other hand, because the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span. Accordingly, the preferable content of either the first or the second components is 0.2 to 3.0 parts by weight.

The contents of the alkali earth metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, when the contents of the alkali earth metal oxides exceeds 0.02% by weight as in the sample No. 2018, the dielectric constant is decreased.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

(Example 14)

A material with a composition of $BaO_{1.010}\cdot TiO_2$ + $0.03Gd_2O_3$ + $0.025BaZrO_3$ + 0.05MgO + 0.01 MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide represented by Li_2O-(Si, Ti)O_2-MO shown in Table 2006, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the first side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1.

TABLE 2006

The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 2007.

TABLE 2007

As is evident from TABLE 2006 and TABLE 2007, preferable results are obtained in the samples No. 2101 to 2112, 2118 and 2120 in which the oxides with compositions

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (X = 20, y = 80, z = 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (x = 45, y = 45, z = 10) and F (x = 45, y = 55, z = 0) (wherein x, y and z represent mole % and w represents mole ratio, w being in the range of $0.3 \leq w < 1.0$ when it falls on the line A - F) of the three component phase diagram of the oxides represented by Li_2O-(Si_w, Ti_{1-w})O_2-MO shown in FIG. 4 are added, wherein the samples have a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

When the oxide represented by Li_2O-$(Si_wTi_{1-w})O_2$-MO has a composition outside of the composition described above as in the samples No. 2113 to 2117 and 2119, on the other hand, sintering becomes insufficient or many rejection appear in the humidity resistance load test even after sintering. When the composition falls on the line A - F and w = 1.0, the sintering temperature becomes high, giving a lot of rejections in the humidity resistance load test as shown in the samples No. 2119 and 2121. When the value of w is less than 3.0, the sintering temperature becomes so high that many rejections appear in the humidity resistance test as shown in Sample No. 2122.

(Example 15)

A material with a composition of $BaO_{1.010}{\cdot}TiO_2$ + $0.03Dy_2O_3$ + $0.02BaZrO_3$ + 0.05 MgO + 0.01 MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide represented by SiO_2-TiO_2-XO shown in Table 2008, having a mean particle size of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the second side component. The amounts of addition of Al_2O_3 and ZrO_3 are indicated by parts by weight relative to 100 parts by weight of the second side component ($xSiO_2$-$yTiO_2$-zXO). The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1.

TABLE 2008

The electric characteristics were then measured by the same method as in Example 1. The results are shown in TABLE 2009.

TABLE 2009

As is evident from TABLE 2008 and TABLE 2009, preferable results are obtained in the samples No. 2201 to 2212, in which oxides with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (x = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60), (wherein x, y and z represent mole %), of the three component phase diagram of the oxides

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

represented by SiO_2-TiO_2-XO shown in FIG. 5 are added, wherein the samples have a capacitance decreasing ratio of as small as within -45% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more and no rejections were found in the humidity resistance load test besides enabling a relatively low firing temperature of 1300 °C or less.

When the oxide represented by SiO_2-TiO_2-XO has a composition outside of the composition described above as in the samples No. ~~1213~~ 2213 to ~~1219~~ 2219, on the contrary, sintering

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

becomes insufficient or many rejection appear in the humidity resistance load test even after sintering.

While a monolithic capacitor having an insulation resistance of 5400 Ω·F or more and 300 Ω·F or more at 25 °C and 150 °C, respectively, under a strong electric field of 10 kV/mm can be obtained by allowing Al_2O_3 and/or ZrO_2 to contain in the SiO_2-TiO_2-XO oxides as in the sample No. 2211 and 2212, sintering property is extremely decreased when Al_2O_3 and ZrO_2 are added in an amounts of 15 parts by weight or more and 5 parts by weight or more, respectively, as in the samples No. 2217 and 2218.

(Example 16)

Four kinds of barium titanate ($BaTiO_3$), an oxide powder as a first side component and an oxide powder as a second side component were obtained by the same method as in Example 1.

Then, $BaCO_3$ for adjusting the mole ratio Ba/Ti in barium titanate, Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, and MnO, each having a purity of 99% or more, were prepared. These raw material powders and the oxides described above to be either the first or the second component were weighed so as to be the composition in TABLE 2010 and TABLE 2011. The amounts of addition of the first

This Sheet Has Been Replaced

THIS SHEET HAS BEEN
REPLACED

and second side components are defined by the amount of addition relative to 100 parts by weight of $(BaO)_mTiO_2$ + αR_2O_3 + $\beta BaZrO_3$ + γMnO. A monolithic ceramic capacitor was produced by the same method as in Example 1 using these weighed materials. The overall dimensions of the monolithic ceramic capacitor are the same as in Example 1.

TABLE 2010

TABLE 2011

The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 2012 and TABLE 2013.

TABLE 2012

TABLE 2013

It is evident from Table 2010 to TABLE 2013 that the monolithic ceramic capacitor according to the present invention has a capacitance decreasing ratio of as small as within -40% or less at an impressed voltage of 5 kV/mm and a dielectric loss of less than 1.0 %, wherein the rate of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

change against temperature changes satisfies both the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

The reason why the composition was limited in the present invention will be described hereinafter.

In the composition of $(BaO)_mTiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MgO$ (wherein R_2O_3 represents at least one compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, α, β and γ representing mole ratio, respectively), the Mn_2O_3 content α of less than 0.001 as shown in the sample No. 2301 is not preferable because the temperature characteristics does not satisfy the B-level characteristics / X7R

This Sheet Has Been Replaced

characteristics. On the other hand, the Mn_2O_3 content α of more than 0.06 as shown in the sample No. 2302 is also not preferable because the specific dielectric constant becomes as small as less than 900. Accordingly, the preferable range of the Mn_2O_3 content α is $0.001 \leq \alpha \leq 0.06$.

The $BaZrO_3$ content β of zero as in the sample No. 2303 is not preferable since the insulation resistance is low and the voltage dependency of the insulating resistance is larger than that of the composition system containing $BaZrO_3$. It is also not preferable that the $BaZrO_3$ content β is more than 0.06 as in the sample No. 2304 because the temperature characteristic does not satisfy the B-level characteristic / X7R characteristic, along with shortening the mean life span. Accordingly, the preferable range of the $BaZrO_3$ content β is $0.005 \leq \beta \leq 0.06$.

It is not preferable that, as seen in the sample No. 2305, the MgO content γ is 0.001 since measuring is impossible due to formation of semiconductors. On the other hand, it is not preferable that the MgO content γ exceeds 0.13 as in the sample No. 2306, because the temperature characteristic X7R is not satisfied and the insulation capacitance is low along with the mean life span being short. Accordingly, the Mn content γ is preferably in the range of $0.001 \leq \gamma < 0.13$.

THIS SHEET HAS BEEN
REPLACED

It is not preferable that the BaO/TiO_2 ratio m is less than 1.000 as in the sample No. 2307 because measurements are impossible due to formation of semiconductors. It is also not preferable that, as seen in the sample No. 2308, the BaO/TiO_2 ratio m is 1.000 since the insulation resistance as well as the AC and DC breakdown voltage becomes low along with shortening the mean life span. It is not preferable, on the other hand, that the BaO/TiO_2 ratio m is over 1.035 as in the samples No. 2309 and 2310 since measurements becomes impossible due to insufficient sintering. Accordingly, the BaO/TiO_2 ratio m in the range of $1.000 < m \leq 1.035$ is preferable.

It is not preferable that the amount of addition of the first or second side component is zero as in the samples No. 2311 and 2313 because measurements are impossible due to insufficient sintering. It is not preferable that the amount of addition of the first or second side component exceeds 3.0 parts by weight as seen in the samples No. 2312 and ~~314~~ 2314, on the other hand, because the dielectric loss exceeds 1.0% and the insulation resistance and insulation breakdown voltage are lowered along with shortening the mean life span. Accordingly, the preferable content of either the first or the second components is 0.2 to 3.0 parts by weight.

This Sheet Has Been Replaced

The contents of the alkali earth metal oxides contained in barium titanate as impurities are suppressed below 0.02% by weight because, when the contents of the alkali earth metal oxides exceeds 0.02% by weight as in the sample No. 2315, the dielectric constant is decreased.

(Example 17)

A material with a composition of $BaO_{1.010}\cdot TiO_2$ + $0.015Ho_2O_3$ + $0.01BaZrO_3$ + 0.03 MnO (mole ratio) was prepared using barium titanate in TABLE 1A as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide represented by Li_2O-(Si, Ti)O_2-MO shown in Table 2006, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the first side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1. The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 2014. In Table 2014, the samples No. 2401 to 2422 correspond to the samples No. 2101 to 2122 in TABLE 2006. For example, the sample No. 2401 in TABLE 2014 was obtained by adding the side component of the sample No. 2101 in TABLE 2006.

THIS SHEET HAS BEEN REPLACED

TABLE 2014

As is evident from the samples No. 2401 to 2412, 2418 and 2420, preferable results are obtained in the samples in which oxides of the samples No. 2101 to 2112, 2118 and 2120 in TABLE 2006 with compositions within or on the boundary lines of the area surrounded by the straight lines connecting each spot indicated by A (x = 20, y = 80, z = 0), B (X = 10, y = 80, z = 10), C (X = 10, y = 70, z = 20), D (X = 35, y = 45, z = 20), E (x = 45, y = 45, z =10) and F (x = 45, y = 55, z = 0) (wherein x, y and z represent mole %, w represents mole ratio, w being within the range of $0.3 \leq w < 1.0$ when it falls on the line A - F) in the three component phase diagram of the oxides represented by Li_2O-(Si_w, Ti_{1-w})O_2-MO in FIG. 4 are added, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150

This Sheet Has Been Replaced

°C as expressed by the product CR show as high values as 5000 Ω·F or more and 190 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

When the oxide represented by $Li_2O-(Si_w, Ti_{1-w})O_2-MO$ has a composition outside of the composition described above as in the samples No. 2113 to 2117 and 2119, on the other hand, sintering becomes insufficient or many rejection appear in the humidity resistance load test even after sintering as seen in the samples No. 2413 to 2417 and 2419 in TABLE 2014. When the composition falls on the line A - F and w = 1.0 as in the samples No. 2119 and 2121 in TABLE 2006, the sintering temperature becomes high and many rejects appear in the humidity resistance load test. When the value of w is less than 0.30 as in the sample No. 2122 in TABLE 2006, he sintering temperature becomes high and many rejects appear in the humidity resistance load test as seen in the sample No. 2422 in TABLE 2014.

THIS SHEET HAS BEEN REPLACED

(Example 18)

A material with a composition of $BaO_{1.010}TiO_2$ + $0.025Eu_2O_3$ + $0.01BaZrO_3$ + 0.05 MnO (mole ratio) was prepared using barium titanate "A" in TABLE 1 as a dielectric powder. A monolithic ceramic capacitor was produced by the same method as in Example 1, except that an oxide SiO_2-TiO_2-XO ~~$Li_2O-(Si, Ti)O_2-MO$~~ shown in Table 2008 ~~2006~~, having a mean particle size of 1 μm or less produced by heating the material described above at 1200 to 1500 °C, was added as the second side component. The overall dimensions of the monolithic ceramic capacitor produced is the same as in Example 1. The electric characteristics were measured by the same method as in Example 1. The results are shown in TABLE 2015. In Table 2015, the samples No. 2501 to 2519 in TABLE 2015 correspond to the samples No. 2201 to 2219 in TABLE 2008. For example, the sample No. 2501 in TABLE 2015 was obtained by adding the side component of the sample No. 2201 in TABLE 2008.

TABLE 2015

As is evident from the samples No. 2501 to 2512 ~~2412~~ in TABLE 2015 , preferable results are obtained in the samples in which oxides of the samples No. 2201 to 2212 in TABLE 2008 with compositions within or on the boundary lines of

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

the area surrounded by the straight lines connecting each spot indicated by A (x = 85, y = 1, z = 14), B (X = 35, y = 51, z = 14), C (X = 30, y = 20, z = 50) and D (X = 39, y = 1, z = 60) (wherein x, y and z represent mole %) in the three component phase diagram of the SiO_2-TiO_2-XO oxides shown in FIG. 5 are added, wherein the samples have a capacitance decreasing ratio of as small as within -40% at an impressed voltage of 5 kV/mm and a dielectric loss of 1.0% or less, along with the rate of change of the electrostatic capacitance against temperature changes satisfying the B-level characteristic standard stipulated in the JIS Standard in the temperature range of -25 °C to +85 °C and X7R-level characteristic standard stipulated in the EIA standard in the temperature range of -55 °C to +125 °C.

Moreover, the insulation resistances at 25 °C and 150 °C as expressed by the product CR show as high values as 5000 Ω·F or more and 200 Ω·F or more, respectively, when the ceramic capacitor is used under a high electric field strength of 10 kV/mm. The insulation breakdown voltage also shows high values of 12 kV/mm or more under the AC voltage and 14 kV/mm or more under the DC voltage. In addition, an acceleration test at 150 °C and DC 25 kV/mm gave a mean life span as long as 800 hours or more besides enabling a relatively low firing temperature of 1300 °C or less.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

When the oxide SiO_2-TiO_2-XO has a composition outside of the composition described above as in the samples No. 2213 to 2119 in TABLE 2008, on the other hand, sintering becomes insufficient or many rejection appear in the humidity resistance load test even after sintering as seen in the samples No. 2513 to 2519 in TABLE 2015.

While a monolithic capacitor having an insulation resistance of 5400 Ω·F or more and 330 Ω·F or more at 25 °C and 150 °C, respectively, under a strong electric field of 10 kV/mm can be obtained by allowing Al_2O_3 and/or ZrO_2 to contain in the SiO_2-TiO_2-XO oxides as in the sample No. 2211 and 2212 in TABLE 2008, sintering property is extremely decreased as shown in the samples NO. 2517 and ~~1518~~ 2518 in TABLE 2015 when Al_2O_3 and ZrO_2 are added in an amounts of 15 parts by weight or more and 5 parts by weight or more, respectively, as in the samples No. 2517 and 2518 in TABLE ~~2008~~ 2015.

Although powders prepared by the oxalic acid method are used in the foregoing examples, the methods are not limited thereto but a powder of barium titanate prepared by an alkoxide method or hydrothermal synthesis method may be used. It may happen that the characteristics of the monolithic ceramic capacitor are more improved than those shown in the foregoing examples by using these powders.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

The oxide powders as starting materials are not limited to those hitherto described, but the resulting characteristics are not affected in any sense by using a solution of an alkoxide or organometallic compound, provided that the starting materials are formulated so as to construct the dielectric ceramic layers within the scope of the present invention.

It can be made clear from the foregoing descriptions that the dielectric ceramic composition according to the present invention is not reduced by firing in the reducing atmosphere along with not being formed into semiconductors, besides sintering is possible at a relatively low temperature of 1300 °C or less.

Accordingly, when a monolithic ceramic capacitor is constructed by using this dielectric ceramic composition as dielectric ceramic layers, the production cost of the monolithic ceramic capacitor can be reduced since base metals such as nickel or nickel alloys may be used for the electrode materials.

When the monolithic ceramic capacitor using this dielectric ceramic composition is used under a high electric field of 10 kV/mm where reliability can not be ensured due to low insulation resistance in the monolithic ceramic capacitor using nickel or nickel alloys for the conventional

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

inner electrodes, a monolithic ceramic capacitor being excellent in weather resistance properties such as high temperature load at an impressed voltage of DC 25 kV/mm at 150 °C and humidity resistance load can be obtained, wherein the insulation resistances at room temperature and at 150 °C represented by a product of the insulation resistance and electrostatic capacitance (a CR product) becomes as high as 4900 to 5000 Ω·F and 190 to 200 Ω·F, respectively, the voltage dependency of the insulation resistance is low, the capacitance decrease ratio at an impressed voltage of 5 kV/mm is as small as 40 to 45% and the insulation durability is high, besides the temperature characteristics of the electrostatic capacitance satisfies the B-level characteristic standard stipulated in the JIS Standard and X7R-level characteristic standard stipulated in the EIA standard.

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

~~【表１】~~
Table 1

〈お願い〉
本図表はこのまま海外へFAX送信します。
訳は黒字で明瞭に併記入下さるようお願いします。

1 $BaTiO_3$の種類	2 不純物含有量（重量%）					平均粒径 4 (μm)
	3 アルカリ金属酸化物	SrO	CaO	SiO_2	Al_2O_3	
A	0.003	0.012	0.001	0.01	0.005	0.6
B	0.02	0.01	0.003	0.019	0.008	0.56
C	0.012	0.179	0.018	0.155	0.071	0.72
D	0.062	0.014	0.001	0.019	0.004	0.58

1. Kind of $BaTiO_3$
2. Content of impurities (% by weight)
3. Alkali metal oxide
4. Mean particle size (μm)

~~【００２５】~~

また、第１の副成分として０．２５Li_2O－０．６５（０．３０TiO_2・０．７０SiO_2）－０．１０Al_2O_3（モル比）の組成割合になるように、各成分の酸化物、炭酸塩または水酸化物を秤量し、混合粉砕して粉末を得た。

同様に、第２の副成分として０．６６SiO_2－０．１７TiO_2－０．１５BaO－０．０２MnO（モル比）の組成割合になるように、各成分の酸化物、炭酸塩または水酸化物を秤量し、混合粉砕して粉末を得た。

This Sheet Has Been Replaced

【表2】 Table2

【0028】

＊印は本発明の範囲外⑤

試料番号①	$(BaO)_m \cdot TiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMgO + hMnO$															第1の副成分の添加量(重量部)⑥	第2の副成分の添加量(重量部)⑦
	$BaTiO_3$の種類②	α		αの合計③	β				βの合計④	α+β	γ	g	h	g+h	m		
		Sc_2O_3	Y_2O_3		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3									
*1	A	0	0.0008	0.0008	0	0.05	0	0	0.05	0.0508	0.02	0.05	0.07	0.12	1.005	1	0
*2	A	0.03	0.03	0.06	0	0	0.001	0	0.001	0.061	0.03	0.04	0.08	0.12	1.005	1	0
*3	A	0.01	0.01	0.02	0	0	0.0008	0	0.0008	0.0208	0.03	0.02	0.03	0.05	1.005	1	0
*4	A	0	0.001	0.001	0	0.03	0.02	0.02	0.07	0.071	0.03	0.03	0.1	0.13	1.01	1	0
*5	A	0.01	0.02	0.03	0.02	0	0	0.02	0.04	0.07	0.03	0.12	0.01	0.13	1.01	1	0
*6	A	0.01	0.01	0.02	0	0.02	0.02	0	0.04	0.06	0	0.07	0.06	0.13	1.01	1.5	0
*7	A	0	0.01	0.01	0	0	0	0.02	0.02	0.03	0.08	0.03	0.04	0.07	1.01	1.5	0
*8	A	0.01	0.02	0.03	0	0	0.01	0.01	0.02	0.05	0.02	0.001	0.069	0.07	1.01	1	0
*9	A	0.01	0	0.01	0.01	0	0	0	0.01	0.02	0.02	0.125	0.005	0.13	1.01	1	0
*10	A	0.01	0.01	0.02	0.01	0.01	0	0	0.02	0.04	0.02	0.079	0.001	0.08	1.01	1	0
*11	A	0.01	0	0.01	0	0.01	0	0.01	0.02	0.03	0.02	0.005	0.13	0.13	1.01	1	0
*12	A	0.01	0.02	0.03	0.02	0	0	0.02	0.04	0.07	0.03	0.05	0.08	0.14	1.01	1	0
*13	A	0.005	0.005	0.01	0	0.01	0.01	0	0.02	0.03	0.03	0.03	0.025	0.055	0.99	1	0
*14	A	0.01	0	0.01	0.01	0.005	0.005	0.01	0.03	0.04	0.04	0.04	0.03	0.07	1.00	1	0
*15	A	0.005	0.005	0.01	0	0	0.01	0	0.01	0.02	0.04	0.02	0.03	0.05	1.038	1	0
*16	A	0.01	0	0.01	0.01	0	0	0.01	0.02	0.03	0.02	0.03	0.02	0.05	1.05	0	1
*17	A	0	0.01	0.01	0	0	0.01	0.01	0.02	0.03	0.02	0.03	0.04	0.07	1.01	0	0
*18	A	0	0.01	0.01	0	0.01	0.01	0.01	0.03	0.04	0.02	0.04	0.03	0.07	1.01	5	0
*19	A	0	0.01	0.01	0.01	0.01	0	0	0.02	0.03	0.02	0.02	0.04	0.06	1.01	0	0
*20	A	0.01	0.01	0.02	0	0	0.01	0	0.01	0.03	0.02	0.03	0.02	0.05	1.01	0	4
*21	D	0	0.01	0.01	0	0.01	0.02	0	0.03	0.04	0.03	0.04	0.05	0.09	1.01	2	0
22	A	0	0.001	0.001	0.02	0	0.009	0	0.029	0.03	0.02	0.04	0.01	0.05	1.015	1	0
23	B	0.01	0.01	0.02	0	0.01	0	0	0.01	0.03	0.03	0.03	0.02	0.05	1.02	1	0

① Sample No.
② Kind of $BaTiO_3$
③ Total of α
④ Total of β
⑤ The mark * indicate "out of the scope of the present invention
⑥ Amount of addition of the first side compoment
⑦ Amount of addition of the second side compo~~me~~nent

THIS SHEET HAS BEEN REPLACED.
This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

【表3】 Table 3

【0029】

① 試料番号	② $(BaO)_m \cdot TiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMgO + hMnO$			③					④							⑤	⑥
	$BaTiO_3$の種類	α		αの合計	β				βの合計	α+β	γ	g	h	g+h	m	第1の副成分の添加量（重量部）	第2の副成分の添加量（重量部）
		Sc_2O_3	Y_2O_3		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3									
24	C	0.01	0.02	0.03	0	0	0	0.01	0.01	0.04	0.03	0.12	0.002	0.122	1.03	1	0
25	A	0.01	0.03	0.04	0	0	0.01	0	0.01	0.05	0.03	0.07	0.06	0.13	1.02	1	0
26	A	0.01	0.04	0.05	0	0.01	0	0	0.01	0.06	0.03	0.002	0.12	0.122	1.01	0	1
27	A	0.005	0.005	0.01	0	0	0	0.001	0.001	0.011	0.02	0.01	0.02	0.03	1.01	1	0
28	A	0	0.01	0.01	0.01	0.01	0	0	0.02	0.03	0.02	0.03	0.02	0.05	1.01	1	0
29	A	0	0.01	0.01	0.02	0	0.01	0	0.03	0.04	0.02	0.05	0.03	0.08	1.015	0	1
30	A	0	0.01	0.01	0	0.04	0	0	0.04	0.05	0.02	0.06	0.03	0.09	1.01	0	1
31	A	0	0.01	0.01	0	0.03	0	0.02	0.05	0.06	0.02	0.05	0.06	0.11	1.01	1	0
32	A	0.01	0.02	0.03	0	0	0.02	0	0.02	0.05	0.02	0.05	0.04	0.09	1.01	1	0
33	A	0.01	0.02	0.03	0	0	0	0.03	0.03	0.06	0.03	0.06	0.04	0.1	1.01	1	0
34	A	0	0.01	0.01	0	0.02	0	0	0.02	0.03	0.01	0.03	0.02	0.05	1.01	1	0
35	A	0.01	0.01	0.02	0.02	0	0	0	0.02	0.04	0.04	0.05	0.03	0.08	1.01	1	0
36	A	0.01	0.01	0.02	0	0.01	0.01	0	0.02	0.04	0.06	0.05	0.02	0.07	1.01	1	0
37	A	0.01	0.01	0.02	0	0	0.01	0.01	0.02	0.04	0.03	0.04	0.03	0.07	1.01	2	0
38	A	0.01	0.01	0.02	0.01	0	0	0	0.01	0.03	0.03	0.04	0.015	0.055	1.01	2	0
39	A	0.01	0.01	0.02	0	0.01	0	0	0.01	0.03	0.02	0.03	0.04	0.07	1.01	2	0
40	A	0	0.02	0.02	0	0	0.01	0	0.01	0.03	0.02	0.03	0.02	0.05	1.01	2	0
41	A	0	0.02	0.02	0	0	0	0.01	0.01	0.03	0.02	0.03	0.03	0.06	1.001	2	0
42	A	0.02	0	0.02	0.01	0.01	0	0	0.02	0.04	0.03	0.04	0.03	0.07	1.01	0	2
43	A	0.01	0.01	0.02	0	0	0.01	0.01	0.02	0.04	0.03	0.03	0.05	0.08	1.035	2	0
44	A	0.01	0.01	0.02	0	0.02	0	0	0.02	0.04	0.03	0.04	0.03	0.07	1.015	0.2	0
45	A	0.01	0.01	0.02	0	0	0	0.01	0.01	0.03	0.03	0.03	0.02	0.05	1.01	3	0
46	A	0	0.02	0.02	0	0	0	0.01	0.01	0.03	0.03	0.02	0.04	0.06	1.01	0	0.2
47	A	0	0.02	0.02	0.01	0	0.01	0	0.02	0.04	0.03	0.05	0.02	0.07	1.01	0	3

① Sample No.
② Kind of $BaTiO_3$
③ Total of α
④ Total of β
⑤ Amount of addition of the first side component
⑥ Amount of addition of the second side component

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED (19)

【表4】 Table 4

【0038】

① Sample No. ③ Dielectric constant ⑥ Maximum value ⑧ product CR
② Baking temp. ④ Dielectric loss ⑦ DC vias characteristic
⑤ Ratio of temperature ~~dependent~~ dependent capacitor change

*印は本発明の範囲外 ⑨

① 試料番号	② 焼成温度 (℃)	③ 誘電率	④ 誘電損失 tanδ (%)	⑤ 容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	⑥ 最大値	⑦ DCバイアス特性(%) ΔC/C 5kV/mm	⑧ CR積(Ω·F) 25℃ 315V印加 ⑩	25℃ 945V印加 ⑩	150℃ 315V印加 ⑩	150℃ 945V印加 ⑩	⑪ 絶縁破壊電圧 (kV/mm) AC	DC	⑫ 耐湿負荷試験 不良個数	⑬ 平均寿命時間 (h)
*1	1300	1210	0.7	5.6	−12	6.4	−17.5	21	−21	5110	4860	220	210	12	14	0/72	960
*2	1300	960	0.7	2.3	−7.8	4.7	−6.9	8.7	−16	8520	8090	200	190	12	14	0/72	910
*3	1300	1550	0.7	3	−7.9	5	−6.8	8.5	−42	3020	2870	120	110	13	14	0/72	930
*4	1300	920	0.7	6	−12.9	7.5	−19	25.3	−14	5060	4810	−250	240	12	14	0/72	120
*5	1280	960	2	2.1	−8	4.2	−7.1	8.5	−14	5070	4820	−260	250	12	14	10/72	180
*6	1280	1070	0.7	1.9	−8.2	3	−7.5	8.9	−16	3120	2180	−140	100	12	14	0/72	870
*7	1300	1440	0.7	2.2	−14.3	4.5	−31.5	36.2	−36	5160	4900	−240	230	12	14	0/72	160
*8	1280	1280	0.8	2.2	−12.5	4.6	−16.3	21.3	−26	3090	2940	−130	120	13	14	0/72	950
*9	1360	1530	2.6	2.3	−7.7	5	−7.5	8.5	−43	5110	4860	−230	220	12	14	53/72	120
*10	半導体化のため測定不能 ⑭																
*11	1280	1460	0.7	3	−8.5	5.1	−17.9	23.6	−38	3150	2990	−150	140	12	14	0/72	150
*12	1280	940	2.1	2.3	−8.2	4.5	−8.5	8.7	−14	5060	4800	−240	230	12	14	9/72	100
*13	半導体化のため測定不能 ⑭																
*14	1300	1360	0.7	3.4	−8.4	5.3	−8	9.3	−30	3200	3040	−160	150	10	11	0/72	130
*15	焼結不足のため測定不能 ⑮																
*16	焼結不足のため測定不能 ⑮																
*17	焼結不足のため測定不能 ⑮																
*18	1300	1320	2.6	3.3	−8.3	5.1	−8.2	9.2	−25	3250	3090	−170	160	11	12	0/72	150
*19	焼結不足のため測定不能 ⑮													11			
*20	1300	1470	2.6	1.9	−8.7	4	−8	9.3	−41	3300	3140	−180	170	12	12	0/72	110
*21	1300	1140	0.6	2.2	−8.9	7	−8.3	9.5	−26	5180	4920	−280	270	12	14	0/72	860
22	1280	1480	0.7	5.2	−7.2	6.5	−7	8.7	−39	5090	4840	−270	260	12	15	0/72	920
23	1280	1460	0.7	1.6	−7.6	7	−7.2	8.8	−39	5020	4770	−250	240	12	14	0/72	940

⑩ Impressed voltage

⑨ The mark * indicate "out of the scope of the present invention

~~⑩ impress~~ ⑪ Insulation breakdown voltage ⑫ Humidity resistance load test ; Number of rejects.

⑬ Mean life span ⑭ Unmeasurable due to semiconductor formation

⑮ Unmeasurable due to insufficient sintering

This Sheet Has Been Replaced

表5 Table 5

Ratio of temperature dependent capacitance change

① Sample No. ③ Dielectric constant ⑤ ~~Rate of temperature change~~ ~~Capacitance change ratio due to temperature~~ change

② Baking temp. ④ Dielectric loss

*印は本発明の範囲外

① 試料番号	② 焼成温度 (℃)	③ 誘電率	④ 誘電損失 tanδ (%)	⑤ 容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	⑦ DCバイアス特性(%) ΔC/C 5kV/mm	⑧ CR積(Ω·F) 315V 印加 ⑪ 25℃	945V 印加 ⑪ 25℃	315V 印加 ⑪ 150℃	945V 印加 ⑪ 150℃	⑩ 絶縁破壊電圧 (kV/mm) AC	DC	⑫ 耐湿負荷試験 不良個数	⑬ 平均寿命時間 (h)
24	1280	1350	0.6	1.7	−8.5	5.9	−7.8	8.9	−31	5280	5020	290	280	12	15	0/72	990
25	1300	1260	0.6	2	−8.7	5.1	−8.2	9.5	−23	5130	4870	270	260	12	14	0/72	890
26	1300	1080	0.7	2.1	−8.8	5.5	−8.3	9.2	−17	5200	4940	220	210	12	15	0/72	950
27	1300	1650	0.6	2.1	−7.5	6.1	−7.5	8.7	−45	5210	4950	230	220	12	14	0/72	820
28	1300	1410	0.7	3	−7.9	6.7	−7.3	8.8	−36	5290	5030	280	270	12	14	0/72	850
29	1280	1370	0.6	3.1	−8.2	6	−7.8	8.8	−33	5200	4940	290	280	13	14	0/72	900
30	1280	1230	0.6	2.1	−8.5	5.8	−7.9	9.5	−22	5260	5000	250	240	12	14	0/72	870
31	1300	1030	0.6	2	−8.9	5	−8.2	9.2	−15	5240	4980	210	200	12	14	0/72	920
32	1300	1260	0.6	1.9	−7.9	4.8	−7.5	8.7	−21	5010	4760	200	190	12	14	0/72	920
33	1300	1060	0.6	2	−8	4.9	−7.8	8.5	−16	5230	4970	260	250	12	14	0/72	870
34	1280	1420	0.6	2	−8.2	5.3	−7.9	8.9	−36	5060	4810	280	270	12	14	0/72	850
35	1280	1360	0.6	2	−7.8	5.7	−8	8.6	−30	5260	5000	230	220	12	15	0/72	820
36	1300	1370	0.7	2.5	−7.9	6	−7.6	8	−32	5100	4850	220	210	12	14	0/72	850
37	1300	1350	0.6	2	−8	6.1	−7.7	8.5	−32	5070	4820	250	240	12	14	0/72	890
38	1300	1470	0.6	2	−8.1	5.8	−8	8.6	−39	5090	4840	230	220	13	14	0/72	900
39	1280	1440	0.7	2.6	−8.1	5.9	−7.9	8.7	−39	5100	4850	240	230	13	14	0/72	870
40	1280	1480	0.7	2.5	−8.5	6	−8.2	9.2	−40	5210	4950	210	200	12	14	0/72	910
41	1280	1460	0.6	2	−7.8	6.7	−8	8.6	−40	5220	4960	260	250	12	14	0/72	890
42	1300	1380	0.6	2.7	−7.9	6	−8.2	8.7	−30	5160	4900	230	220	12	14	0/72	920
43	1300	1350	0.6	2	−8.1	5.8	−8	8.5	−30	5360	5090	250	240	12	14	0/72	900
44	1300	1320	0.6	2.5	−8.2	5.9	−7.7	8.9	−25	5180	4920	230	220	12	14	0/72	880
45	1300	1450	0.7	2.3	−8.3	7.2	−7.8	8.8	−38	5190	4930	290	280	12	14	0/72	850
46	1280	1430	0.7	2.3	−8	6.8	−7.9	8.8	−38	5230	4970	270	260	12	14	0/72	860
47	1300	1440	0.6	2.2	−7.9	6.5	−7.5	8	−38	5260	5000	260	250	12	14	0/72	920

⑥ Maximum value ⑦ DC vias characteristic ⑧ Product CR

⑨ The mark * indicate "out of the scope of the present invention"

⑩ Insulation breakdown voltage ⑪ Impressed voltage ⑫ Humidity resistance load test Number of reject

⑬ Mean life span

【0039】

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

【0049】

~~【表6】~~ Table 6

THIS SHEET HAS BEEN REPLACED

① 試料番号	② 添加量（重量部）	③ 第1の副成分 ④ 組成（モル%、但しWを除く）				
		Li_2O	$(Si_wTi_{1-w})O_2$	w	Al_2O_3	ZrO_2
101	1	20	80	0.3	0	0
102	1	10	80	0.6	5	5
103	0.8	10	70	0.5	20	0
104	0.8	35	45	1	10	10
105	1.5	45	45	0.5	10	0
106	1.5	45	55	0.3	0	0
107	1	20	70	0.6	5	5
108	1	20	70	0.4	10	0
109	1.2	30	60	0.7	5	5
110	1.2	30	60	0.8	10	0
111	2	40	50	0.6	5	5
112	2	40	50	0.9	0	10
113	1.5	10	85	0.4	5	0
114	2	5	75	0.6	10	10
115	1.2	20	55	0.5	25	0
116	1	45	40	0.8	0	15
117	0.8	50	45	0.7	5	0
118	1.2	25	75	0.9	0	0
119	1.5	25	75	1	0	0
120	1	35	65	0.9	0	0
121	1.5	35	65	1	0	0
122	1.2	20	70	0.2	0	10

~~【0050】~~

次いで、実施例1と同様にして電気的特性を測定した。その結果を表7に示す。

~~【0051】~~

① Sample No.
② Amount of addition (parts by weight)
③ The first side component
④ Composition (mol %, except w)

This Sheet Has Been Replaced

【表7】 Table 7

① Sample No. ② Baking temp. ③ Dielectric constant. ④ Dielectric loss
~~⑤ Capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑤ Ratio of temperature dependent capacitance change

① 試料番号	② 焼成温度 (℃)	③ 誘電率	④ 誘電損失 tanδ (%)	⑤ 容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	⑦ DCバイアス特性(%) ΔC/C 5kV/mm	⑧ CR積(Ω·F) 315V ⑨印加 25℃	945V ⑨印加 25℃	315V ⑨印加 150℃	945V ⑨印加 150℃	⑩ 絶縁破壊電圧 (kV/mm) AC	DC	⑪ 耐湿負荷試験 不良個数	⑫ 平均寿命時間 (h)
101	1280	1480	0.6	2.1	−8.5	5.2	−8	8.3	−39	5090	4840	230	220	12	15	0/72	880
102	1280	1490	0.6	2.3	−8	5.6	−8.5	8.9	−40	5080	4830	240	230	12	14	0/72	850
103	1280	1420	0.6	3	−8.1	4.9	−8.9	9.5	−38	5070	4820	250	240	12	14	0/72	900
104	1300	1400	0.6	2.4	−8.3	5	−9.2	9.5	−36	5100	4850	230	220	12	15	0/72	910
105	1300	1460	0.6	2.6	−8	5.2	−9.5	9.7	−37	5120	4860	220	210	13	14	0/72	820
106	1280	1440	0.7	2.1	−8.9	4.8	−8.2	8.8	−37	5100	4850	230	220	12	14	0/72	820
107	1280	1500	0.6	2	−7.9	4.9	−9.1	9.5	−40	5230	4970	250	240	13	14	0/72	910
108	1280	1480	0.6	3.1	−7.8	5.2	−9.4	9.6	−40	5130	4870	240	230	12	14	0/72	930
109	1280	1480	0.6	2.8	−8.2	5.4	−9	9.2	−40	5090	4840	230	220	12	14	0/72	880
110	1300	1490	0.6	2.5	−8.2	5.5	−9.5	9.8	−40	5080	4830	220	220	12	14	0/72	860
111	1300	1460	0.6	2	−8.5	5.7	−9.1	9.5	−39	5070	4820	220	210	12	14	0/72	880
112	1280	1470	0.6	2.8	−8	5	−9	9.2	−39	5130	4870	220	210	12	14	0/72	870
113	1350	焼結不足のため測定不能 ⑬															
114	1350	焼結不足のため測定不能 ⑬															
115	1350	1450	1.4	2.2	−8.9	4.8	−8.7	9	−39	5160	4900	250	240	11	13	20/72	120
116	1350	焼結不足のため測定不能 ⑬															
117	1350	焼結不足のため測定不能 ⑬															
118	1300	1450	0.6	2.3	−8.8	5.3	−8.9	9.2	−39	5200	4940	240	230	12	14	0/72	820
119	1350	1490	1.3	1.9	−8.5	4.5	−8.6	8.9	−40	5190	4930	260	250	11	13	11/72	190
120	1300	1440	0.6	2.4	−9.2	5	−9.2	9.3	−37	5180	4920	250	240	12	14	0/72	860
121	1350	1460	1.3	2.1	−8.8	4.2	−8.7	9	−37	5170	4910	240	230	11	13	22/72	120
122	1350	1450	1.2	2.2	−8.7	4.5	−8.8	9.2	−37	5200	4940	230	220	11	13	19/72	170

⑦ DC vias characteristic ⑧ Product CR. ⑨ Impressed voltage
⑩ Insulation breakdown voltage ⑪ Humidity resistance load test; Number of reject
⑫ Mean life span ⑬ Unmeasurable due to insufficient sintering

THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

表8 Table 8

試料番号 ①	③ 第2の副成分 添加量（重量部） ②	④ 主成分（モル%） SiO_2	TiO_2	XO BaO	CaO	SrO	MgO	ZnO	MnO	合計	⑤ 添加成分（重量部） Al_2O_3	ZrO_2
201	1	85	1	1	0	0	0	4	9	14	0	0
202	1	35	51	0	10	0	0	0	4	14	0	0
203	1	30	20	0	30	0	15	4	1	50	0	0
204	1	39	1	20	20	2	0	13	5	60	0	0
205	1	70	10	5	5	0	0	10	0	20	0	0
206	1	45	10	0	0	0	0	15	30	45	0	0
207	1	50	20	10	10	3	7	0	0	30	0	0
208	1	50	30	0	16	0	0	0	4	20	0	0
209	1	35	30	25	10	0	0	0	0	35	0	0
210	1	40	40	10	0	0	0	5	5	20	0	0
211	1	45	22	3	30	0	0	0	0	33	15	0
212	1	45	22	3	30	0	0	0	0	33	10	5
213	1	65	25	5	5	0	0	0	0	10	0	0
214	1	25	40	15	0	10	0	5	5	35	0	0
215	1	30	10	30	25	0	0	5	0	60	0	0
216	1	50	0	35	15	0	0	0	0	50	0	0
217	1	45	22	30	0	0	3	0	0	33	25	0
218	1	45	22	30	0	3	0	0	0	33	0	15
219	1	30	60	10	0	0	0	0	0	10	0	0

① Sample No.
② Amount of addition (parts by weight)
③ The second side component
④ Essential component (mole %)

【0057】

次いで、実施例1と同様にして電気的特性を測定した。その結果を表9に示す。

【0058】

THIS SHEET HAS BEEN REPLACED (28)

This Sheet Has Been Replaced

【表9】 Table 9

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ Capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑤ Ratio of temperature dependent capacitance change

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間(h) ⑫
201	1300	1460	0.6	3.2	−8.2	6.8	−7.9	8.5	−39	5080	4830	220	210	12	14	0/72	840
202	1280	1490	0.6	3.5	−8.4	7	−8.1	8.6	−40	5080	4830	230	220	12	14	0/72	800
203	1280	1470	0.6	4	−8.6	7.2	−8.3	8.7	−39	5120	4860	220	210	12	14	0/72	920
204	1300	1450	0.6	3.8	−8.5	6.9	−8.2	8.6	−39	5150	4890	240	230	12	14	0/72	860
205	1300	1460	0.6	3.9	−8.5	7.1	−8.2	8.8	−39	5070	4820	220	210	12	14	0/72	820
206	1280	1430	0.6	3.7	−8.5	6.8	−8.3	8.7	−38	5080	4830	220	210	13	15	0/72	900
207	1280	1450	0.6	3.5	−8.4	7	−8.1	8.7	−39	5030	4780	230	220	12	14	0/72	890
208	1300	1470	0.6	3.1	−8	6.7	−7.9	8.3	−39	5040	4790	200	190	12	14	0/72	930
209	1300	1460	0.6	3.5	−8.4	6.9	−8	8.7	−39	5080	4830	220	210	12	14	0/72	830
210	1300	1450	0.6	3.9	−8.6	7.2	−8.2	8.8	−39	5100	4850	210	200	12	14	0/72	860
211	1280	1430	0.6	4	−8.7	7.3	−8.5	8.9	−38	5410	5140	300	290	12	14	0/72	870
212	1300	1440	0.6	3.8	−8.4	6.9	−8	8.7	−39	5420	5150	310	300	12	14	0/72	880
213	1350	1420	1.2	3.1	−8.1	6.6	−7.6	8.3	−38	5120	4860	230	220	11	13	38/72	150
214	1350	焼結不足のため測定不能 ⑬															
215	1350	焼結不足のため測定不能 ⑬															
216	1350	1420	1.3	3.3	−8.2	6.8	−7.8	8.5	−38	5030	4780	220	210	11	13	70/72	120
217	1350	焼結不足のため測定不能 ⑬															
218	1350	焼結不足のため測定不能 ⑬															
219	1350	焼結不足のため測定不能 ⑬															

⑩ Insulation breakdown voltage ⑪ Humidity resistance load test : Number of reject
⑫ Mean life span ⑬ ~~the~~ Unmeasurable due to insufficient sintering

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【表10】 Table 10

⑤ *印は本発明の範囲外

試料番号 ①	$[BaO]_m \cdot TiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$													⑥ 第1の副成分の添加量（重量部）	⑦ 第2の副成分の添加量（重量部）
	② $BaTiO_3$ の種類	α		③ αの合計	β				④ βの合計	α＋β	γ	g	m		
		Sc_2O_3	Y_2O_3		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3							
*301	A	0	0.0007	0.0007	0.04	0	0	0	0.04	0.0407	0.03	0.09	0.01	1.5	0
*302	A	0.05	0.02	0.07	0	0.001	0.001	0	0.002	0.072	0.02	0.14	1.005	1.2	0
*303	A	0.02	0	0.02	0	0	0	0.0008	0.0008	0.0208	0.03	0.04	1.015	1	0
*304	A	0	0.001	0.001	0.04	0	0.03	0	0.07	0.071	0.04	0.14	1.005	1	0
*305	A	0	0.04	0.04	0	0.02	0.02	0	0.04	0.08	0.03	0.16	1.005	1	0
*306	A	0.01	0	0.01	0.01	0	0	0.02	0.03	0.04	0	0.08	1.01	1.5	0
*307	A	0	0.01	0.01	0	0	0.02	0	0.02	0.03	0.08	0.06	1.01	1.5	0
*308	A	0.01	0.01	0.02	0	0.02	0	0	0.02	0.04	0.01	0.001	1.005	1	0
*309	A	0	0.01	0.01	0.01	0	0	0	0.01	0.02	0.02	0.14	1.01	1	0
*310	A	0.01	0	0.01	0	0	0	0.02	0.02	0.03	0.03	0.06	0.99	1.2	0
*311	A	0	0.02	0.02	0	0.01	0.01	0.01	0.03	0.05	0.03	0.1	1.00	1	0
*312	A	0.005	0.005	0.01	0	0.03	0	0	0.03	0.04	0.04	0.08	1.038	1	0
*313	A	0	0.01	0.01	0	0	0	0.03	0.03	0.04	0.03	0.08	1.05	0	2
*314	A	0.02	0	0.02	0.01	0.01	0	0	0.02	0.04	0.03	0.09	1.005	0	0
*315	A	0	0.01	0.01	0.01	0	0	0.02	0.03	0.04	0.02	0.08	1.01	5	0
*316	A	0.01	0	0.01	0	0	0.01	0.01	0.02	0.03	0.02	0.06	1.01	0	0
*317	A	0.02	0	0.02	0.02	0	0	0	0.02	0.04	0.03	0.08	1.015	0	4
*318	D	0.01	0	0.01	0	0	0	0.03	0.03	0.04	0.03	0.08	1.01	2.5	0
319	A	0	0.001	0.001	0.01	0.01	0.01	0	0.03	0.031	0.02	0.06	1.015	1	0
320	B	0	0.02	0.02	0	0	0	0.01	0.01	0.03	0.02	0.06	1.01	1	0
321	C	0.01	0.01	0.02	0.01	0	0.02	0	0.03	0.05	0.03	0.11	1.01	1	0
322	A	0.01	0.03	0.04	0	0	0	0.01	0.01	0.05	0.02	0.1	1.005	1	0

① Sample No. ② Kind of ~~Bati~~ $BaTiO_3$ ③ Total of α ④ Total of β
⑤ The mark * indicates "out of the scope of the present invention
⑥ The amount of addition of the first side component (parts by weight)
⑦ The amount of addition of the second side component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【0064】

【表11】 Table 11

① 試料番号	② $(BaO)_m \cdot TiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$													⑤ 第1の副成分の添加量（重量部）	⑥ 第2の副成分の添加量（重量部）
	$BaTiO_3$の種類	α		③ αの合計	β				④ βの合計	α＋β	γ	g	m		
		Sc_2O_3	Y_2O_3		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3							
323	A	0	0.05	0.05	0.01	0	0	0	0.01	0.06	0.03	0.13	1.01	0	1
324	A	0.02	0.01	0.03	0	0.001	0	0	0.001	0.031	0.02	0.06	1.005	1	0
325	A	0.02	0	0.02	0	0	0	0.02	0.02	0.04	0.03	0.08	1.01	1.1	0
326	A	0	0.01	0.01	0.01	0	0.02	0	0.03	0.04	0.02	0.08	1.01	0	1
327	A	0.01	0	0.01	0	0	0.01	0.02	0.03	0.04	0.03	0.08	1.01	0	2
328	A	0.01	0	0.01	0.03	0.02	0	0	0.05	0.06	0.02	0.12	1.01	1	0
329	A	0.01	0.01	0.02	0.02	0	0	0	0.02	0.04	0.02	0.08	1.005	1	0
330	A	0.01	0.02	0.03	0	0.01	0.01		0.02	0.05	0.02	0.1	1.01	1	0
331	A	0.01	0	0.01	0	0.01	0	0.02	0.03	0.04	0.005	0.08	1.01	1	0
332	A	0.01	0.01	0.02	0	0.02	0.01		0.03	0.05	0.03	0.1	1.01	1	0
333	A	0.02	0	0.02	0.01	0	0	0.01	0.02	0.04	0.06	0.08	1.01	1	0
334	A	0	0.02	0.02	0.02	0	0	0	0.02	0.04	0.03	0.08	1.005	2	0
335	A	0.01	0.02	0.03		0	0.01	0	0.01	0.04	0.03	0.09	1.01	2	0
336	A	0.01	0.01	0.02	0.01	0	0	0.01	0.02	0.04	0.03	0.08	1.01	2	0
337	A	0.01	0.01	0.02	0.02	0.01	0	0	0.03	0.05	0.02	0.1	1.005	2	0
338	A	0.005	0	0.005	0	0	0.005	0	0.005	0.01	0.02	0.02	1.001	2	0
339	A	0.01	0.01	0.02	0	0	0.01	0.01	0.02	0.04	0.03	0.08	1.01	0	1.5
340	A	0.03	0	0.03	0	0.02	0	0	0.02	0.05	0.02	0.1	1.035	2	0
341	A	0	0.02	0.02	0	0	0.01	0.01	0.02	0.04	0.03	0.08	1.01	0.2	0
342	A	0.01	0.01	0.02	0	0.01	0	0	0.01	0.03	0.03	0.06	1.01	3	0
343	A	0.01	0.01	0.02	0.02	0	0.01	0	0.03	0.05	0.03	0.1	1.01	0	0.2
344	A	0.02	0.01	0.03	0	0.03	0	0	0.03	0.06	0.02	0.13	1.005	0	3

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α ④ Total of β
⑤ The amount of addition of the first component (parts by weight)
⑥ The amount of addition of the second component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

~~【表12】~~ Table 12

THIS SHEET HAS BEEN REPLACED (35)

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ Capacitance change due to temperature change~~ ⑥ Maximum value
⑦ DC bias characteristic ⑧ Product CR ⑨ Impressed voltage

⑤ Ratio of temperature dependent capacitance change

*印は本発明の範囲外 ⑩

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率 (%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧CR積(Ω・F) 315V 印加 ⑨ 25℃	945V 印加 ⑨ 25℃	315V 印加 ⑨ 150℃	945V 印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑪ AC	DC	耐湿負荷試験 不良個数 ⑫	平均寿命時間 (h) ⑬
*301	1300	1220	0.6	5.3	−12.5	6.5	−17.5	17.5	−18	5000	4750	210	200	13	14	0/72	980
*302	1300	820	0.7	2.5	−7.2	5	−7.5	7.6	−5	5110	4860	220	210	12	14	0/72	950
*303	1300	1450	0.6	3.2	−7.1	5.2	−7.6	8	−38	2900	2760	130	120	13	14	0/72	900
*304	1300	800	0.7	6.4	−13.5	7.6	−19.5	19.5	−7	4920	4670	230	220	12	14	0/72	100
*305	1280	710	2.2	3	−6.5	5	−7.3	7.5	−6	5030	4780	240	230	12	14	15/72	150
*306	1280	1220	0.6	2.2	−7.5	4	−8.4	8.6	−22	2850	2000	110	80	12	14	0/72	900
*307	1300	1340	0.7	2.5	−13.5	5	−31.5	31.5	−32	5110	4860	250	240	12	14	0/72	130
*308	半導体化のため測定不能 ⑭																
*309	1280	1460	0.7	3.3	−7.5	5.5	−18.5	18.5	−37	2940	2790	160	150	12	14	0/72	110
*310	半導体化のため測定不能 ⑭																
*311	1300	1160	0.7	4	−7.6	5.6	−8	8.3	−20	3080	2930	170	160	10	11	0/72	100
*312	焼結不足のため測定不能 ⑮																
*313	焼結不足のため測定不能 ⑮																
*314	焼結不足のため測定不能 ⑮																
*315	1300	1240	2.7	4	−7.4	5.8	−7.7	8.3	−22	3100	2950	160	150	10	12	0/72	130
*316	焼結不足のため測定不能 ⑮																
*317	1300	1260	2.8	2.3	−8.3	5	−8.5	8.8	−22	3110	2960	170	160	11	12	0/72	100
*318	1300	1250	0.7	2.5	−8.1	7.2	−8.2	8.8	−21	5050	4800	240	230	13	14	0/72	880
319	1280	1380	0.7	5.5	−6.6	7	−7.1	8.1	−35	5000	4750	240	230	12	15	0/72	960
320	1280	1360	0.6	1.7	−7.3	7.5	−8	8.2	−35	4990	4740	230	220	12	14	0/72	940
321	1280	1130	0.6	2	−8.1	4	−8.5	8.6	−18	5170	4910	250	240	12	15	0/72	970
322	1300	1130	0.6	2.2	−8.3	4.5	−8.5	8.7	−18	5090	4840	230	220	12	14	0/72	900

⑩ The mark * indicates "out of the scope of the present invention.
⑪ Insulation breakdown voltage ⑫ Humidity resistance load test: Number of reject.
⑬ Mean life span ⑮ Unmeasurable due to insufficient sintering
⑭ Unmeasurable due to semiconductor formation

【0067】

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

~~表13~~ Table 13.

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ ~~Capacitance change ratio due to temperature change~~ ⑥ Maximum value
Ratio of temperature dependent capacitance change

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω・F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間(h) ⑫
323	1300	940	0.7	2.3	−8.2	5	−8.5	8.8	−11	5000	4750	210	200	12	15	0/72	930
324	1300	1320	0.6	2.1	−7.5	5.5	−8	8.2	−32	5120	4860	250	240	12	14	0/72	850
325	1300	1230	0.6	3.3	−7.5	6	−8.4	8.4	−23	5170	4910	250	240	12	14	0/72	870
326	1280	1280	0.6	3	−7.8	5.5	−8.3	8.5	−24	5080	4830	250	240	13	14	0/72	890
327	1280	1240	0.7	2.5	−8.1	5.1	−8.2	8.7	−19	5120	4860	250	240	12	15	0/72	900
328	1300	930	0.6	2.5	−8.3	6	−8.5	8.8	−11	5100	4850	250	240	13	14	0/72	960
329	1300	1250	0.6	2.3	−7.5	5.2	−7.9	8.5	−22	5010	4760	220	210	12	14	0/72	990
330	1300	1110	0.7	3	−7.7	5	−8	7.9	−17	5000	4750	220	210	12	14	0/72	900
331	1280	1260	0.6	2	−8	5.1	−8.2	8.1	−21	4980	4730	220	210	12	15	0/72	880
332	1280	1160	0.6	2.4	−7.4	5	−8.1	8	−21	5090	4840	250	240	12	14	0/72	820
333	1300	1220	0.7	3	−7.5	6.2	−8	8.1	−23	4920	4670	220	210	12	14	0/72	870
334	1300	1240	0.7	2.1	−7.7	6	−8.5	8.1	−21	5000	4750	200	190	12	14	0/72	900
335	1300	1250	0.6	1.9	−7.6	5.4	−8.3	8.5	−22	5010	4760	200	190	13	14	0/72	920
336	1280	1260	0.7	2.6	−7.8	5.8	−7.9	8.2	−22	5110	4860	250	240	13	14	0/72	880
337	1280	1150	0.6	2.3	−8.3	6.2	−8.5	8.8	−18	5100	4850	250	240	12	14	0/72	960
338	1280	1520	0.6	2	−7.5	6.1	−8.1	8.2	−40	5080	4830	250	240	12	14	0/72	900
339	1300	1260	0.6	2.4	−7.4	6.2	−7.5	8.3	−23	4990	4740	200	190	12	14	0/72	950
340	1300	1110	0.7	2	−7.6	6	−7.9	8.1	−17	5120	4860	250	240	12	14	0/72	940
341	1300	1270	0.6	2.6	−7.9	5.8	−8.5	8.5	−25	5100	4850	250	240	12	14	0/72	900
342	1300	1350	0.7	2.4	−7.8	7	−8.4	8.5	−33	5140	4880	250	240	12	14	0/72	920
343	1280	1130	0.7	2.2	−7.7	6.4	−8.3	8.5	−18	5190	4930	250	240	12	14	0/72	900
344	1300	980	0.7	2	−8.1	6	−8.5	8.8	−11	5100	4850	240	230	12	14	0/72	960

⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation breakdown voltage ⑪ Humidity resistance load test : Number of reject.
⑫ Mean life span

This Sheet Has Been Replaced

【表14】 Table 14

① sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ Capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑦ DC bias characteristic ⑧ Product CR ⑨ Impressed voltage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率 (%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性 (%) ⑦ ΔC/C 5kV/mm	CR積 (Ω·F) ⑧ 315V 印加 ⑨ 25℃	945V 印加 ⑨ 25℃	315V 印加 ⑨ 150℃	945V 印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
401	1280	1350	0.7	2.2	−8.4	4.8	−8.2	8.4	−33	4950	4700	220	210	13	15	0/72	920
402	1280	1380	0.6	2.1	−8	4.9	−8.1	8.3	−36	4970	4720	240	230	12	14	0/72	940
403	1280	1360	0.6	2.7	−7.9	5	−7.8	8.1	−33	4960	4710	230	220	13	15	0/72	930
404	1300	1310	0.6	2.1	−7.7	5.1	−7.9	8.3	−31	4990	4740	250	240	12	14	0/72	900
405	1300	1380	0.6	2.3	−7.9	4.7	−8.4	8.6	−36	5040	4790	230	220	12	14	0/72	870
406	1280	1380	0.6	2	−7.7	4.7	−8.5	8.7	−36	5010	4760	240	230	12	14	0/72	950
407	1280	1370	0.6	2	−7.5	5	−8.5	8.8	−35	5140	4880	250	240	12	14	0/72	930
408	1280	1380	0.6	2.8	−8	5	−8.2	8.5	−36	5030	4780	250	240	12	14	0/72	940
409	1280	1380	0.6	3	−7.4	4.9	−8.4	8.3	−36	4980	4730	240	230	12	14	0/72	900
410	1300	1350	0.6	2.4	−7.6	5.1	−8.5	8.7	−33	5000	4750	240	230	12	14	0/72	970
411	1300	1320	0.7	2.3	−7.5	5.4	−8.3	8.5	−32	4990	4740	230	220	12	14	0/72	920
412	1280	1360	0.6	2.7	−7.5	5.1	−8.2	8.3	−33	5050	4800	210	200	12	14	0/72	900
413	1350	焼結不足のため測定不能 ⑬															
414	1350	焼結不足のため測定不能 ⑬															
415	1350	1350	1.4	2.4	−7.7	5	−8.5	8.6	−33	5040	4790	240	230	11	13	32/72	110
416	1350	焼結不足のため測定不能 ⑬															
417	1350	焼結不足のため測定不能 ⑬															
418	1300	1350	0.6	2.5	−7.5	5.1	−8.3	8.5	−33	5080	4830	230	220	12	14	0/72	880
419	1350	1370	1.3	2	−7.3	4.9	−8.2	8.5	−35	5100	4850	250	240	11	13	25/72	140
420	1300	1350	0.7	2.4	−7.8	4.7	−8.5	8.7	−33	4960	4710	260	250	12	14	0/72	920
421	1350	1360	1.3	2.5	−8	4.3	−8.3	8.5	−33	5070	4820	250	240	11	13	33/72	110
422	1350	1330	1.2	2.3	−8.1	4.9	−8.2	8.5	−32	5070	4820	250	240	11	13	28/72	150

⑤ Ratio of temperature dependent capacitance change

⑩ Insulation breakdown voltage ~~⑪ [illegible]~~
⑪ Humidity resistance load test Number of rejection ⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

【0078】

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【0083】

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation breakdown voltage ⑪ Humidity resistance load test; Number of reject

【表15】 Table 15

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
501	1300	1350	0.6	3.3	−8	6.2	−7.5	7.8	−34	4970	4720	210	200	12	14	0/72	900
502	1280	1370	0.6	3.2	−8.1	6.5	−7.7	7.9	−36	4980	4730	220	210	12	14	0/72	890
503	1280	1360	0.7	3.4	−8.2	6.7	−8	8.2	−34	5030	4780	220	210	12	14	0/72	930
504	1300	1330	0.6	4	−8	6.5	−8.1	8.2	−33	5020	4770	230	220	13	15	0/72	870
505	1300	1350	0.6	3.5	−8.1	6.8	−7.9	8.1	−34	4990	4740	230	220	12	14	0/72	850
506	1280	1320	0.6	3.4	−7.9	6.3	−7.7	8	−33	4980	4730	210	200	13	15	0/72	900
507	1280	1350	0.6	3.5	−8.1	6.4	−7.5	7.7	−34	4950	4700	230	220	12	14	0/72	880
508	1300	1360	0.6	3.3	−7.7	6.8	−7.8	8	−34	4950	4700	200	190	12	14	0/72	910
509	1300	1370	0.6	3.7	−8.1	6.5	−7.7	7.8	−36	4980	4730	230	220	12	14	0/72	880
510	1300	1360	0.6	3.5	−7.9	6.8	−7.5	7.7	−34	5000	4750	220	210	12	14	0/72	870
511	1280	1340	0.6	3.8	−8	7	−7.6	7.8	−33	5320	5050	310	300	12	14	0/72	900
512	1300	1330	0.6	3.4	−7.8	6.8	−7.8	8.2	−34	5330	5060	320	300	13	15	0/72	900
513	1350	1310	1.3	3.3	−7.8	6.8	−7.9	8.3	−33	5100	4850	220	210	11	13	42/72	120
514	1350	焼結不足のため測定不能 ⑬															
515	1350	焼結不足のため測定不能 ⑬															
516	1350	1300	1.2	3.5	−8	6.5	−7.5	7.7	−33	4950	4700	230	220	11	13	71/72	130
517	1350	焼結不足のため測定不能 ⑬															
518	1350	焼結不足のため測定不能 ⑬															
519	1350	焼結不足のため測定不能															

⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

⑤ Ratio of temperature dependent capacitance change

整理番号＝1980037

THIS SHEET HAS BEEN REPLACED

① Sample No. ② Kind of $BaTiO_3$ ③ Total of 2

④ The mark * indicate "out of the scope of the present invention

整理番号＝198038

表4 Table 1002

THIS SHEET HAS BEEN REPLACED

④ ＊印は本発明の範囲外 ⑤ ⑥

試料番号 ①	$(BaO)_mTiO_2+\alpha M_2O_3+\beta BaZrO_3+\gamma MgO+gMnO$									第1の副成分の添加量（重量部）	第2の副成分の添加量（重量部）
	$BaTiO_3$ ②の種類	α		③αの合計	β	γ	g	γ+g	m		
		Sc_2O_3	Y_2O_3								
*1001 ~~*1~~	IA	0	0.0008	0.0008	0.02	0.002	0.002	0.004	1.005	1	0
*1002 ~~*2~~	IA	0.01	0.06	0.07	0.03	0.07	0.05	0.12	1.005	1	0
*1003 ~~*3~~	IA	0.01	0.02	0.03	0	0.03	0.02	0.05	1.01	1.5	0
*1004 ~~*4~~	IA	0.02	0.01	0.03	0.08	0.02	0.04	0.06	1.01	1.5	0
*1005 ~~*5~~	IA	0.01	0.01	0.02	0.02	0.001	0.034	0.035	1.01	1	0
*1006 ~~*6~~	IA	0.01	0.02	0.03	0.02	0.125	0.005	0.13	1.01	1	0
*1007 ~~*7~~	IA	0.02	0.02	0.04	0.02	0.079	0.001	0.08	1.01	1	0
*1008 ~~*8~~	IA	0.01	0.02	0.03	0.02	0.005	0.125	0.13	1.01	1	0
*1009 ~~*9~~	IA	0.01	0.02	0.03	0.03	0.08	0.06	0.14	1.01	1	0
*1010 ~~*10~~	IA	0.02	0.01	0.03	0.03	0.02	0.03	0.05	0.99	1	0
*1011 ~~*11~~	IA	0.01	0.01	0.02	0.04	0.03	0.02	0.05	1.00	1	0
*1012 ~~*12~~	IA	0.02	0	0.02	0.04	0.02	0.01	0.03	1.038	1	0
*1013 ~~*13~~	IA	0.01	0.01	0.02	0.02	0.03	0.01	0.04	1.05	0	1
*1014 ~~*14~~	IA	0.01	0.01	0.02	0.02	0.01	0.02	0.03	1.01	0	0
*1015 ~~*15~~	IA	0.02	0.01	0.03	0.02	0.03	0.02	0.05	1.01	5	0
*1016 ~~*16~~	IA	0.01	0.01	0.02	0.02	0.01	0.03	0.04	1.01	0	0
*1017 ~~*17~~	IA	0.005	0.025	0.03	0.02	0.03	0.02	0.05	1.01	0	4
*1018 ~~*18~~	ID	0.01	0.02	0.03	0.03	0.03	0.03	0.06	1.01	2	0
1019 ~~19~~	IA	0	0.001	0.001	0.02	0.002	0.0015	0.003	1.015	1	0
1020	IB	0.02	0	0.02	0.03	0.02	0.01	0.03	1.02	1	0
1021	IC	0.005	0.05	0.055	0.03	0.12	0.002	0.122	1.03	1	0
1022	IA	0	0.04	0.04	0.03	0.03	0.04	0.07	1.02	1	0
1023	IA	0	0.06	0.06	0.03	0.01	0.12	0.13	1.01	0	1

⑤ Amount of addition of the ~~fo~~ first side component (parts by weight)

⑥ Amount of addition of the second side component (parts by weight)

表1001は存在しません (Table 1001 was deleted.)

This Sheet Has Been Replaced

【表3】 Table

① Sample No. ② ~~Kind~~ Kind of $BaTiO_3$ ③ Total of α
④ Amount of addition of the first side component
⑤ Amount of addition of the second side component

試料番号①	$(BaO)_mTiO_2+\alpha M_2O_3+\beta BaZrO_3+\gamma MgO+gMnO$									④ 第1の副成分の添加量（重量部）	⑤ 第2の副成分の添加量（重量部）
	$BaTiO_3$ ②の種類	α		③ αの合計	β	γ	g	γ+g	m		
		Sc_2O_3	Y_2O_3								
1024	IA	0	0.01	0.01	0.005	0.01	0.02	0.03	1.01	1	0
1025	IA	0	0.02	0.02	0.04	0.01	0.03	0.04	1.01	1	0
1026	IA	0	0.03	0.03	0.06	0.03	0.02	0.05	1.01	1	0
1027	IA	0.01	0.04	0.05	0.03	0.06	0.05	0.11	1.01	2	0
1028	IA	0	0.005	0.005	0.02	0.005	0.006	0.011	1.001	2	0
1029	IA	0	0.04	0.04	0.03	0.05	0.02	0.07	1.01	0	2
1030	IA	0	0.02	0.02	0.03	0.02	0.03	0.05	1.035	2	0
1031	IA	0	0.02	0.02	0.03	0.03	0.01	0.04	1.015	0.2	0
1032	IA	0	0.02	0.02	0.03	0.02	0.03	0.05	1.01	3	0
1033	IA	0	0.02	0.02	0.03	0.02	0.015	0.035	1.01	0	0.2
1034	IA	0	0.02	0.02	0.03	0.03	0.01	0.04	1.01	0	3

【0029】

次いで、この秤量物にポリビニルブチラール系バインダおよびエタノールなどの有機溶剤を加えて、ボールミルにより湿式混合し、セラミックスラリーを調整

This Sheet Has Been Replaced

【表4】 Table 1004

This Sheet Has Been Replaced

JIS SHEET HAS BEEN REPLACED

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ Capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑦ DC bias characteristic ⑧ Product CR ⑨ Impressed voltage

⑤ Ratio of temperature dependent capacitance change

＊印は本発明の範囲外 ⑩

	試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率 (%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑪ AC	DC	耐湿負荷試験不良個数 ⑫	平均寿命時間 (h) ⑬
＊1001	＊1	1300	1140	0.8	5.5	−12.5	4.6	−17.2	20	−17	5130	4870	210	200	12	14	0/72	890
＊1002	＊2	1300	850	0.7	2.1	−7.2	4.4	−6.5	8	−12	8490	8070	190	180	12	14	0/72	850
＊1003	＊3	1280	1020	0.6	2	−8	4.2	−8.2	9.1	−15	3140	2200	150	110	12	14	0/72	840
＊1004	＊4	1300	1360	0.7	2.4	−14.7	5.1	−29.5	35.4	−26	5170	4910	230	220	12	14	0/72	150
＊1005	＊5	1280	1220	0.7	3.2	−14.2	4.1	−17.9	23	−21	3070	2920	130	120	13	14	0/72	830
＊1006	＊6	1360	1400	2.7	2.5	−8.3	4.3	−8.6	9	−35	5140	4880	220	210	12	14	61/72	180
＊1007	＊7	半導体化のため測定不能 ⑭																
＊1008	＊8	1280	1340	0.8	3.5	−8.9	4.8	−18.6	25.1	−28	3140	2980	140	130	12	14	0/72	190
＊1009	＊9	1280	880	2.6	3.5	−9.2	3.8	−9.1	9.9	−12	5010	4760	240	230	12	14	15/72	130
＊1010	＊10	半導体化のため測定不能 ⑭																
＊1011	＊11	1300	1280	0.7	3.9	−9	4.7	−9.3	10.2	−25	3300	3140	160	150	10	12	0/72	110
＊1012	＊12	焼結不足のため測定不能 ⑮																
＊1013	＊13	焼結不足のため測定不能 ⑮																
＊1014	＊14	焼結不足のため測定不能 ⑮																
＊1015	＊15	1300	1280	2.3	4	−8.9	4.2	−9.4	10.9	−25	3310	3150	160	150	11	11	0/72	150
＊1016	＊16	焼結不足のため測定不能																
＊1017	＊17	1300	1260	2.5	2.8	−8.4	3.1	−7.6	8.4	−23	3150	2990	180	170	10	11	0/72	170
＊1018	＊18	1300	1030	0.7	2.5	−7.9	5.6	−9.4	9.2	−15	5120	4860	260	250	12	14	0/72	870
1019	1019	1280	1580	0.7	2.5	−7.2	3.8	−8.5	8.8	−45	5070	4820	260	250	12	15	0/72	950
1020	1020	1280	1520	0.6	2.6	−7	4	−8	8.6	−45	5050	4800	240	230	12	14	0/72	960
1021	1021	1280	1080	0.6	3	−8	4.1	−8.2	9	−15	5290	5030	280	270	12	15	0/72	820
1022	1022	1300	1320	0.6	2.5	−8.3	3.8	−8.6	8.8	−26	5160	4900	250	240	12	14	0/72	830
1023	1023	1300	1050	0.7	2.4	−8.1	4.2	−8.4	8.9	−15	5230	4970	220	210	13	15	0/72	840

⑩ The mark ＊ indicate "out of the scope of the present invention
⑪ Insulation breakdown voltage ⑫ Humidity resistance load test: Number of reject
⑬ Mean life span ⑭ Unmeasurable due to semiconductor formation
⑮ Unmeasurable due to insufficient sintering

整理番号＝198038

【表5】 Table. 105

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
~~⑤ Capacitance change ratio due to temperature change~~ ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation breakdown voltage
⑪ Humidity resistance load test : Number of rejects
⑫ Mean life span.

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間(h) ⑫
1024	1300	1570	0.6	2.9	−7.9	4.1	−8.2	8.8	−45	5180	4920	230	220	12	14	0/72	890
1025	1300	1480	0.7	3.1	−7.1	4.3	−7.9	8.5	−40	5300	5040	270	260	12	15	0/72	900
1026	1280	1420	0.6	3.2	−8.1	3.8	−8.3	9	−35	5240	4980	280	270	13	14	0/72	830
1027	1280	1230	0.7	2.4	−7.5	3.9	−8.1	8.6	−22	5260	5000	220	210	12	14	0/72	840
1028	1300	1590	0.6	2.8	−7.6	4.2	−7.9	8.4	−45	5280	5020	200	190	12	14	0/72	860
1029	1300	1330	0.6	2.7	−7.2	4.3	−8.2	8.6	−26	5040	4790	210	200	12	14	0/72	950
1030	1300	1540	0.6	2.6	−7.9	4.5	−8.1	8.8	−42	5230	4970	240	230	13	14	0/72	900
1031	1280	1560	0.6	2.5	−8	4.1	−8.5	8.9	−42	5080	4830	270	260	12	15	0/72	870
1032	1280	1550	0.6	2	−8.1	3.9	−8.2	8.7	−42	5190	4930	210	200	12	14	0/72	890
1033	1300	1540	0.7	2.4	−7.8	3.9	−8.5	9.1	−42	5140	4880	210	200	12	14	0/72	860
1034	1300	1520	0.6	2.5	−7.6	4.2	−8.4	9.2	−43	5080	4830	230	220	12	14	0/72	840

⑤ Ratio of temperature dependent capacitance change

【0039】

THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

【~~表６~~】 Table 1006

試料番号 ①	② 添加量（重量部）	③ 第１の副成分 ④ 組成（モル%、但しWを除く）				
		Li_2O	$(Si_wTi_{1-w})O_2$	w	Al_2O_3	ZrO_2
1101	1	20	80	0.3	0	0
1102	1	10	80	0.6	5	5
1103	0.8	10	70	0.5	20	0
1104	0.8	35	45	1	10	10
1105	1.5	45	45	0.5	10	0
1106	1.5	45	55	0.3	0	0
1107	1	20	70	0.6	5	5
1108	1	20	70	0.4	10	0
1109	1.2	30	60	0.7	5	5
1110	1.2	30	60	0.8	10	0
1111	2	40	50	0.6	5	5
1112	2	40	50	0.9	0	10
1113	1.5	10	85	0.4	5	0
1114	2	5	75	0.6	10	10
1115	1.2	20	55	0.5	25	0
1116	1	45	40	0.8	0	15
1117	0.8	50	45	0.7	5	0
1118	1.2	25	75	0.9	0	0
1119	1.5	25	75	1	0	0
1120	1	35	65	0.9	0	0
1121	1.5	35	65	1	0	0
1122	1.2	20	70	0.2	0	10

~~【００４９】~~

次いで、実施例１と同様にして電気的特性を測定した。その結果を表７に示す。

~~【００５０】~~

① Sample No.
② Amount of addition (parts by weight)
③ The first side component
④ Composition (mol %, ~~exce~~ except W)

This Sheet Has Been Replaced

表4 Table 1001

① sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tan δ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧CR積(Ω・F) 315V印加⑨ 25℃	945V印加⑨ 25℃	315V印加⑨ 150℃	945V印加⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間(h) ⑫
I101	1280	1430	0.8	2.5	−8.2	3.3	−8.4	9.4	−36	5120	4860	220	210	13	14	0/72	840
I102	1280	1450	0.6	2.3	−8.4	3.8	−8.6	9.5	−37	5080	4830	230	220	13	14	0/72	890
I103	1280	1490	0.6	2.4	−7.9	4.2	−8.2	9.9	−39	5160	4900	220	210	12	14	0/72	850
I104	1300	1470	0.7	2.1	−7.8	4.6	−8.1	8.9	−39	5200	4940	210	200	12	15	0/72	830
I105	1300	1430	0.6	2	−7.8	3.5	−8.3	9.4	−36	5180	4920	230	220	13	14	0/72	900
I106	1280	1450	0.7	2.6	−8.2	3.7	−8.6	9.2	−37	5090	4840	210	200	12	14	0/72	870
I107	1280	1430	0.8	2.8	−8.6	3.8	−8.9	9.3	−36	5070	4820	220	210	13	14	0/72	830
I108	1280	1440	0.6	2.9	−8.4	4.1	−8.7	8.9	−36	5030	4780	220	210	12	14	0/72	890
I109	1280	1480	0.7	2.4	−7.6	4.2	−8.2	8.8	−39	5220	4960	210	200	12	14	0/72	910
I110	1300	1470	0.6	2.6	−7.4	3.8	−8.3	8.8	−39	5080	4830	230	220	13	14	0/72	870
I111	1300	1420	0.8	2.4	−8	3.9	−8.1	9	−36	5100	4850	200	190	12	14	0/72	850
I112	1280	1410	0.6	2.2	−8.4	3.9	−8.6	9.1	−35	5180	4920	210	200	12	14	0/72	840
I113	1350	焼結不足のため測定不能 ⑬															
I114	1350	焼結不足のため測定不能 ⑬															
I115	1350	1460	1.5	2.8	−7.8	4.2	−8.2	8.9	−37	4820	4580	190	180	11	13	32/72	180
I116	1350	焼結不足のため測定不能 ⑬															
I117	1350	焼結不足のため測定不能 ⑬															
I118	1300	1420	0.8	2.9	−7.9	4.8	−8.3	9.1	−36	5160	4900	210	200	12	14	0/72	860
I119	1350	1430	1.4	2.7	−8.2	4.2	−8.4	9.2	−36	4890	4650	190	180	11	13	16/72	150
I120	1300	1450	0.7	2.5	−8	4	−8.2	9.4	−37	5130	4870	210	200	12	14	0/72	840
I121	1350	1460	1.4	2.2	−8.1	3.8	−8.6	9.1	−38	4950	4700	190	180	11	13	36/72	140
I122	1350	1450	1.3	2.3	−8.3	3.8	−8.7	9.1	−38	4870	4630	190	180	11	13	25/72	190

⑩ Insulation breakdown voltage ⑪ Humidity resistant load test: Number of reject ⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

【0051】

THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

【表8】 Table 10

試料番号 ①	添加量（重量部）②	③ 第2の副成分 ④ 主成分（モル%） SiO_2	TiO_2	XO BaO	CaO	SrO	MgO	ZnO	MnO	⑤ 合計	添加成分（重量部） ⑥ Al_2O_3	ZrO_2
1201	1	85	1	1	0	0	0	4	9	14	0	0
1202	1	35	51	0	10	0	0	0	4	14	0	0
1203	1	30	20	0	30	0	15	4	1	50	0	0
1204	1	39	1	20	20	2	0	13	5	60	0	0
1205	1	70	10	5	5	0	0	10	0	20	0	0
1206	1	45	10	0	0	0	0	15	30	45	0	0
1207	1	50	20	10	10	3	7	0	0	30	0	0
1208	1	50	30	0	16	0	0	0	4	20	0	0
1209	1	35	30	25	10	0	0	0	0	35	0	0
1210	1	40	40	10	0	0	0	5	5	20	0	0
1211	1	45	22	3	30	0	0	0	0	33	15	0
1212	1	45	22	3	30	0	0	0	0	33	10	5
1213	1	65	25	5	5	0	0	0	0	10	0	0
1214	1	25	40	15	0	10	0	5	5	35	0	0
1215	1	30	10	30	25	0	0	5	0	60	0	0
1216	1	50	0	35	15	0	0	0	0	50	0	0
1217	1	45	22	30	0	0	3	0	0	33	25	0
1218	1	45	22	30	0	3	0	0	0	33	0	15
1219	1	30	60	10	0	0	0	0	0	10	0	0

① Sample No. ② Amount of addition ③ the second side component
④ Essential component (mol %) ⑤ Total
⑥ Added component (Parts by weight)

【0056】

次いで、実施例1と同様にして電気的特性を測定した。その結果を表9に示す

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【表4】 Table 4

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation break down voltage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧CR積(Ω·F) 315V ⑨印加 25℃	945V ⑨印加 25℃	315V ⑨印加 150℃	945V ⑨印加 150℃	⑩絶縁破壊電圧(kV/mm) AC	DC	⑪耐湿負荷試験 不良個数	⑫平均寿命時間(h)
1201	1300	1520	1.3	2.4	−7.2	2.5	−7.5	8.1	−41	5010	4760	200	190	12	14	0/72	820
1202	1300	1530	1.4	2.3	−7.5	2.4	−7.8	8.2	−41	5000	4750	210	200	12	14	0/72	810
1203	1300	1550	1.3	2.2	−7.8	2.3	−7.9	8	−42	5020	4770	200	190	13	14	0/72	800
1204	1300	1540	1.3	2.3	−7.7	2.4	−7.8	8.3	−41	5010	4760	200	190	12	15	0/72	860
1205	1300	1520	1.3	2.4	−7.5	2.2	−7.6	8.1	−41	5030	4780	200	190	12	14	0/72	830
1206	1300	1530	1.3	2.2	−7.4	2	−7.8	8.1	−41	5010	4760	200	190	13	15	0/72	890
1207	1300	1560	1.3	2.3	−7.6	2.1	−7.9	8.2	−42	5000	4750	210	200	12	14	0/72	870
1208	1300	1520	1.3	2.4	−7.5	2.3	−8	8.2	−41	5010	4760	200	190	12	14	0/72	850
1209	1300	1530	1.3	2.2	−7.1	2.4	−7.8	8.3	−41	5020	4770	200	190	13	14	0/72	820
1210	1300	1510	1.4	2.3	−7.5	2.4	−7.9	8.1	−41	5030	4780	200	190	12	14	0/72	810
1211	1300	1530	1.3	2.5	−7.2	2.5	−7.8	8	−41	5420	5150	320	300	12	14	0/72	860
1212	1300	1540	1.3	2.1	−7.1	2.2	−7.6	8.1	−41	5410	5140	300	290	12	14	0/72	840
1213	1350	1550	1.5	2	−7	2.3	−7.6	8.2	−42	4830	4590	200	190	11	13	52/72	160
1214	1350	焼結不足のため測定不能 ⑬															
1215	1350	焼結不足のため測定不能 ⑬															
1216	1350	1560	1.6	2.3	−7.2	2.4	−7.8	8.2	−42	4790	4550	200	190	11	13	72/72	180
1217	1350	焼結不足のため測定不能 ⑬															
1218	1350	焼結不足のため測定不能 ⑬															
1219	1350	焼結不足のため測定不能 ⑬															

⑪ Humidity resistance load test: Number of reject
⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

【0058】

THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

【表10】 Table 10

【0083】

④ ＊印は本発明の範囲外

試料番号 ①	$(BaO)_mTiO_2+\alpha M_2O_3+\beta BaZrO_3+\gamma MnO$							⑤ 第1の副成分の添加量（重量部）	⑥ 第2の副成分の添加量（重量部）
	② $BaTiO_3$の種類	α		αの③合計	β	γ	m		
		Sc_2O_3	Y_2O_3						
＊1301 ~~＊301~~	IA	0	0.0008	0.0008	0.01	0.0015	1.005	1	0
＊1302 ~~＊302~~	IA	0.03	0.045	0.075	0.02	0.15	1.01	1	0
＊1303 ~~＊303~~	IA	0.01	0.01	0.02	0	0.042	1.01	1.5	0
＊1304 ~~＊304~~	IA	0.02	0.01	0.03	0.07	0.06	1.01	1.5	0
＊1305 ~~＊305~~	IA	0	0.02	0.02	0.02	0.001	1.01	1	0
＊1306 ~~＊306~~	IA	0.02	0	0.02	0.03	0.14	1.01	1	0
＊1307 ~~＊307~~	IA	0	0.03	0.03	0.03	0.06	0.99	1	0
＊1308 ~~＊308~~	IA	0.005	0.015	0.02	0.04	0.041	1	1	0
＊1309 ~~＊309~~	IA	0	0.02	0.02	0.03	0.04	1.038	1	0
＊1310 ~~＊310~~	IA	0	0.03	0.03	0.02	0.06	1.045	0	1
＊1311 ~~＊311~~	IA	0	0.02	0.02	0.02	0.04	1.01	0	0
＊1312 ~~＊312~~	IA	0.01	0.02	0.03	0.02	0.06	1.01	5	0
＊1313 ~~＊313~~	IA	0.02	0.01	0.03	0.02	0.063	1.02	0	0
＊1314 ~~＊214~~	IA	0	0.02	0.02	0.03	0.04	1.01	0	4
＊1315 ~~＊315~~	ID	0	0.03	0.03	0.03	0.06	1.02	1.5	0

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α:

④ The ~~mack~~ mark * indicates " out of the scope of the present invention

⑤ Amount of addition of the first side component (parts by weight)

⑥ Amount of addition of the second side component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

【表11】 Table 1011

【0064】

次いで、実施例1と同様にして電気的特性を測定した。その結果を表12および表13に示す。

【0065】

試料番号①	$(BaO)_mTiO_2+\alpha M_2O_3+\beta BaZrO_3+\gamma MnO$							④ 第1の副成分の添加量（重量部）	⑤ 第2の副成分の添加量（重量部）
	② $BaTiO_3$の種類	α		③ αの合計	β	γ	m		
		Sc_2O_3	Y_2O_3						
1316	A	0	0.001	0.001	0.02	0.002	1.01	1	0
1317	B	0	0.02	0.02	0.03	0.04	1.02	1	0
1318	C	0.01	0	0.01	0.03	0.13	1.03	1	0
1319	A	0.01	0.04	0.05	0.04	0.1	1.02	1	0
1320	A	0.02	0.04	0.06	0.03	0.12	1.01	0	1
1321	A	0	0.01	0.01	0.005	0.02	1.01	1	0
1322	A	0.01	0.01	0.02	0.04	0.04	1.01	2	0
1323	A	0	0.03	0.03	0.06	0.06	1.01	1	0
1324	A	0.02	0.02	0.04	0.03	0.078	1.01	2	0
1325	A	0	0.01	0.01	0.02	0.02	1.001	2	0
1326	A	0	0.005	0.005	0.04	0.01	1.02	0	2
1327	A	0.01	0.01	0.02	0.03	0.04	1.035	2	0
1328	A	0.02	0	0.02	0.03	0.04	1.025	0.2	0
1329	A	0.01	0.01	0.02	0.03	0.04	1.01	3	0
1330	A	0	0.02	0.02	0.03	0.041	1.01	0	0.2
1331	A	0	0.02	0.02	0.03	0.04	1.01	0	3

① Sample ~~No.~~ No. ② Kind of $BaTiO_3$ ③ Total of α.
④ Amount of addition of the first side component (parts by weight)
⑤ Amount of addition of the second side component (parts by weight)

This Sheet Has Been Replaced

【表1】 Table 1012

① Sample No ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ The mark * indicates "out of the scope of the present invention

＊印は本発明の範囲外

	試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ(%) ④	⑤ 容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧ CR積(Ω·F) 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑪ AC	DC	耐湿負荷試験 不良個数 ⑫	平均寿命時間(h) ⑬
#1301	~~*301~~	1300	1570	0.7	5	−12	4.2	−16.7	16.7	−42	5100	4850	200	190	12	14	0/72	900
#1302	~~*302~~	1300	820	0.7	2.2	−6.7	4	−6	6.7	−9	5500	5230	180	170	12	14	0/72	910
#1303	~~*303~~	1300	1450	0.7	2.1	−7.5	4	−7.7	8.2	−36	3020	2110	100	70	12	14	0/72	890
#1304	~~*304~~	1300	1350	0.7	2.3	−14.2	5.3	−28	28	−27	5100	4850	200	190	12	14	0/72	120
#1305	~~*305~~	半導体化のため測定不能 ⑭																
#1306	~~*306~~	1280	1420	0.8	3.5	−8.4	4.5	−18.1	18	−36	3120	2960	140	130	12	14	0/72	140
#1307	~~*307~~	半導体化のため測定不能																
#1308	~~*308~~	1300	1410	0.7	3.5	−8.5	4.3	−8.8	9.1	−35	3100	2950	130	120	10	12	0/72	100
#1309	~~*309~~	焼結不足のため測定不能 ⑮																
#1310	~~*310~~	焼結不足のため測定不能 ⑮																
#1311	~~*311~~	焼結不足のため測定不能 ⑮																
#1312	~~*312~~	1300	1330	2.3	3.6	−8.4	4.1	−8.9	9.2	−27	3330	3160	140	130	11	11	0/72	130
#1313	~~*313~~	焼結不足のため測定不能																
#1314	~~*314~~	1300	1450	2.5	2.7	−7.9	3.2	−7.1	7.9	−36	3150	2990	160	150	10	11	0/72	160
#1315	~~*315~~	1300	1310	0.7	2.6	−7.4	5.5	−8.9	9.2	−25	5060	4810	230	220	12	14	0/72	920

⑪ Insulation breakdown voltage ⑫ Humidity resistance load test; Number of reject
⑬ Mean life span
⑭ Unmeasurable due to semiconductor formation
⑮ Unmeasurable due to insufficient sintering

This Sheet Has Been Replaced
THIS SHEET HAS BEEN REPLACED

【0066】

【表1 31 Table 013

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω・F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験 ⑪ 不良個数	平均寿命時間(h) ⑫
1316	1280	1590	0.7	2.5	−6.7	3	−8	8.4	−40	4900	4660	230	220	12	14	0/72	970
1317	1280	1450	0.6	2.7	−6.5	3.8	−7.5	8	−36	4960	4710	220	210	13	15	0/72	960
1318	1280	1570	0.7	3	−7.5	3.5	−7.7	8.2	−39	5000	4750	250	240	12	14	0/72	850
1319	1300	1110	0.6	2.6	−7.8	3.7	−8.5	8.8	−15	5100	4850	210	200	12	14	0/72	840
1320	1300	940	0.6	2.5	−7.6	4.1	−7.8	8.1	−12	5120	4860	190	180	12	14	0/72	900
1321	1300	1530	0.6	2.7	−7.4	4	−7.6	8	−40	5070	4820	200	190	12	14	0/72	890
1322	1300	1460	0.7	3	−6.6	4.2	−7.4	7.9	−37	5200	4940	250	240	13	15	0/72	910
1323	1300	1340	0.6	3.1	−7.6	4	−7.8	8.2	−26	5230	4970	250	240	13	15	0/72	870
1324	1280	1230	0.7	2.5	−7	3.7	−7.6	7.9	−22	5260	5000	210	200	12	14	0/72	860
1325	1300	1560	0.6	2.7	−7.1	4	−7.3	7.7	−40	5100	4850	190	180	12	14	0/72	890
1326	1300	1580	0.6	2.6	−6.7	4.1	−7.5	7.8	−40	5020	4770	190	180	12	14	0/72	950
1327	1300	1430	0.7	2.5	−7.4	4.2	−7.5	7.8	−36	5110	4860	230	220	13	15	0/72	930
1328	1280	1430	0.6	2.5	−7.5	4.1	−7.8	8	−36	4980	4730	250	240	12	14	0/72	900
1329	1280	1440	0.6	2.3	−7.6	4	−7.7	8	−36	5080	4830	190	180	12	14	0/72	890
1330	1300	1430	0.7	2.7	−7.3	3.8	−7.8	8.1	−36	5060	4810	200	190	13	15	0/72	910
1331	1300	1340	0.6	2.6	−7.1	4	−7.9	8.2	−26	4990	4740	200	190	12	14	0/72	880

⑩ Insulation breakdown voltage
⑪ Humidity resistance load test ; Number of reject
⑫ Mean life span

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

① Sample No. ② Baking temp ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage

表14 Table 104

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤ 容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧ CR積(Ω:F) 315V印加⑨ 25℃	945V印加⑨ 25℃	315V印加⑨ 150℃	945V印加⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
1401	1280	1420	0.7	2.4	−8.1	3.2	−8.3	8.5	−35	4950	4700	210	200	12	14	0/72	900
1402	1300	1430	0.6	2.2	−8.3	3.7	−8.5	8.7	−37	4980	4730	220	210	13	15	0/72	910
1403	1280	1460	0.6	2.4	−7.8	4	−8.1	8.3	−36	5100	4850	200	190	12	14	0/72	860
1404	1300	1480	0.7	2.1	−7.9	4.1	−8	8.2	−37	5000	4750	230	220	12	15	0/72	870
1405	1300	1440	0.7	2.1	−7.8	3.7	−8.2	8.4	−36	5080	4830	220	210	13	14	0/72	880
1406	1300	1440	0.7	2.6	−8.1	3.6	−8.5	8.8	−36	5070	4820	200	190	13	15	0/72	910
1407	1300	1430	0.8	2.7	−8.5	3.7	−8.5	8.8	−35	5120	4860	210	200	13	14	0/72	930
1408	1280	1450	0.6	2.9	−8.4	4	−8.5	8.8	−37	5160	4900	210	200	12	14	0/72	970
1409	1280	1470	0.7	2.5	−7.9	4.1	−8.1	8.4	−36	5000	4750	200	190	12	14	0/72	900
1410	1280	1480	0.6	2.6	−7.6	3.7	−8.3	8.5	−37	5140	4880	220	210	13	14	0/72	880
1411	1300	1430	0.7	2.5	−7.5	3.8	−8.2	8.3	−35	5100	4850	210	200	13	15	0/72	890
1412	1280	1420	0.6	2.3	−8	3.7	−8.4	8.5	−35	5120	4860	200	190	12	14	0/72	930
1413	1350	焼結不足のため測定不能 ⑬															
1414	1350	焼結不足のため測定不能 ⑬															
1415	1350	1450	1.5	2.7	−7.9	4	−8	8.4	−37	4900	4660	180	170	11	13	45/72	140
1416	1350	焼結不足のため測定不能 ⑬															
1417	1350	焼結不足のため測定不能 ⑬															
1418	1300	1430	0.8	2.8	−8	4.2	−8.2	8.6	−35	5030	4780	200	190	11	14	0/72	900
1419	1350	1440	1.5	2.6	−8.1	4	−8.3	8.5	−36	4980	4730	190	180	11	13	23/72	130
1420	1300	1460	0.7	2.6	−8.3	3.9	−8	8.5	−37	5000	4750	200	190	12	13	0/72	880
1421	1350	1450	1.5	2.4	−8.2	3.7	−8.2	8.7	−37	4970	4720	190	180	11	13	39/72	150
1422	1350	1460	1.3	2.4	−8.3	3.7	−8.5	8.7	−37	4990	4740	190	180	11	13	36/72	160

⑩ Insulation breakdown voltage ⑪ Humidity resistance load test: Number of reject
⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

整理番号＝198038
THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

【表15】 Table. 15

① Sample No. ② Baking temp. ③ Dielectric constant. ④ Dielectric loss
⑤ Ratio of temperature dependent ⑥ Maximum value ⑦ DC bias characteristic
⑧ Product CR ⑨ Impressed votage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤ 容量温度変化率 (%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧ CR積(Ω·F) 315V 印加 ⑨ 25℃	945V 印加 ⑨ 25℃	315V 印加 ⑨ 150℃	945V 印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
1501	1300	1440	1	2.3	−7.3	2.3	−7.6	8	−35	4950	4700	190	180	13	15	0/72	920
1502	1300	1430	1.1	2.2	−7.2	2.2	−7.8	8.2	−35	4970	4720	200	190	12	14	0/72	890
1503	1300	1460	1.2	2.1	−7.7	2.1	−7.7	8.1	−36	5000	4750	190	180	13	15	0/72	920
1504	1300	1420	1.1	2.1	−7.6	2.3	−7.8	8.2	−34	5020	4770	230	220	13	15	0/72	960
1505	1300	1470	1	2.3	−7.4	2.2	−7.6	8.1	−37	4960	4710	200	190	12	14	0/72	880
1506	1300	1450	1.2	2.2	−7.2	2.1	−7.9	8.2	−36	5100	4850	200	190	12	15	0/72	940
1507	1300	1420	1.2	2.3	−7.3	2.3	−7.9	8.2	−34	5020	4770	200	190	12	14	0/72	950
1508	1300	1430	1.2	2.3	−7.5	2.4	−8.1	8.2	−35	5060	4810	230	220	12	14	0/72	870
1509	1300	1440	1.1	2.1	−7.2	2.3	−7.8	8.2	−35	5050	4800	210	200	12	14	0/72	890
1510	1300	1480	1.2	2.2	−7.3	2.4	−8	8.1	−37	5020	4770	200	190	12	14	0/72	900
1511	1300	1460	1.1	2.3	−7.1	2.4	−7.8	8.3	−36	5290	5030	310	300	13	15	0/72	960
1512	1300	1440	1.2	2.4	−7.3	2.3	−7.6	8.1	−35	5300	5040	320	300	12	14	0/72	950
1513	1350	1420	1.1	2.3	−7.2	2	−7.7	8.1	−34	4820	4580	210	200	11	13	46/72	150
1514	1350	焼結不足のため測定不能 ⑬															
1515	1350	焼結不足のため測定不能 ⑬															
1516	1350	1430	1.2	2.2	−7.3	2.5	−7.7	8.1	−34	4790	4550	210	200	11	13	72/72	130
1517	1350	焼結不足のため測定不能 ⑬															
1518	1350	焼結不足のため測定不能 ⑬															
1519	1350	焼結不足のため測定不能 ⑬															

⑩ Insulation breakdown voltage ⑫ Humidity resistance load test ; Number of rejects
⑬ Unmeasurable due to insufficient sintering.

【0081】

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【表2】 Table - 2002

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【0028】

*印は本発明の範囲外

試料番号 ①	$(BaO)_m \cdot TiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO$ ② $BaTiO_3$の種類	α Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3	Ho_2O_3	Er_2O_3	Tm_2O_3	Yb_2O_3	αの合計 ③	β	γ	g	γ+g	m	第1の副成分の添加量（重量部） ⑤	第2の副成分の添加量（重量部） ⑥
*2001 *1	2A	0	0.0008	0	0	0	0	0	0	0.0008	0.02	0.0015	0.0015	0.003	1.005	1	0
*2002 *2	2A	0	0	0	0.04	0.03	0	0	0	0.07	0.03	0.04	0.09	0.13	1.01	1	0
*2003 *3	2A	0	0.02	0.02	0	0	0	0	0	0.04	0	0.04	0.038	0.078	1.01	1.5	0
*2004 *4	2A	0	0	0	0.03	0	0	0	0	0.03	0.08	0.03	0.02	0.05	1.01	1.5	0
*2005 *5	2A	0.02	0	0	0	0	0	0	0	0.02	0.02	0.001	0.039	0.04	1.01	1	0
*2006 *6	2A	0	0.02	0.03	0	0	0	0	0.01	0.06	0.02	0.125	0.005	0.13	1.01	1.5	0
*2007 *7	2A	0	0	0	0	0.01	0	0.01	0	0.02	0.03	0.039	0.001	0.04	1.01	1	0
*2008 *8	2A	0	0	0	0.04	0	0.02	0	0	0.06	0.02	0.005	0.125	0.13	1.01	1	0
*2009 *9	2A	0	0.04	0.01	0.01	0	0	0	0	0.06	0.03	0.04	0.1	0.14	1.01	1	0
*2010 *10	2A	0	0	0	0	0.02	0	0	0	0.02	0.03	0.02	0.03	0.05	0.99	1	0
*2011 *11	2A	0.03	0	0	0	0	0	0	0	0.03	0.04	0.03	0.02	0.05	1.00	1	0
*2012 *12	2A	0.01	0	0	0	0	0	0	0	0.01	0.04	0.015	0.005	0.02	1.038	1	0
*2013 *13	2A	0	0.02	0	0	0	0	0	0	0.02	0.02	0.02	0.03	0.05	1.05	0	1
*2014 *14	2A	0	0	0.02	0	0	0	0	0	0.02	0.02	0.02	0.01	0.03	1.01	0	0
*2015 *15	2A	0	0	0.01	0.02	0	0	0	0	0.03	0.03	0.02	0.03	0.05	1.01	5	0
*2016 *16	2A	0	0	0	0.02	0	0	0	0	0.02	0.02	0.03	0.01	0.04	1.01	0	0
*2017 *17	2A	0	0.01	0	0	0	0	0	0	0.01	0.02	0.015	0.005	0.02	1.01	0	4
*2018 *18	2D	0	0	0	0.03	0	0	0	0	0.03	0.03	0.03	0.02	0.05	1.01	2	0
2019 19	2A	0.02	0.01	0	0.02	0	0	0	0	0.05	0.02	0.05	0.07	0.12	1.015	1	0
2020 20	2B	0	0	0	0.02	0	0	0	0	0.02	0.03	0.02	0.01	0.03	1.02	1	0
2021 21	2C	0	0	0.02	0	0	0	0	0	0.06	0.03	0.12	0.002	0.122	1.03	1.5	0
2022 22	2A	0.05	0	0	0	0	0	0	0.01	0.06	0.03	0.06	0.07	0.13	1.02	1	0
2023 23	2A	0.01	0.01	0	0.04	0	0	0	0	0.06	0.03	0.002	0.12	0.122	1.01	0	[illegible]

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α

④ The mark * indicates "out of the scope of the present invention"

⑤ ~~The first~~ Amount of addition of the first component (~~wt~~ parts by weight)

⑥ Amount of addition of the second side component (parts by weight)

表2001は削除した。(Table 2001 was deleted.)

【表21】 Table 21

① 試料番号	② $(BaO)_m \cdot TiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MgO + gMnO$									③						④	⑤
	$BaTiO_3$ の種類	α								αの合計	β	γ	g	γ+g	m	第1の副成分の添加量（重量部）	第2の副成分の添加量（重量部）
		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3	Ho_2O_3	Er_2O_3	Tm_2O_3	Yb_2O_3								
2024	2A	0	0	0	0.001	0	0	0	0	0.001	0.02	0.0015	0.0015	0.003	1.01	1	0
2025	2A	0	0	0.01	0	0	0.01	0	0	0.02	0.02	0.02	0.03	0.05	1.01	1	0
2026	2A	0	0	0	0.02	0	0	0.01	0	0.03	0.02	0.03	0.02	0.05	1.015	0	1
2027	2A	0.02	0	0	0	0.02	0	0	0	0.04	0.02	0.03	0.05	0.08	1.01	0	1
2028	2A	0	0.05	0	0	0	0	0	0	0.05	0.02	0.05	0.06	0.11	1.01	1	0
2029	2A	0	0.02	0	0.04	0	0	0	0	0.06	0.02	0.06	0.062	0.122	1.01	1	0
2030	2A	0	0	0	0.01	0	0.01	0	0	0.02	0.005	0.02	0.03	0.05	1.01	1	0
2031	2A	0	0	0	0.01	0	0	0.01	0	0.02	0.06	0.02	0.02	0.04	1.01	1	0
2032	2A	0	0.02	0	0	0	0.01	0	0	0.03	0.03	0.02	0.04	0.06	1.035	2	0
2033	2A	0	0.01	0	0.01	0	0	0	0	0.02	0.03	0.02	0.03	0.05	1.015	0.2	0
2034	2A	0	0	0.01	0	0	0	0	0	0.01	0.02	0.01	0.012	0.022	1.01	3	0
2035	2A	0	0	0	0.01	0	0	0	0	0.01	0.03	0.015	0.005	0.02	1.01	0	0.2
2036	2A	0.01	0	0	0.01	0	0	0	0	0.02	0.03	0.02	0.03	0.05	1.01	0	3

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α
④ The amount of addition of the first component (parts by weight)
⑤ The amount of addition of the second component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

整理番号＝198040

表4 Table 2004

THIS SHEET HAS BEEN REPLACED

【0038】

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of time dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage

⑩ *印は本発明の範囲外

	試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tan δ (%) ④	容量温度変化率 (%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V 印加 ⑨ 25℃	945V 印加 ⑨ 25℃	315V 印加 ⑨ 150℃	945V 印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑪ AC	DC	耐湿負荷試験 不良個数 ⑫	平均寿命時間 (h) ⑬
*2001	*1	1300	2030	0.8	2.4	−8.6	4.3	−12.5	13.4	−56	3040	2890	110	110	13	14	0/72	850
*2002	*2	1300	860	1	3.5	−14.9	6.5	−23.4	23.4	−14	5070	4820	240	230	13	14	0/72	170
*2003	*3	1280	1350	0.9	3.6	−8.5	3.3	−13.4	13.4	−30	3020	2110	120	80	12	14	0/72	800
*2004	*4	1300	1420	1	3.5	−13.2	4	−28.6	28.6	−36	5120	4860	210	200	12	14	0/72	120
*2005	*5	1280	1550	0.9	3.6	−13.2	4	−17.2	17.2	−41	3040	2890	120	110	13	14	0/72	880
*2006	*6	1360	1080	2.5	2.9	−9.1	4.5	−12.8	12.8	−16	5080	4830	220	210	12	14	49/72	180
*2007	*7	半導体化のため測定不能 ⑭																
*2008	*8	1280	1060	0.8	4.2	−9.2	4.5	−18.3	18.3	−16	3060	2910	140	130	12	14	0/72	110
*2009	*9	1280	1040	2.5	3.1	−9	4.1	−13.5	13.5	−15	5080	4830	230	220	12	14	15/72	100
*2010	*10	半導体化のため測定不能																
*2011	*11	1300	1460	0.9	3.4	−9.4	3.8	−13.4	13.4	−38	3180	3020	170	160	10	11	0/72	190
*2012	*12	焼結不足のため測定不能 ⑮																
*2013	*13	焼結不足のため測定不能 ⑮																
*2014	*14	焼結不足のため測定不能 ⑮																
*2015	*15	1300	1470	2.7	3.5	−9.3	4	−12.9	12.9	−39	3160	3000	180	170	10	12	0/72	150
*2016	*16	焼結不足のため測定不能																
*2017	*17	1300	1920	2.6	3.2	−9.1	3.8	−12.7	12.7	−55	3250	3090	170	160	11	11	0/72	120
*2018	*18	1300	1050	0.8	3	−8.7	4.2	−13.5	13.5	−15	5140	4880	250	240	13	15	0/72	850
2019	19	1280	1230	0.7	2.8	−8.9	3.8	−12.8	12.8	−22	5080	4830	260	250	12	15	0/72	890
2020	20	1280	1560	0.8	2.7	−9	3.8	−13.6	13.6	−42	5060	4810	270	260	12	14	0/72	920
2021	21	1280	1080	0.7	2.9	−9.2	3.7	−13.5	13.5	−16	5200	4940	280	270	12	15	0/72	890
2022	22	1300	1060	0.8	3	−9.4	3.9	−13.7	13.7	−16	5160	4900	260	250	12	14	0/72	850
2023	23	1300	1070	0.7	3.2	−9	4	−13.8	13.8	−16	5220	4960	250	240	13	15	0/72	900

⑩ The mark * indicates ~~that~~ "out of the scope of the present invention
⑪ Insulation breakdown voltage ⑫ Humidity resistance load test; number of injects
⑬ Mean life span ⑭ Unmeasurable due to semiconductor formation
⑮ Unmeasurable due to insufficient sintering

This Sheet Has Been Replaced

THIS SHEET HAS BEEN REPLACED

表5 Table. 2005

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of ~~time d~~ temperature dependent capacitance change ⑨ Impressed voltage
⑩ Insulation breakdown voltage ⑪ Humidity resistance load test ; number of rejects
⑫ Mean life span.

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間(h) ⑫
2024	1300	2010	0.9	3.4	−8.9	4	−13.6	14	−56	5260	5000	250	240	12	14	0/72	830
2025	1300	1530	0.8	3.4	−8.7	4.1	−12.9	13	−42	5280	5020	280	270	12	14	0/72	840
2026	1280	1470	0.8	3	−8.8	3.9	−13	13	−38	5100	4850	240	230	13	14	0/72	890
2027	1280	1360	0.7	2.9	−8.9	3.8	−12.8	13	−32	5160	4900	260	250	12	14	0/72	820
2028	1300	1220	0.7	3.5	−9.2	3.5	−13.2	13	−22	5290	5030	230	220	13	14	0/72	870
2029	1300	1050	0.7	3.3	−9.3	3.8	−13.8	14	−15	5060	4810	210	200	12	14	0/72	900
2030	1300	1550	0.7	3.2	−9.1	3.8	−13.5	14	−41	5120	4860	260	250	12	14	0/72	830
2031	1280	1570	0.7	3	−9	4	−12.8	13	−41	5180	4920	250	240	12	15	0/72	810
2032	1280	1430	0.7	3.5	−8.9	4.1	−13	13	−37	5280	5020	250	240	12	14	0/72	860
2033	1300	1580	0.7	4	−8.8	3.9	−13.7	14	−41	5160	4900	230	220	12	14	0/72	810
2034	1300	1600	0.7	4.1	−8.7	3.9	−13.5	14	−45	5090	4840	260	250	12	14	0/72	870
2035	1300	1600	0.7	3.2	−9	3.5	−13.9	14	−45	5100	4850	250	240	13	14	0/72	850
2036	1280	1540	0.7	3.5	−8.9	3.6	−12.9	13	−43	5160	4900	280	270	13	14	0/72	880

This Sheet Has Been Replaced

【表６】 Table 2006

THIS SHEET HAS BEEN REPLACED

試料番号 ①	② 第１の副成分					
	添加量 ③ (重量部)	④ 組成（モル%、但しWを除く）				
		Li_2O	$(Si_wTi_{1-w})O_2$	w	Al_2O_3	ZrO_2
z101	1	20	80	0.3	0	0
z102	1	10	80	0.6	5	5
z103	0.8	10	70	0.5	20	0
z104	0.8	35	45	1	10	10
z105	1.5	45	45	0.5	10	0
z106	1.5	45	55	0.3	0	0
z107	1	20	70	0.6	5	5
z108	1	20	70	0.4	10	0
z109	1.2	30	60	0.7	5	5
z110	1.2	30	60	0.8	10	0
z111	2	40	50	0.6	5	5
z112	2	40	50	0.9	0	10
z113	1.5	10	85	0.4	5	0
z114	2	5	75	0.6	10	10
z115	1.2	20	55	0.5	25	0
z116	1	45	40	0.8	0	15
z117	0.8	50	45	0.7	5	0
z118	1.2	25	75	0.9	0	0
z119	1.5	25	75	1	0	0
z120	1	35	65	0.9	0	0
z121	1.5	35	65	1	0	0
z122	1.2	20	70	0.2	0	10

【００４９】

次いで、実施例１と同様にして電気的特性を測定した。その結果を表７に示す。

【００５０】

① Sample No.
② The first side component
③ Amount of addition (parts by weight)
④ Composition (mol %, except W)

This Sheet Has Been Replaced

表1 Table

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC bias characteristic ⑧ Product CR ⑨ Impressed voltage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	容量温度変化率 (%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
2101	1280	1430	0.8	3.6	−9	4.2	−13.4	13	−37	5240	4980	240	230	12	14	0/72	850
2102	1280	1460	0.8	3.8	−8.7	3.8	−13.5	14	−37	5130	4870	220	210	12	14	0/72	890
2103	1280	1490	0.8	4.1	−8.9	3.9	−13.6	14	−40	5170	4910	220	210	12	14	0/72	870
2104	1300	1420	0.8	4	−9	4	−14	14	−35	5090	4840	230	220	12	14	0/72	830
2105	1300	1430	0.9	3.2	−9.2	4.2	−13.8	14	−36	5080	4830	220	210	13	14	0/72	840
2106	1280	1400	0.8	3.6	−9.4	3.7	−13.7	14	−35	5100	4850	210	200	12	14	0/72	850
2107	1280	1460	0.8	3.5	−8.8	3.5	−13.9	14	−38	5160	4900	210	200	13	14	0/72	890
2108	1280	1460	0.8	4	−9.5	3.9	−12.8	13	−38	5240	4980	210	200	12	15	0/72	840
2109	1280	1420	0.9	3.8	−9.6	4.2	−12.5	13	−36	5230	4970	210	200	12	14	0/72	830
2110	1300	1470	0.8	3.5	−9.7	3.5	−13	13	−38	5200	4940	210	200	12	14	0/72	840
2111	1300	1430	0.8	3.9	−9.5	4.2	−13.8	14	−35	5180	4920	220	210	13	14	0/72	890
2112	1280	1420	0.8	4	−9.6	4.3	−13.6	14	−35	5270	5010	220	210	12	14	0/72	900
2113	1350	焼結不足のため測定不能 ⑬															
2114	1350	焼結不足のため測定不能 ⑬															
2115	1350	1230	1.8	3.5	−9.1	4	−13.8	14	−22	3800	3610	150	140	11	12	26/72	150
2116	1350	焼結不足のため測定不能 ⑬															
2117	1350	焼結不足のため測定不能 ⑬															
2118	1300	1480	0.9	3.8	−9.3	4.6	−13.5	14	−37	5160	4900	220	210	12	14	0/72	860
2119	1350	1200	1.6	3.2	−8.8	3.8	−12.9	13	−20	3860	3670	120	110	11	12	20/72	160
2120	1300	1450	0.9	3	−8.9	3.8	−13.7	14	−38	5230	4970	230	220	12	14	0/72	840
2121	1350	1210	1.4	3.8	−8.9	3.5	−13.6	14	−21	3810	3620	130	120	11	12	34/72	130
2122	1350	1190	1.5	3.6	−9	4	−13.5	14	−20	3850	3660	100	90	11	12	29/72	180

⑩ Insulation breakdown voltage ⑪ Humidity resistance load test; number of rejections
⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

THIS SHEET HAS BEEN REPLACED

【0051】

This Sheet Has Been Replaced

整理番号＝1980040

【表8】 Table 2008

THIS SHEET HAS BEEN REPLACED (2)

① Sample No. ② Amount of addition (parts by weight)
④ Essential component (mol %) ⑤ Added component (parts by weight)

試料番号 ①	③ 第２の副成分										⑤ 添加成分(重量部)	
	添加量(重量部) ②	④ 主成分(モル%)										
		SiO_2	TiO_2	XO							Al_2O_3	ZrO_2
				BaO	CaO	SrO	MgO	ZnO	MnO	合計		
2201	1	85	1	1	0	0	0	4	9	14	0	0
2202	1	35	51	0	10	0	0	0	4	14	0	0
2203	1	30	20	0	30	0	15	4	1	50	0	0
2204	1	39	1	20	20	2	0	13	5	60	0	0
2205	1	70	10	5	5	0	0	10	0	20	0	0
2206	1	45	10	0	0	0	0	15	30	45	0	0
2207	1	50	20	10	10	3	7	0	0	30	0	0
2208	1	50	30	0	16	0	0	0	4	20	0	0
2209	1	35	30	25	10	0	0	0	0	35	0	0
2210	1	40	40	10	0	0	0	5	5	20	0	0
2211	1	45	22	3	30	0	0	0	0	33	15	0
2212	1	45	22	3	30	0	0	0	0	33	10	5
2213	1	65	25	5	5	0	0	0	0	10	0	0
2214	1	25	40	15	0	10	0	5	5	35	0	0
2215	1	30	10	30	25	0	0	5	0	60	0	0
2216	1	50	0	35	15	0	0	0	0	50	0	0
2217	1	45	22	30	0	0	3	0	0	33	25	0
2218	1	45	22	30	0	3	0	0	0	33	0	15
2219	1	30	60	10	0	0	0	0	0	10	0	0

【0055】

次いで、実施例1と同様にして電気的特性を測定した。その結果を表9に示す。

This Sheet Has Been Replaced

【0056】

【表9】 Table 9

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation breakdown voltage

試料番号①	焼成温度(℃)②	誘電率③	誘電損失 tanδ(%) ④	容量温度変化率(%) ⑤ ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	CR積(Ω·F) ⑧ 315V印加⑨ 25℃	945V印加⑨ 25℃	315V印加⑨ 150℃	945V印加⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間(h) ⑫
2201	1300	1040	0.7	3.4	−9.5	3.6	−13.9	14	−16	5070	4820	210	200	13	15	0/72	880
2202	1280	1060	0.7	3.5	−8.9	4	−14.2	14	−17	5090	4840	210	200	12	14	0/72	850
2203	1280	1100	0.7	3.8	−9.1	3.9	−13.8	14	−18	5100	4850	220	210	12	15	0/72	800
2204	1300	1070	0.7	4	−9	4.2	−13.5	14	−17	5120	4860	210	200	12	14	0/72	900
2205	1300	1020	0.7	4.2	−9.2	4.3	−13.6	14	−15	5130	4870	210	200	13	14	0/72	920
2206	1280	1080	0.7	3.9	−8.8	4.5	−13.7	14	−17	5080	4830	230	220	13	15	0/72	840
2207	1280	1100	0.7	3.4	−8.7	4.5	−14	14	−18	5080	4830	210	200	12	14	0/72	860
2208	1300	1060	0.7	3.6	−8.9	4.2	−13.5	14	−17	5120	4860	220	210	12	14	0/72	920
2209	1300	1090	0.7	4.1	−8.8	4	−13.6	14	−18	5160	4900	220	210	12	14	0/72	900
2210	1300	1050	0.7	3.8	−9	4.3	−13.7	14	−17	5150	4890	210	200	12	14	0/72	880
2211	1280	1070	0.7	3.9	−9.2	4.2	−13.3	13	−17	5430	5160	310	300	12	15	0/72	870
2212	1300	1080	0.7	4	−9.4	4	−13.5	14	−18	5450	5180	320	300	12	14	0/72	900
2213	1350	860	1.4	3.5	−8.7	3.9	−13.6	14	−14	3790	3600	150	140	11	13	45/72	160
2214	1350	焼結不足のため測定不能 ⑬															
2215	1350	焼結不足のため測定不能 ⑬															
2216	1350	830	1.3	3.6	−8.8	3.9	−13.7	14	−14	3860	3670	130	120	11	12	68/72	180
2217	1350	焼結不足のため測定不能 ⑬															
2218	1350	焼結不足のため測定不能 ⑬															
2219	1350	焼結不足のため測定不能 ⑬															

⑪ Humidity resistance load test ; number of rejects.
⑫ Mean life span
⑬ Unmeasurable due to ~~imper~~ insufficient sintering

【0057】

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

Table 2010

④ *印は本発明の範囲外

	試料番号 ①	$(BaO)_m \cdot TiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MnO$									③αの合計	β	γ	m	⑤ 第1の副成分の添加量（重量部）	⑥ 第2の副成分の添加量（重量部）
		② $BaTiO_3$の種類	α													
			Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3	Ho_2O_3	Er_2O_3	Tm_2O_3	Yb_2O_3						
*2301	~~*301~~	A	0	0.0007	0	0	0	0	0	0	0.0007	0.03	0.0014	1.005	1	0
*2302	~~*302~~	A	0	0	0.02	0	0.055	0	0	0	0.075	0.02	0.128	1.01	1	0
*2303	~~*303~~	A	0.01	0	0	0.025	0	0	0	0	0.035	0	0.07	1.015	2	0
*2304	~~*304~~	A	0	0.01	0	0	0.01	0	0.01	0	0.03	0.07	0.06	1.01	2.5	0
*2305	~~*305~~	A	0.04	0	0	0	0	0	0	0	0.04	0.025	0.001	1.01	1	0
*2306	~~*306~~	A	0	0	0	0.02	0	0.03	0	0	0.05	0.03	0.145	1.01	1	0
*2307	~~*307~~	A	0	0	0.02	0	0	0	0	0.01	0.03	0.03	0.06	0.99	0	1
*2308	~~*308~~	A	0	0.01	0	0.01	0	0	0	0	0.02	0.03	0.04	1	2	0
*2309	~~*309~~	A	0	0	0	0	0	0	0.01	0	0.01	0.03	0.02	1.037	1	0
*2310	~~*310~~	A	0.01	0.01	0	0	0	0	0	0	0.02	0.03	0.04	1.045	0	2
*2311	~~*311~~	A	0	0	0	0	0.01	0	0	0	0.01	0.02	0.02	1.01	0	0
*2312	~~*312~~	A	0	0.02	0	0	0	0.02	0	0	0.04	0.03	0.08	1.01	4	0
*2313	~~*313~~	A	0	0	0.01	0.01	0	0	0	0	0.02	0.04	0.04	1.015	0	0
*2314	~~*314~~	A	0.01	0	0	0	0	0	0	0.01	0.02	0.02	0.04	1.01	0	5
*2315	~~*315~~	D	0	0	0	0	0.02	0	0	0	0.02	0.04	0.04	1.01	2	0
2316	~~316~~	A	0	0.02	0.02	0	0	0	0	0	0.04	0.02	0.08	1.01	0	1
2317	~~317~~	B	0	0	0.01	0	0	0.01	0	0	0.02	0.03	0.04	1.02	1	0

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α
④ The mark * indicates "out of the scope of the present invention"
⑤ Amount of addition of the first component (parts by weight)
⑥ Amount of addition of the second component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【0062】

【表11】 Table 2011

試料番号 ①	$\{BaO\}_m \cdot TiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MnO$													④ 第1の副成分の添加量（重量部）	⑤ 第2の副成分の添加量（重量部）
	$BaTiO_3$ の種類 ②	α								αの合計 ③	β	γ	m		
		Eu_2O_3	Gd_2O_3	Tb_2O_3	Dy_2O_3	Ho_2O_3	Er_2O_3	Tm_2O_3	Yb_2O_3						
1318	C	0.03	0	0	0	0	0	0	0	0.03	0.02	0.13	1.03	2	0
1319	A	0	0	0	0.01	0	0	0.02	0	0.03	0.02	0.06	1.015	1	0
1320	A	0	0.04	0	0	0	0	0	0	0.04	0.03	0.08	1.02	0	2
1321	A	0	0.001	0	0	0	0	0	0	0.001	0.02	0.002	1.01	1	0
1322	A	0	0	0.01	0.01	0	0	0	0.01	0.03	0.03	0.06	1.01	1	0
1323	A	0	0	0	0	0	0.02	0	0	0.02	0.02	0.04	1.025	0	1
1324	A	0	0.01	0	0	0.03	0	0	0	0.04	0.02	0.08	1.01	0	1
1325	A	0	0	0	0.02	0	0	0.02	0	0.04	0.03	0.08	1.01	1	0
1326	A	0	0.03	0	0	0	0.03	0	0	0.06	0.03	0.12	1.02	2	0
1327	A	0	0	0.01	0	0	0	0.02	0	0.03	0.005	0.06	1.01	1	0
1328	A	0	0	0	0.01	0.01	0	0	0	0.02	0.06	0.04	1.01	1	0
1329	A	0	0	0.01	0	0	0.01	0	0	0.02	0.02	0.04	1.035	2	0
1330	A	0	0	0	0	0	0	0.03	0	0.03	0.03	0.06	1.01	0.2	0
1331	A	0.01	0	0.01	0	0	0	0	0	0.02	0.02	0.04	1.01	3	0
1332	A	0	0	0	0.01	0	0	0	0.01	0.02	0.04	0.04	1.01	0	0.2
1333	A	0	0	0	0	0	0.02	0	0	0.02	0.03	0.04	1.01	0	3

① Sample No. ② Kind of $BaTiO_3$ ③ Total of α

④ Amount of addition of the first ~~ex~~ side component (parts by weight)

⑤ Amount of addition of the second side component (parts by weight)

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

【表1-2】 Table - 2012

【0065】

① Sample No. ② Baking temp. ③ Dielectric constant
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ The mark * indicates "out of the scope of the present invention

⑩ *印は本発明の範囲外

	試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧ CR積(Ω・F) 315V印加⑨ 25℃	945V印加⑨ 25℃	315V印加⑨ 150℃	945V印加⑨ 150℃	絶縁破壊電圧(kV/mm) ⑪ AC	DC	耐湿負荷試験 不良個数 ⑫	平均寿命時間(h) ⑬
*2301	~~*301~~	1300	1560	0.8	4	−13	5	−18	18	−39	5200	4940	230	220	12	14	0/72	880
*2302	~~*302~~	1300	810	0.7	2.4	−7	4	−7	7	−10	5430	5160	200	190	12	14	12/72	920
*2303	~~*303~~	1300	1330	0.8	2.2	−7.8	5	−8	8	−22	3000	2100	90	60	12	14	0/72	860
*2304	~~*304~~	1300	1330	0.7	2.4	−14.2	4.8	−27	27	−22	5230	4970	220	210	12	14	0/72	130
*2305	~~*305~~	半導体化のため測定不能 ⑭																
*2306	~~*306~~	1280	1120	0.8	3.4	−8.3	4.6	−19	19	−13	3080	2930	130	120	12	14	0/72	120
*2307	~~*307~~	半導体化のため測定不能																
*2308	~~*308~~	1300	1440	0.7	3.2	−8.2	4.1	−9	9	−37	3200	3040	120	110	10	12	0/72	110
*2309	~~*309~~	焼結不足のため測定不能 ⑮																
*2310	~~*310~~	焼結不足のため測定不能 ⑮																
*2311	~~*311~~	焼結不足のため測定不能 ⑮																
*2312	~~*312~~	1300	1280	2.2	3.3	−8.7	4.3	−9.2	9.2	−22	3310	3150	130	120	11	11	0/72	140
*2313	~~*313~~	焼結不足のため測定不能																
*2314	~~*314~~	1300	1420	2.4	2.7	−7.6	3.6	−8	8	−36	3200	3040	150	140	10	11	0/72	170
*2315	~~*315~~	1300	1120	0.7	2.4	−7.2	5	−9.1	9.1	−14	5240	4980	210	200	12	14	0/72	900
2316	~~316~~	1280	1220	0.7	2.4	−8.4	4.5	−11	11	−21	5130	4870	250	240	12	14	0/72	850
2317	~~317~~	1280	1450	0.7	2.6	−8.6	4.6	−12.1	12.1	−37	5160	4900	230	220	13	15	0/72	890

⑪ Insulation breakdown voltage ⑫ Humidity resistance load test: Number of rejects
⑬ Mean life span
⑭ Unmeasurable due to semiconductor formation
⑮ Unmeasurable due to insufficient sintering

THIS SHEET (PAGE 9) HAS BEEN REPLACED

This Sheet Has Been Replaced

整理番号＝198040

THIS SHEET HAS BEEN REPLACED

~~【表1-3】~~ Table 3

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation break down voltage

試料番号 ①	焼成温度(℃) ②	誘電率 ③	誘電損失 tan δ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧ CR積(Ω·F) 315V 印加⑨ 25℃	945V 印加⑨ 25℃	315V 印加⑨ 150℃	945V 印加⑨ 150℃	絶縁破壊電圧(kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間(h) ⑫
2318	1280	1360	0.8	3	−9	4.7	−10.4	10.4	−28	5200	4940	220	210	12	14	0/72	930
2319	1300	1370	0.7	3.4	−9.1	4.5	−9.7	9.7	−30	5080	4830	240	230	12	14	0/72	870
2320	1300	1240	0.7	2.8	−8.7	5	−9.5	9.5	−22	5140	4880	230	220	12	14	0/72	830
2321	1300	1510	0.7	2.6	−8.5	4.8	−13.4	13.4	−39	5300	5040	230	220	12	14	0/72	950
2322	1300	1360	0.7	2	−9	4.6	−10.3	10.3	−29	5220	4960	210	200	12	14	0/72	880
2323	1300	1460	0.7	3	−9.2	4.9	−11.2	11.2	−38	5290	5030	250	240	12	14	0/72	900
2324	1280	1250	0.8	3.2	−8.8	4.6	−11	11	−23	5340	5070	230	220	13	15	0/72	860
2325	1300	1240	0.7	3.3	−8.7	4.3	−12	12	−23	5330	5060	220	210	12	14	0/72	830
2326	1300	960	0.7	2.9	−9.2	5.1	−12.5	12.5	−12	5080	4830	200	190	13	15	0/72	810
2327	1300	1340	0.7	2.8	−9.3	5.3	−12.1	12.1	−30	5210	4950	210	200	12	14	0/72	870
2328	1280	1440	0.7	2.1	−8.5	4	−11.5	11.5	−38	5240	4980	220	210	12	14	0/72	910
2329	1300	1470	0.8	2.6	−8.2	4.6	−13.6	13.6	−39	5260	5000	230	220	12	14	0/72	950
2330	1300	1360	0.7	3	−8.8	4.2	−11.8	11.8	−28	5220	4960	220	210	12	14	0/72	880
2331	1280	1420	0.8	2.7	−9	4.8	−11.9	11.9	−36	5240	4980	210	200	12	14	0/72	930
2332	1300	1430	0.7	2.8	−8.6	4.7	−11	11	−36	5280	5020	230	220	12	14	0/72	910
2333	1300	1460	0.7	3	−9.1	4.3	−10.7	10.7	−39	5300	5040	220	210	12	14	0/72	860

⑪ Humidity resistance load test ; number of rejection
⑫ Mean life span

This Sheet Has Been Replaced

[redacted]

① Sample No. ② Baking temp. ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC vias characteristic ⑧ Product CR ⑨ Impressed voltage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧CR積(Ω·F) 315V 印加⑨ 25℃	945V 印加⑨ 25℃	315V 印加⑨ 150℃	945V 印加⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験 不良個数 ⑪	平均寿命時間 (h) ⑫
2401	1300	1430	0.7	2.6	−8.4	3.6	−10.1	10.1	−36	5100	4850	220	210	12	14	0/72	880
2402	1300	1430	0.6	2.3	−8.4	3.4	−10.5	10.5	−36	5120	4860	210	200	12	14	0/72	900
2403	1280	1440	0.7	2.5	−8	4.1	−10.6	10.6	−36	5230	4970	200	190	12	14	0/72	870
2404	1300	1470	0.7	2.2	−8.1	4.2	−11	11	−38	5100	4850	230	220	12	14	0/72	820
2405	1300	1430	0.7	2.2	−7.9	4	−11.3	11.3	−36	5160	4900	230	220	13	15	0/72	820
2406	1280	1430	0.7	2.7	−8	4.2	−11.5	11.5	−36	5230	4970	210	200	12	14	0/72	950
2407	1300	1430	0.7	2.6	−8.2	3.9	−10.5	10.5	−36	5140	4880	220	210	13	15	0/72	830
2408	1280	1460	0.6	2.8	−8.3	4.1	−11	11	−37	5150	4890	220	210	12	14	0/72	800
2409	1280	1460	0.7	2.4	−8	4.2	−12.1	12.1	−37	5120	4860	200	190	12	14	0/72	880
2410	1280	1480	0.7	2.3	−8.1	4.1	−11.7	11.7	−38	5130	4870	220	210	12	14	0/72	850
2411	1300	1440	0.7	2.4	−8.2	3.9	−11.6	11.6	−36	5140	4880	220	210	12	14	0/72	810
2412	1280	1420	0.6	2.2	−8.3	3.8	−11.5	11.5	−36	5260	5000	200	190	12	14	0/72	920
2413	1350	焼結不足のため測定不能 ⑬															
2414	1350	焼結不足のため測定不能 ⑬															
2415	1350	1440	1.8	2.8	−8	3.8	−11	11	−38	5220	4960	190	180	11	12	55/72	120
2416	1350	焼結不足のため測定不能 ⑬															
2417	1350	焼結不足のため測定不能 ⑬															
2418	1300	1460	0.8	2.7	−8.2	4.1	−10.7	10.7	−37	5170	4910	210	200	11	13	0/72	860
2419	1350	1430	1.6	2.5	−8.3	4.2	−10.8	10.8	−36	5280	5020	220	210	11	13	33/72	110
2420	1300	1440	0.7	2.5	−8.4	4	−11.5	11.5	−37	5100	4850	190	180	12	13	0/72	870
2421	1350	1460	1.8	2.7	−8.3	3.9	−10	10	−37	5160	4900	190	180	11	13	52/72	130
2422	1350	1420	1.6	2.5	−8.2	3.7	−10.7	10.7	−36	5200	4940	200	190	11	13	49/72	140

⑪ Humidity resistance load test Number of rejection
⑩ Insulation breakdown voltage ⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

【0075】

整理番号＝198040

表1 Table 1

THIS SHEET HAS BEEN REPLACED

This Sheet Has Been Replaced

① Sample No. ② Baking temp ③ Dielectric constant ④ Dielectric loss
⑤ Ratio of temperature dependent capacitance change ⑥ Maximum value
⑦ DC bias characteristic ⑧ Product CR ⑨ Impressed voltage
⑩ Insulation breakdown voltage

試料番号 ①	焼成温度 (℃) ②	誘電率 ③	誘電損失 tanδ (%) ④	⑤容量温度変化率(%) ΔC/C20 −25℃	ΔC/C20 85℃	ΔC/C25 −55℃	ΔC/C25 125℃	最大値 ⑥	DCバイアス特性(%) ⑦ ΔC/C 5kV/mm	⑧CR積(Ω·F) 315V印加 ⑨ 25℃	945V印加 ⑨ 25℃	315V印加 ⑨ 150℃	945V印加 ⑨ 150℃	絶縁破壊電圧 (kV/mm) ⑩ AC	DC	耐湿負荷試験不良個数 ⑪	平均寿命時間 (h) ⑫
2501	1300	1350	0.9	2.2	−8.3	3.6	−10.2	10.2	−32	5120	4860	230	220	12	14	0/72	870
2502	1300	1350	0.8	2.3	−8.6	4.1	−10.4	10.4	−32	5210	4950	240	230	12	14	0/72	920
2503	1300	1360	0.9	2.4	−8.7	4	−11	11	−32	5130	4870	220	210	12	14	0/72	860
2504	1300	1320	0.8	2.3	−9	3.8	−11.6	11.6	−31	5140	4880	230	220	13	15	0/72	840
2505	1300	1360	0.9	2.2	−8.2	3.9	−10.8	10.8	−32	5160	4900	220	210	12	14	0/72	920
2506	1300	1340	0.8	2.3	−8.6	4	−10.7	10.7	−32	5120	4860	210	200	12	14	0/72	910
2507	1300	1310	0.9	2.6	−8.4	4.2	−11	11	−30	5240	4980	230	220	13	15	0/72	880
2508	1300	1340	0.9	2.5	−8.2	4	−11.5	11.5	−32	5230	4970	220	210	12	14	0/72	900
2509	1300	1330	0.9	2.3	−8.3	3.7	−11.6	11.6	−31	5200	4940	220	210	12	14	0/72	920
2510	1300	1370	0.9	2.1	−8.4	3.5	−11.3	11.3	−33	5030	4780	210	200	12	14	0/72	930
2511	1300	1360	0.8	2.2	−8.6	3.8	−10.9	10.9	−32	5430	5160	340	320	12	14	0/72	850
2512	1300	1350	0.9	2.6	−8.3	3.6	−10.7	10.7	−32	5410	5140	330	310	12	14	0/72	900
2513	1350	1330	0.9	2.4	−8.4	4	−11	11	−31	5120	4860	220	210	11	13	55/72	120
2514	1350	焼結不足のため測定不能 ⑬															
2515	1350	焼結不足のため測定不能 ⑬															
2516	1350	1320	1	2.3	−8.5	3.8	−11.5	11.5	−30	5160	4900	230	220	11	13	64/72	110
2517	1350	焼結不足のため測定不能 ⑬															
2518	1350	焼結不足のため測定不能 ⑬															
2519	1350	焼結不足のため測定不能 ⑬															

⑪ Humidity resistance load test; Number of reject
⑫ Mean life span
⑬ Unmeasurable due to insufficient sintering

整理番号＝198040
技術員 Takeiri 2015
THIS SHEET HAS BEEN REPLACED
This Sheet Has Been Replaced

* C L M S *

THIS SHEET HAS BEEN REPLACED

WHAT IS CLAIMED IS:

1. A dielectric ceramic composition comprising barium titanate containing 0.02% by weight or less of alkali metal oxides, at least one of either scandium oxide or yttrium oxide, at least one kind of compound selected from europium oxide, gadolinium oxide, terbium oxide and dysprosium oxide, barium zirconate and manganese oxide, containing an essential component represented by the following composition formula;

$$(BaO)_mTiO_2 + \alpha M_2O_3 + \beta R_2O_3 + \gamma BaZrO_3 + gMnO$$

(wherein M_2O_3 represents at least one of either Sc_2O_3 or Y_2O_3 and R_2O_3 represents at least one of the compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3 and Dy_2O_3, α, β, γ and g representing mole ratio in the range of $0.001 \leq \alpha \leq 0.05$, $0.001 \leq \beta \leq 0.05$, $0.005 \leq \gamma \leq 0.06$, $0.001 < g \leq 0.13$ and $\alpha + \beta \leq 0.06$ with $1.000 < m \leq 1.035$),

characterized by containing 0.2 to 3.0 parts by weight of either the first or second side component relative to 100 parts by weight of said essential component, wherein said first side component is an oxide represented by Li_2O - $(Si, Ti)O_2$ - MO (wherein MO is at least one of Al_2O_3 or ZrO_2) and said second side component is an oxide represented by SiO_2 - TiO_2 - XO (wherein XO is at least one of the compound

This Sheet Has Been Replaced

selected from BaO, CaO, SrO, MgO, ZnO and MnO).

2. A dielectric ceramic composition according to Claim 1, wherein said essential component further contains h mole ratio of magnesium oxide, where $0.001 < g \leq 0.12$, $0.001 < h \leq 0.12$ and $g + h \leq 0.13$

3. A dielectric ceramic composition comprising barium titanate containing 0.02% by weight or less of alkali metal oxides, at least one of either scandium oxide or yttrium oxide, barium zirconate and manganese oxide, containing an essential component represented by the following composition formula;

$$(BaO)_mTiO_2 + \alpha M_2O_3 + \beta BaZrO_3 + \gamma MnO$$

(wherein M_2O_3 represents at least one of either Sc_2O_3 or Y_2O_3, α, β and γ representing mole ratio in the range of $0.001 \leq \alpha \leq 0.06$, $0.005 \leq \beta \leq 0.06$ and $0.001 < \gamma \leq 0.13$ with $1.000 < m \leq 1.035$),

characterized by containing 0.2 to 3.0 parts by weight of either the first or second side component relative to 100 parts by weight of said essential component, wherein said first side component is an oxide represented by Li_2O-(Si, Ti)O_2-MO (wherein MO is at least one of Al_2O_3 or ZrO_2) and said second side component is an oxide represented by SiO_2-

TiO_2-XO (wherein XO is at least one of the compound selected from BaO, CaO, SrO, MgO, ZnO and MnO).

4. A dielectric ceramic composition according to Claim 3, wherein said essential component further contains g mole ratio of magnesium oxide, where $0.001 < \gamma \leq 0.12$, $0.001 < g \leq 0.12$ and $\gamma + g \leq 0.13$

5. A dielectric ceramic composition comprising:

barium titanate containing 0.02% by weight or less of alkali metal oxides, at least one kind of the compound selected from europium oxide, gadolinium oxide, terbium oxide, dysprosium oxide, holmium oxide, erbium oxide, thulium oxide and ytterbium oxide, barium zirconate and manganese oxide, containing an essential component represented by the following composition formula;

$$(BaO)_mTiO_2 + \alpha R_2O_3 + \beta BaZrO_3 + \gamma MnO$$

(wherein R_2O_3 represents at least one kind of compound selected from Eu_2O_3, Gd_2O_3, Tb_2O_3, Dy_2O_3, Ho_2O_3, Er_2O_3, Tm_2O_3 and Yb_2O_3, α, β and γ representing mole ratio in the range of $0.001 \leq \alpha \leq 0.06$, $0.005 \leq \beta \leq 0.06$ and $0.001 < \gamma \leq 0.13$ with $1.000 < m \leq 1.025$),

characterized by containing 0.2 to 3.0 parts by weight of either the first or second side component relative to 100

* C L M S *

THIS SHEET HAS BEEN REPLACED

parts by weight of said essential component, wherein said first side component is an oxide represented by Li_2O-(Si, Ti)O_2-MO (wherein MO is at least one of Al_2O_3 or ZrO_2) and said second side component is an oxide represented by SiO_2 - TiO_2 - XO (wherein XO is at least one of the compound selected from BaO, CaO, SrO, MgO, ZnO and MnO).

6. A dielectric ceramic composition according to Claim 5, wherein said essential component further contains g mole ratio of magnesium oxide, where $0.001 \leq \beta \leq 0.06$, $0.001 < \gamma \leq 0.12$, $0.001 < g \leq 0.12$ and $\gamma + g \leq 0.13$.

7. A dielectric ceramic composition according to Claim 1 to Claim 6, wherein said first side component, when its composition is represented by xLi_2O-$y(Si_wTi_{1-w})O_2$-zMO (wherein x, y and z represent mol% and w is in the range of $0.30 \leq w \leq 1.00$), falls within or on the boundary lines of the area surrounded by the straight lines connecting each point indicated by A (x = 20, y = 80, z = 0), B (x = 10, y = 80, z = 10), C (x = 10, y = 70, z = 20), D (x = 35, y = 45, z = 20), E (x = 45, y = 45, z = 10) and F (x = 45, y = 55, z = 0) (when the composition falls on the straight line of A - F, w is within the area of $0.3 \leq w < 1.0$) in the three component phase diagram defined by the apexes corresponding

This Sheet Has Been Replaced

to each component.

8. A dielectric ceramic composition according to Claim 1 to Claim 6, wherein said second side component, when its composition is represented by $xSiO2-yTiO_2-zXO$ (wherein x, y and z represent mol%), falls within or on the boundary lines of the area surrounded by straight lines connecting each point indicated by A (x = 85, y = 1, z = 14), B (x = 35, y = 51, z = 14), C (x = 30, y = 20, z = 50) and D (x = 39, y = 1, z = 60) in the three component phase diagram defines by the apexes corresponding to each component.

9. A dielectric ceramic composition according to Claim 8, wherein the second side component contains in total of 15 parts by weight or less of at least one of Al_2O_3 and ZrO_2 (the content of ZrO_2 is 5 parts by weight or less) relative to 100 parts by weight of the oxide represented by SiO_2-TiO_2-XO.

10. A monolithic ceramic capacitor provided with a plurality of dielectric ceramic layers, inner electrodes formed between said ceramic layers and outer electrodes being electrically connected to said inner electrodes, wherein said dielectric ceramic layers are constructed by

the dielectric ceramic composition according to any one of Claim 1 to Claim 6 and said inner electrodes are constructed by nickel or a nickel alloy.

11. A monolithic ceramic capacitor according to Claim 10, wherein the outer electrode is provided with a sintered layer of an electroconductive metal powder or an electroconductive metal powder supplemented with glass frits.

12. A monolithic ceramic capacitor according to Claim 10, wherein the outer electrode is provided with a first layer comprising a sintered layer of the electroconductive metal powder or the electroconductive metal powder supplemented with glass frits and a second layer comprising a plating layer thereon.

13. A monolithic ceramic capacitor according to Claim 11, wherein the outer electrode is provided with a first layer comprising a sintered layer of the electroconductive metal powder or the electroconductive metal powder supplemented with glass frits and a second layer comprising a plating layer thereon.